

# Monte Carlo study of velocity fluctuations during transient regimes in monolayer graphene



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CAMPUS DE EXCELENCIA INTERNACIONAL

# Outline

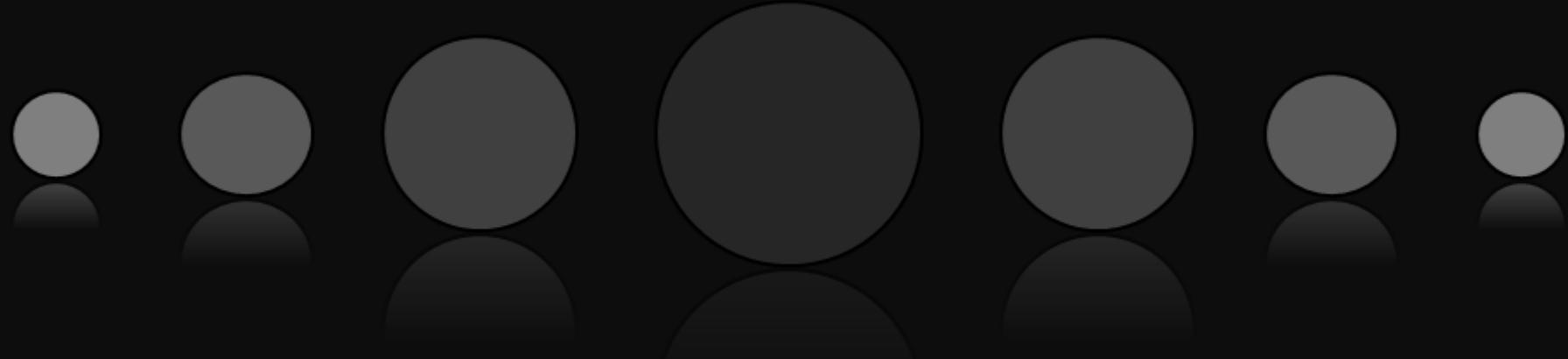
## 1. Introduction

- Ensemble Material Monte Carlo model
- Study of the transient velocity fluctuations

## 2. Results

- Graphene on SiO<sub>2</sub>
  - Evolution of v, k, and ε
  - Low-to-high and high-to-low field: Tr. ACF and Tr. PSD
- Comparison with other cases

## 3. Conclusions

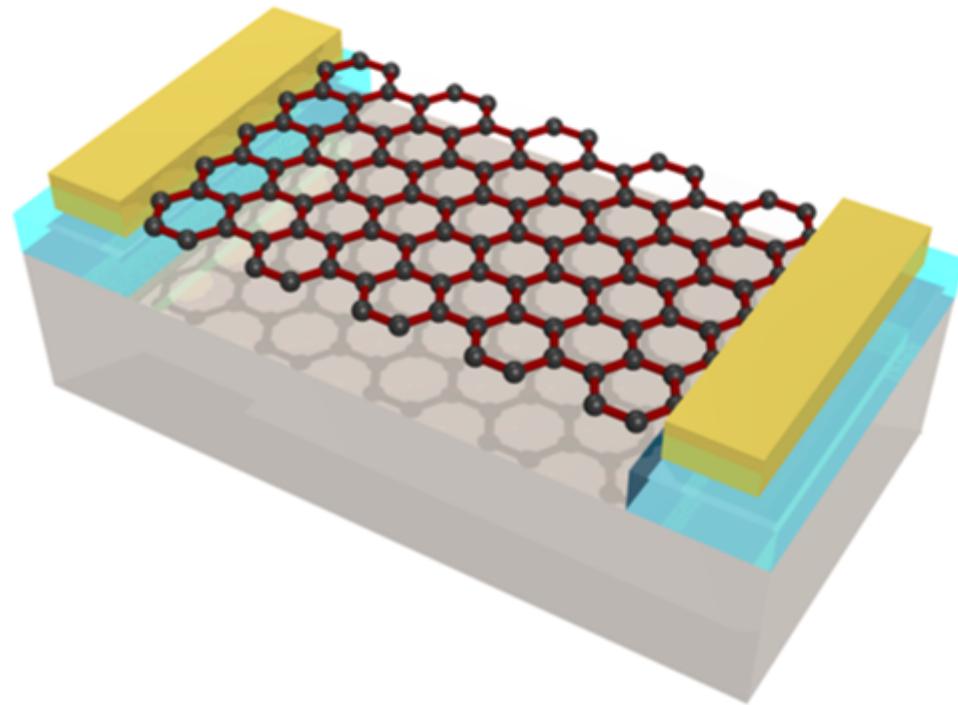


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# Introduction

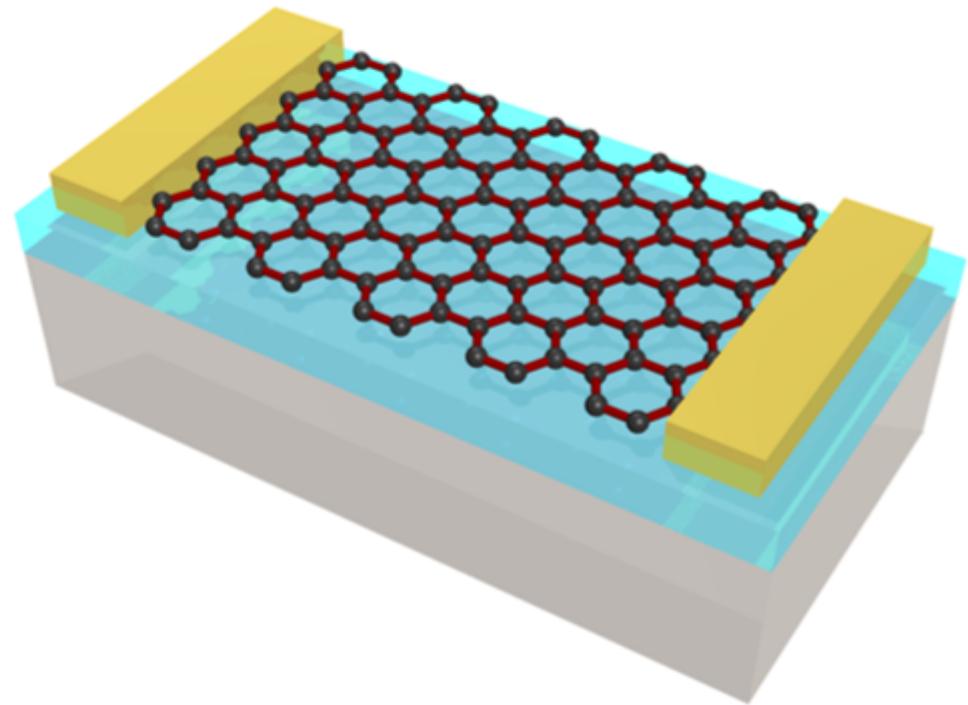
# Why graphene?

- **Suspended graphene:**



- Excellent electronic transport properties
- Extremely high mobility at room temperature

- **Graphene on a substrate**



- Typical substrates:  $\text{SiO}_2$ , h-BN, SiC,  $\text{HfO}_2$ , etc.
- Transport properties affected by scattering with substrate phonons (SPPs), impurities, lattice defects...

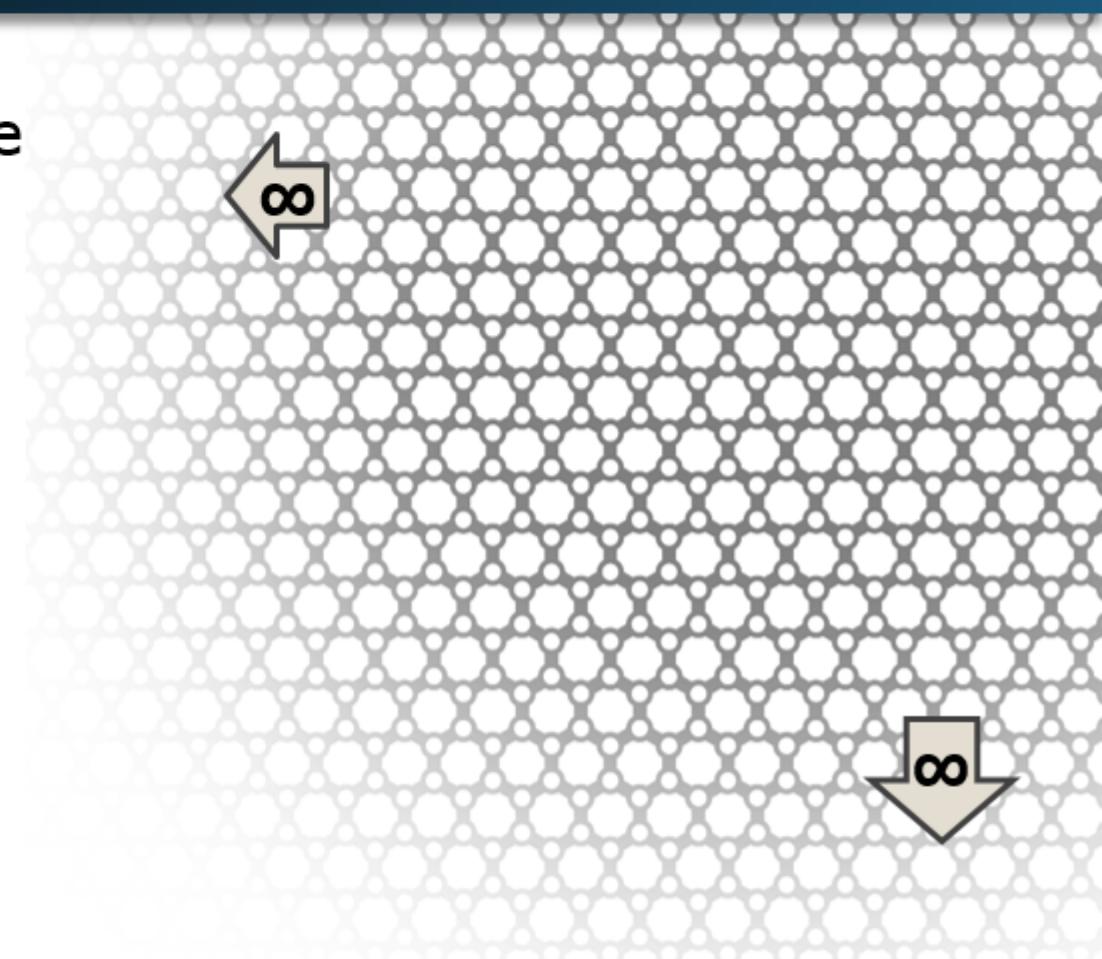
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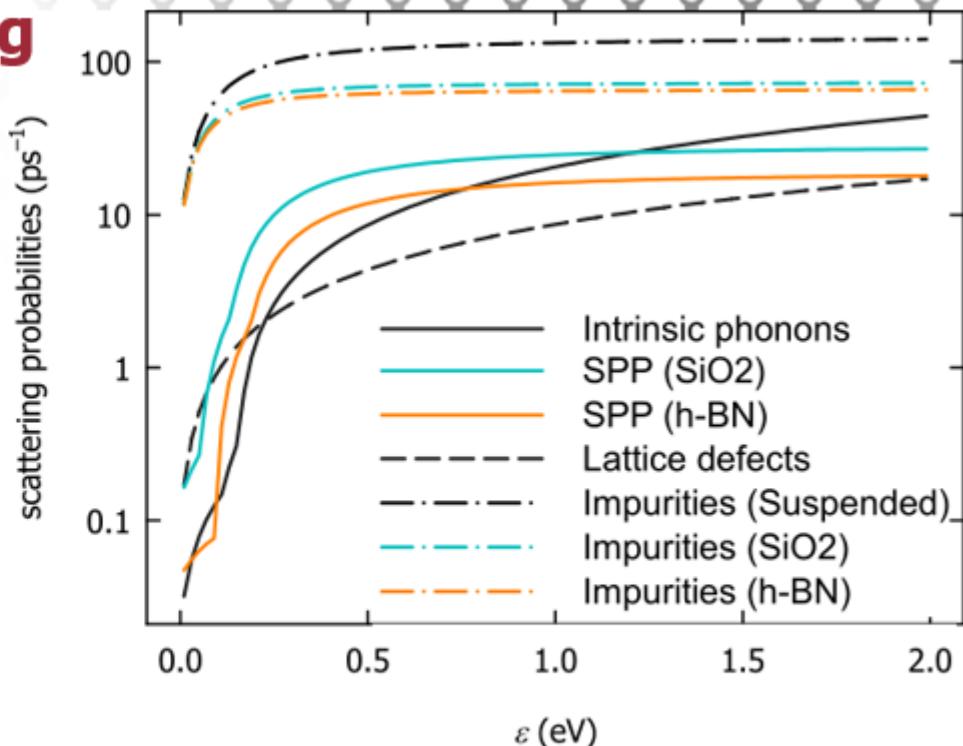
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2. An **ensemble** of “**superparticles**” (typically 100000) is simulated in a gridded ***k*-space** for a given time step.



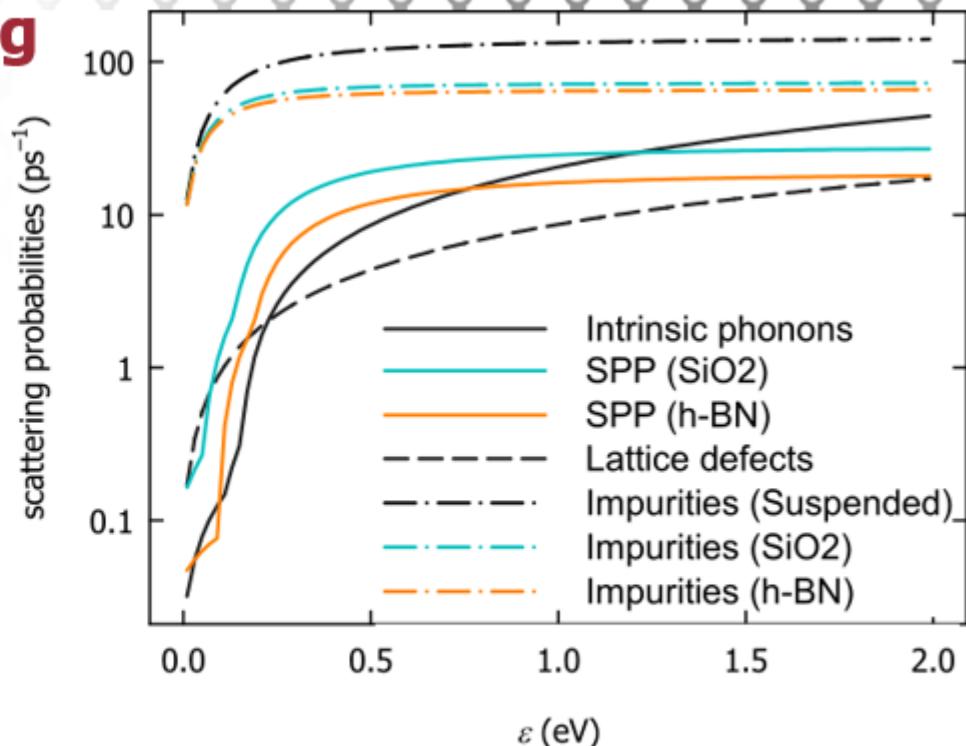
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3. **Dynamics** is ruled by the effect of a **dragging electric field** and the included **scattering mechanisms**:
  - Intrinsic phonons
  - Surface Polar Phonons
  - Impurities, crystalline defects
  - Carrier-carrier

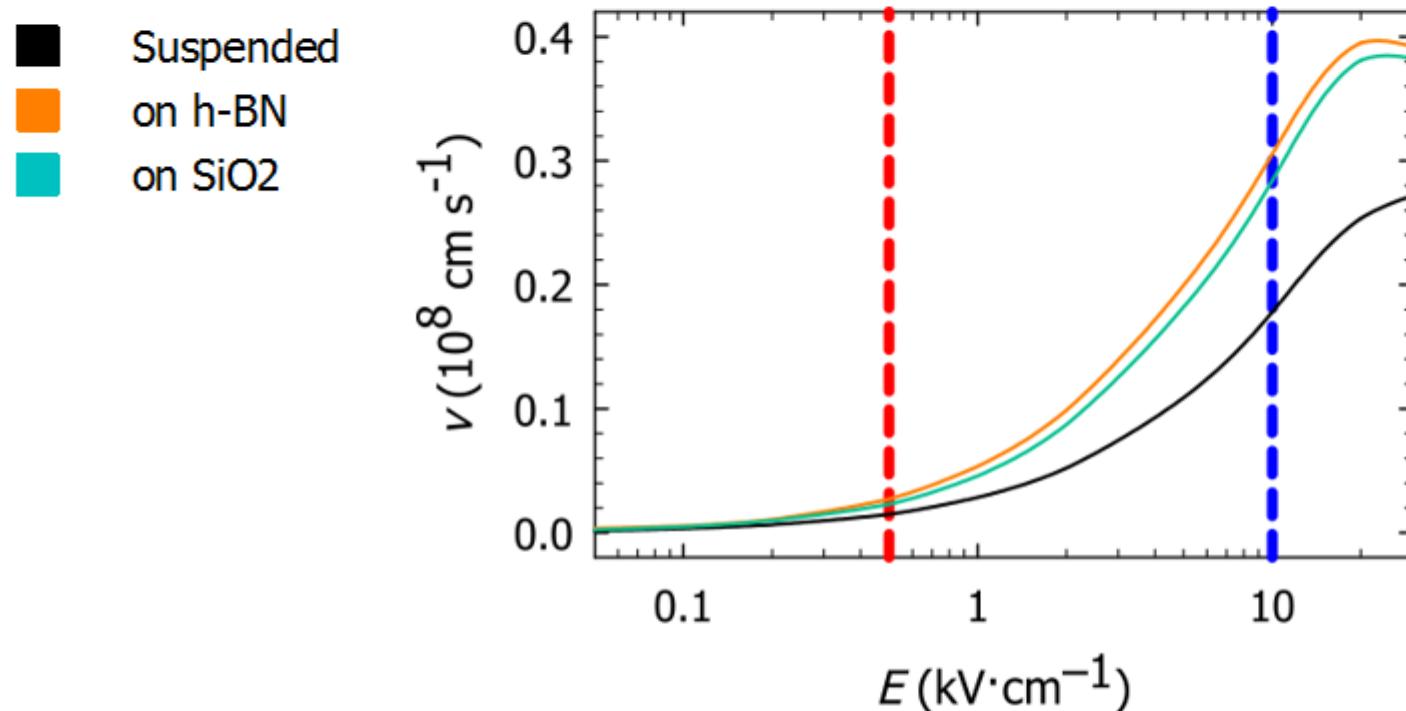


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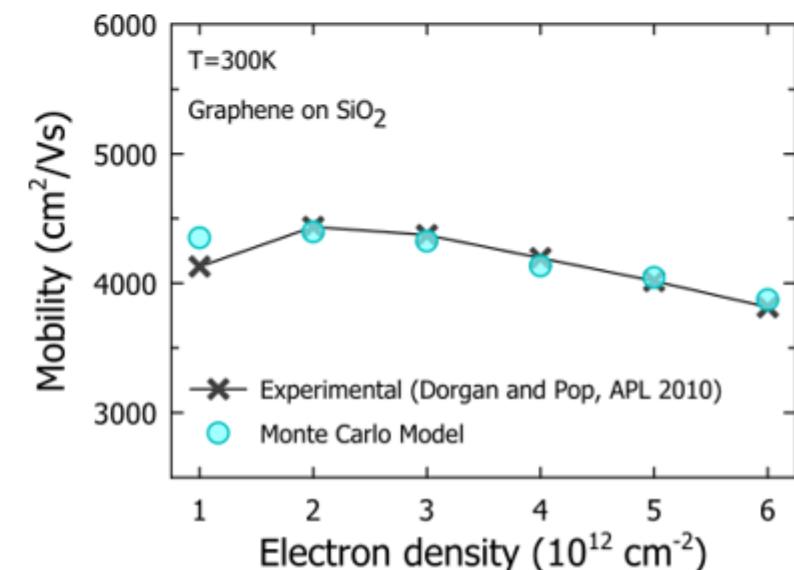
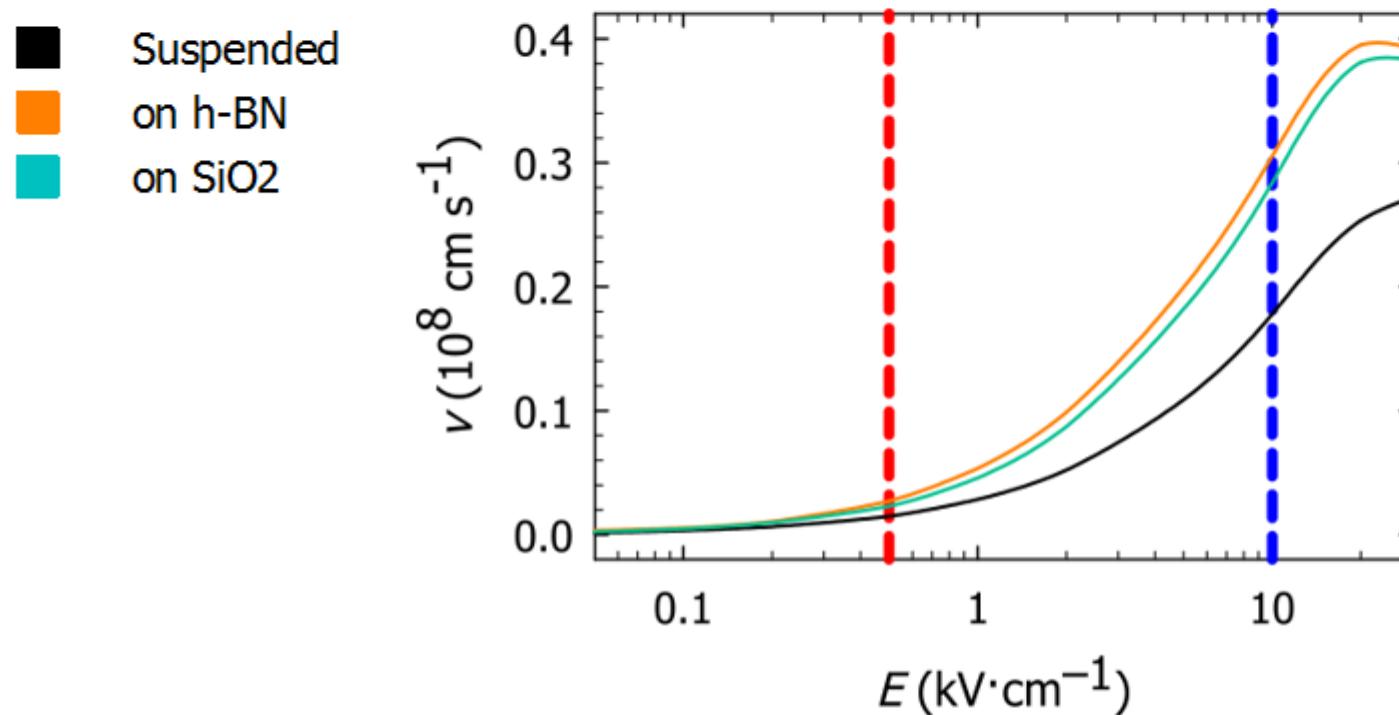
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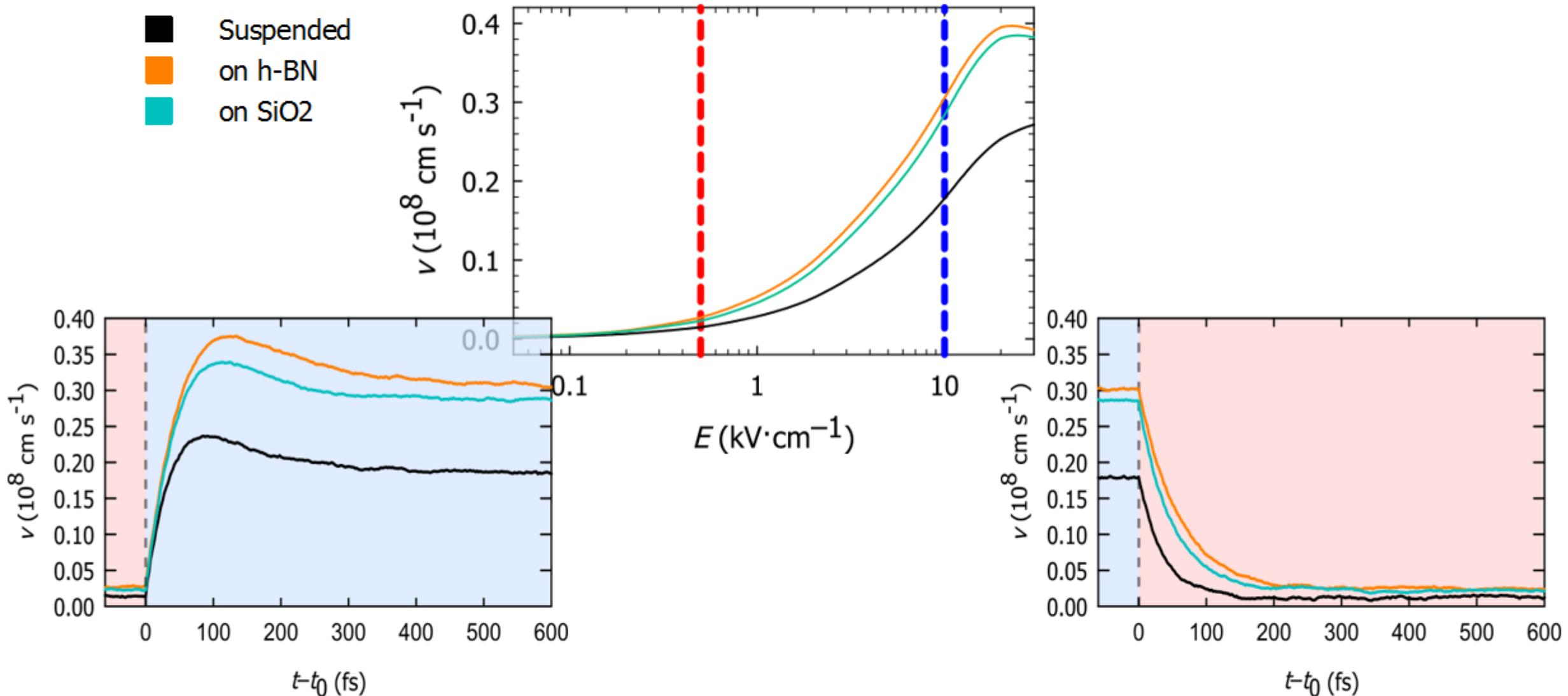


Fit to  
experimental

# Transient regimes for velocity fluctuations: High and low electrostatic field



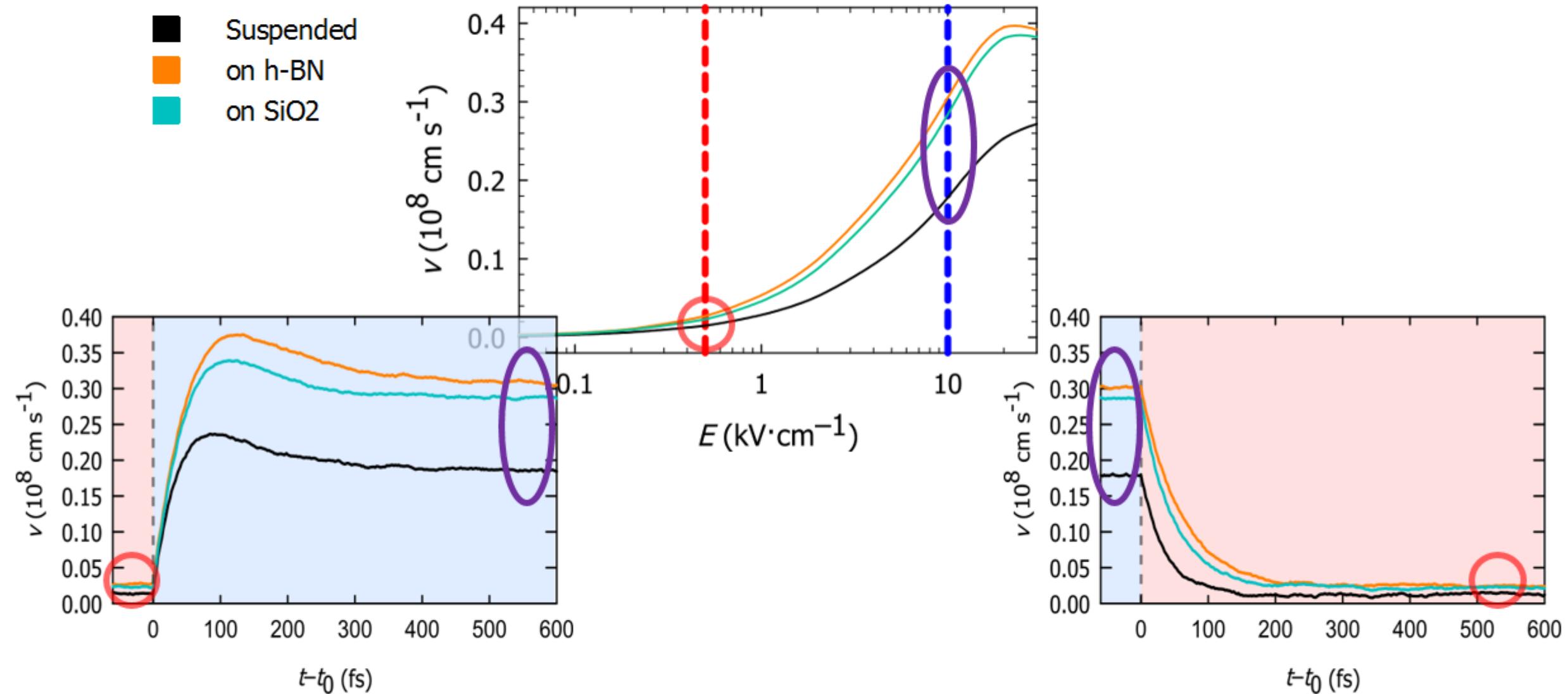
- Suspended
- on h-BN
- on SiO<sub>2</sub>



Low → high field

High → low field

# Transient regimes for velocity fluctuations: High and low electrostatic field



Low → high field

High → low field

# Calculation of the Transient Autocorrelation Function

- Velocity fluctuations in a transient

$$\delta v(t) = v(t) - v_d(t) = v(t) - \langle v(t) \rangle$$

$$\langle \xi \rangle = \sum_{i=1}^N \frac{\xi_i}{N}$$

- Transient Autocorrelation Function

$$C_{\delta v}(t, \tau) = \langle \delta v(t) \delta v(t - \tau) \rangle$$

- Two-time correlation:  $\tau, t$ :  
extends towards the past:  $t_0 \leq \tau \leq t$

[1] R. Brunetti, C. Jacoboni. *Phys. Rev. B* **29**, 5739 (1984)

# Calculation of the Transient Autocorrelation Function

- The values of  $\delta v(t)$  are stored at fixed times ( $\Delta t$ ) for every superparticle in the ensemble:

	$t = 0 = t_0$	$t = \Delta t$	$t = 2\Delta t$	$\dots$	$t = (n-1)\Delta t$	$t = n\Delta t$
1	$\delta v_1(0)$	$\delta v_1(\Delta t)$	$v_1(2\Delta t)$	$\dots$	$\delta v_1((n-1)\Delta t)$	$\delta v_1(n\Delta t)$
2	$\delta v_2(0)$	$\delta v_2(\Delta t)$	$\delta v_2(2\Delta t)$	$\dots$	$\delta v_2((n-1)\Delta t)$	$\delta v_2(n\Delta t)$
:	$\dots$	$\dots$	$\dots$	$\ddots$	$\dots$	$\dots$
$N_p$	$\delta v_{N_p}(0)$	$\delta v_{N_p}(\Delta t)$	$\delta v_{N_p}(2\Delta t)$	$\dots$	$\delta v_{N_p}((n-1)\Delta t)$	$\delta v_{N_p}(n\Delta t)$

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# Contributions to the Autocorrelation Function



The contributions to  $\delta v(t)$

$$\delta v(t) = \delta v_\varepsilon(t) + \delta v_{\mathbf{k}}(t)$$

Convective:	$\delta v_\varepsilon(t) = v_\varepsilon(t) - v_d(t)$
Thermal:	$\delta v_{\mathbf{k}}(t) = v(t) - v_\varepsilon(t)$

$$\begin{bmatrix} C_{\delta v, \varepsilon\varepsilon} & C_{\delta v, \varepsilon\mathbf{k}} \\ C_{\delta v, \mathbf{k}\varepsilon} & C_{\delta v, \mathbf{k}\mathbf{k}} \end{bmatrix} = \begin{bmatrix} \langle \delta_\varepsilon(t) \delta_\varepsilon(t-\tau) \rangle & \langle \delta_\varepsilon(t) \delta_{\mathbf{k}}(t-\tau) \rangle \\ \langle \delta_{\mathbf{k}}(t) \delta_\varepsilon(t-\tau) \rangle & \langle \delta_{\mathbf{k}}(t) \delta_{\mathbf{k}}(t-\tau) \rangle \end{bmatrix}$$

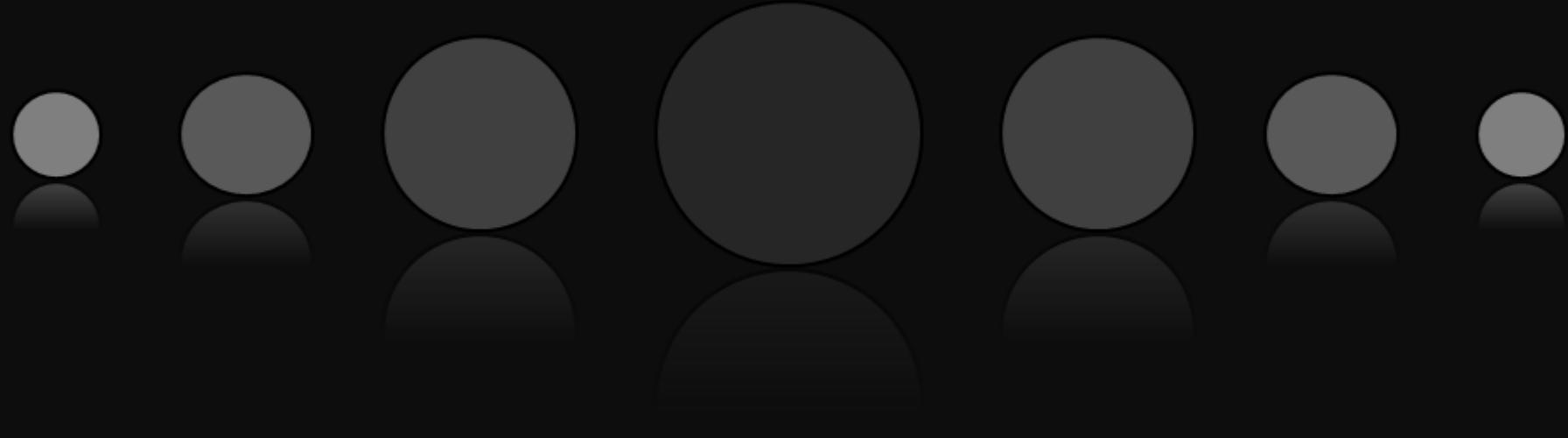
[2] R. Brunetti, C. Jacoboni. *Phys. Rev. Lett.* **50**, 1164 (1983)

# Calculation of the Transient Power Spectral Density

- $S_{\delta v}(f, t)$  provides the power dissipated **between  $t_0$  and  $\tau$**  during the transient for a frequency between  $f$  and  $f+df$

$$S_{\delta v}(f, \tau) = \frac{1}{\tau} \left\langle \left| \int_{t_0}^{\tau} \delta v(t) \exp(j\omega t) dt \right|^2 \right\rangle$$

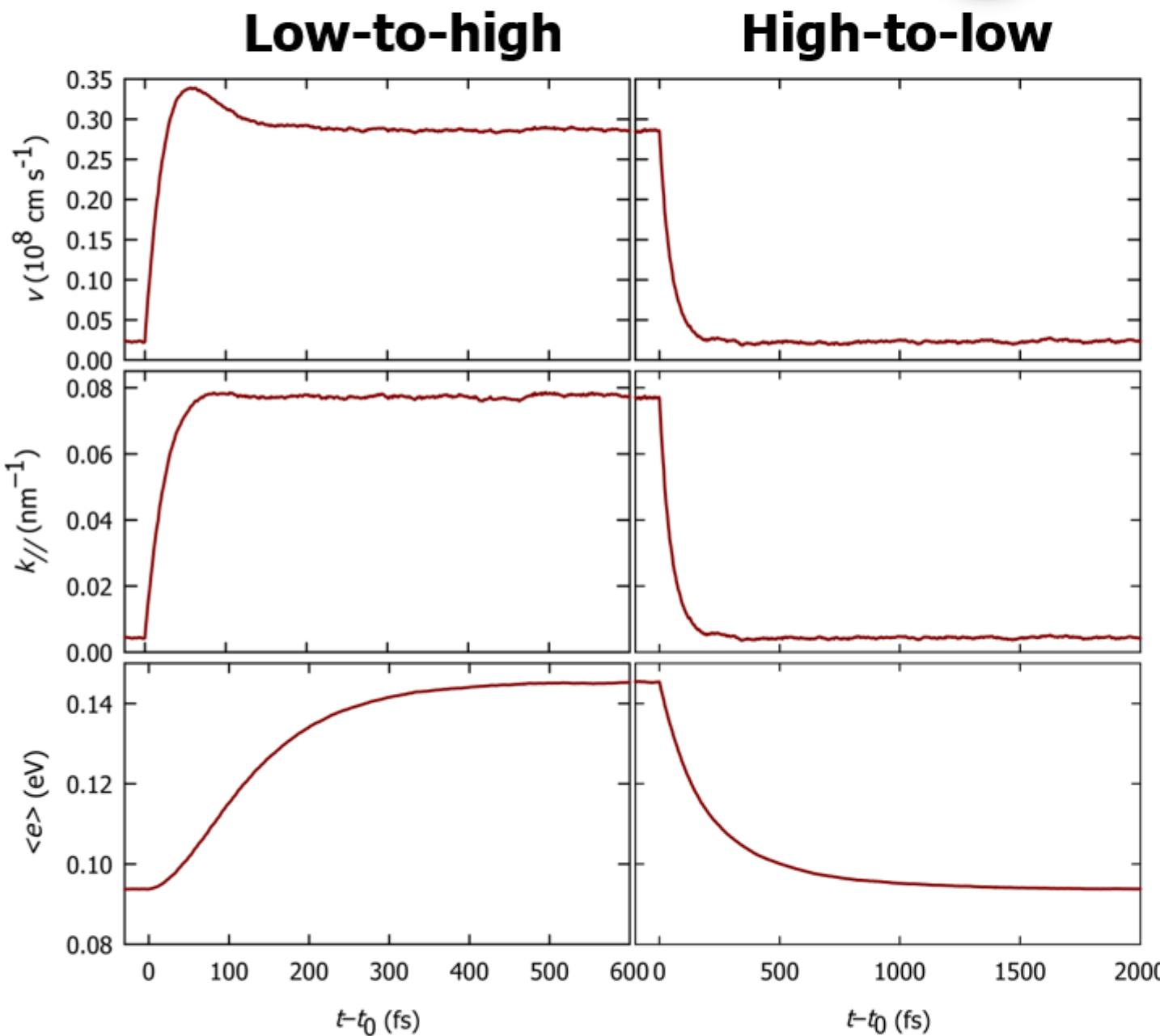
[3] T. González, J. E. Velázquez et al. *Appl. Phys. Lett.* **60** 613 (1992)



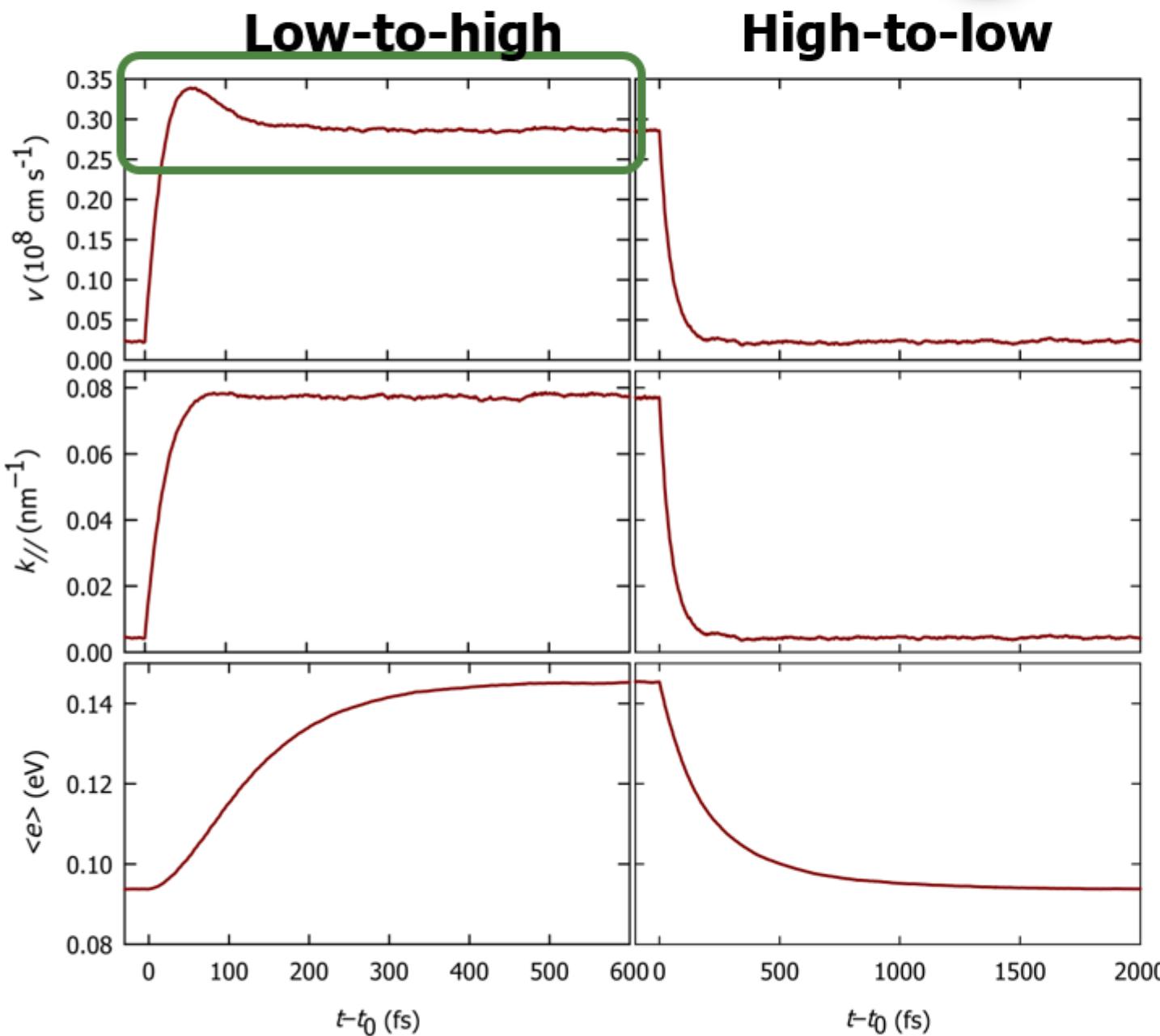
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## Results

# Graphene on SiO<sub>2</sub>: Evolution of the average velocity, kinetic energy and parallel momentum

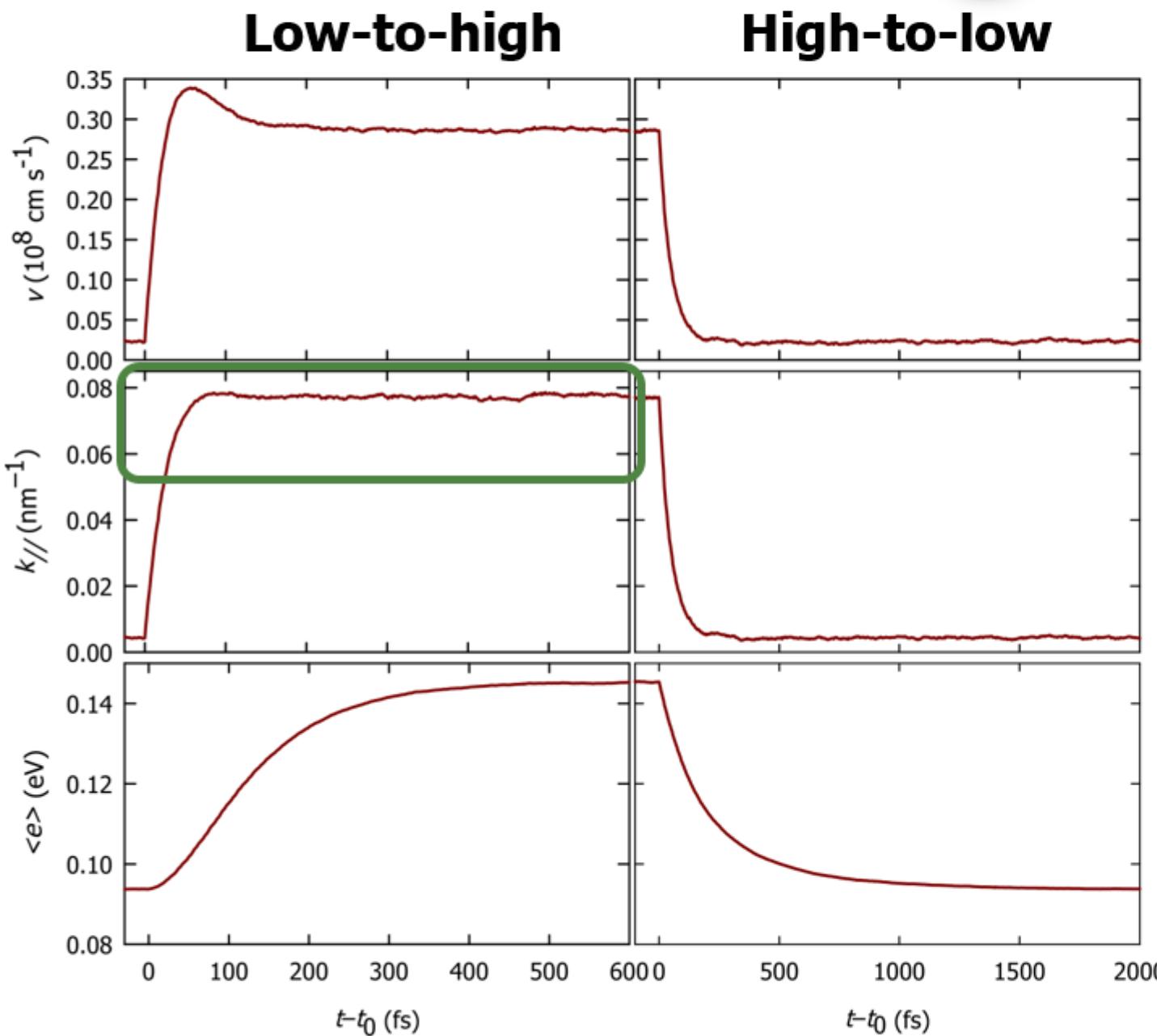


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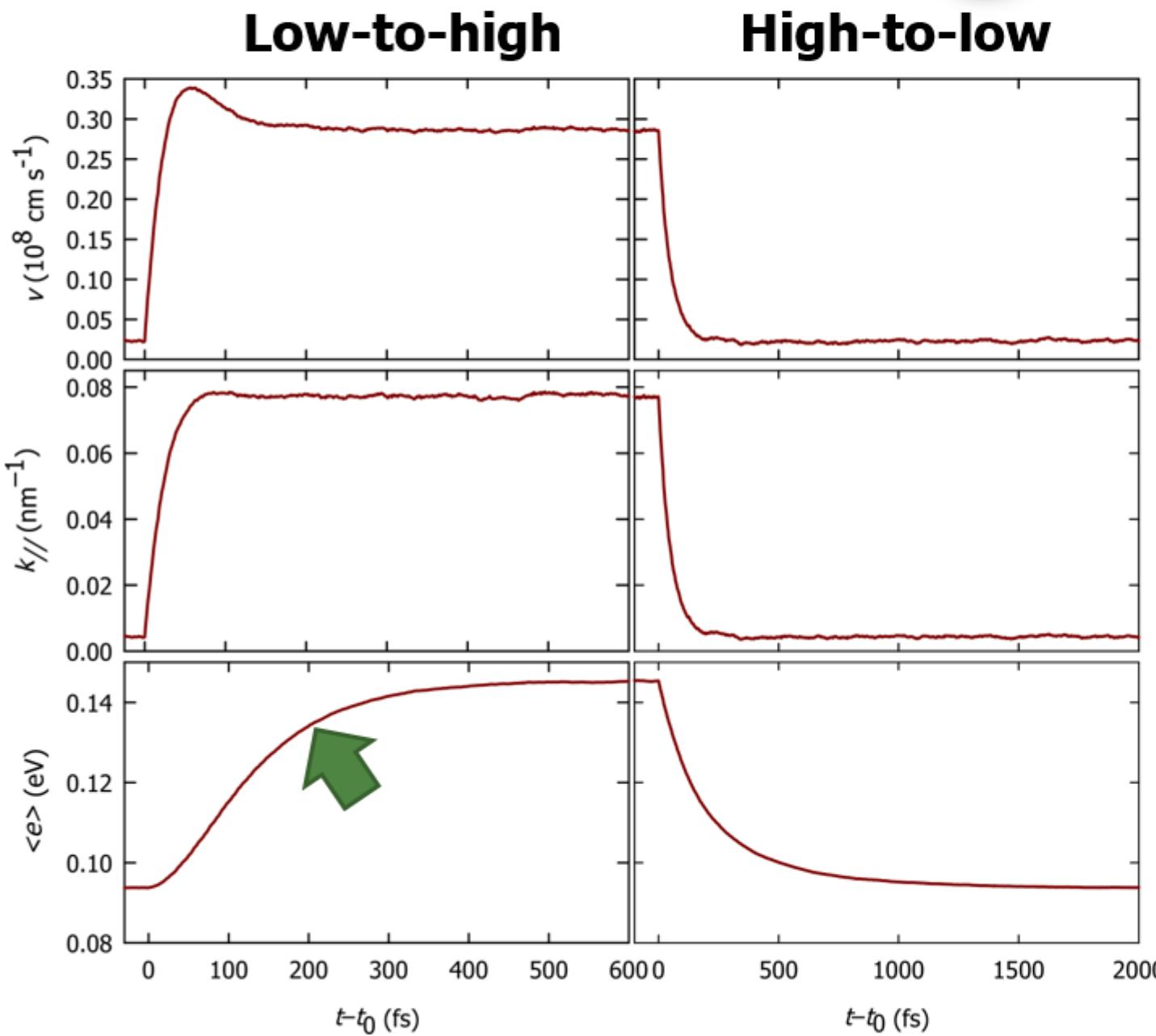
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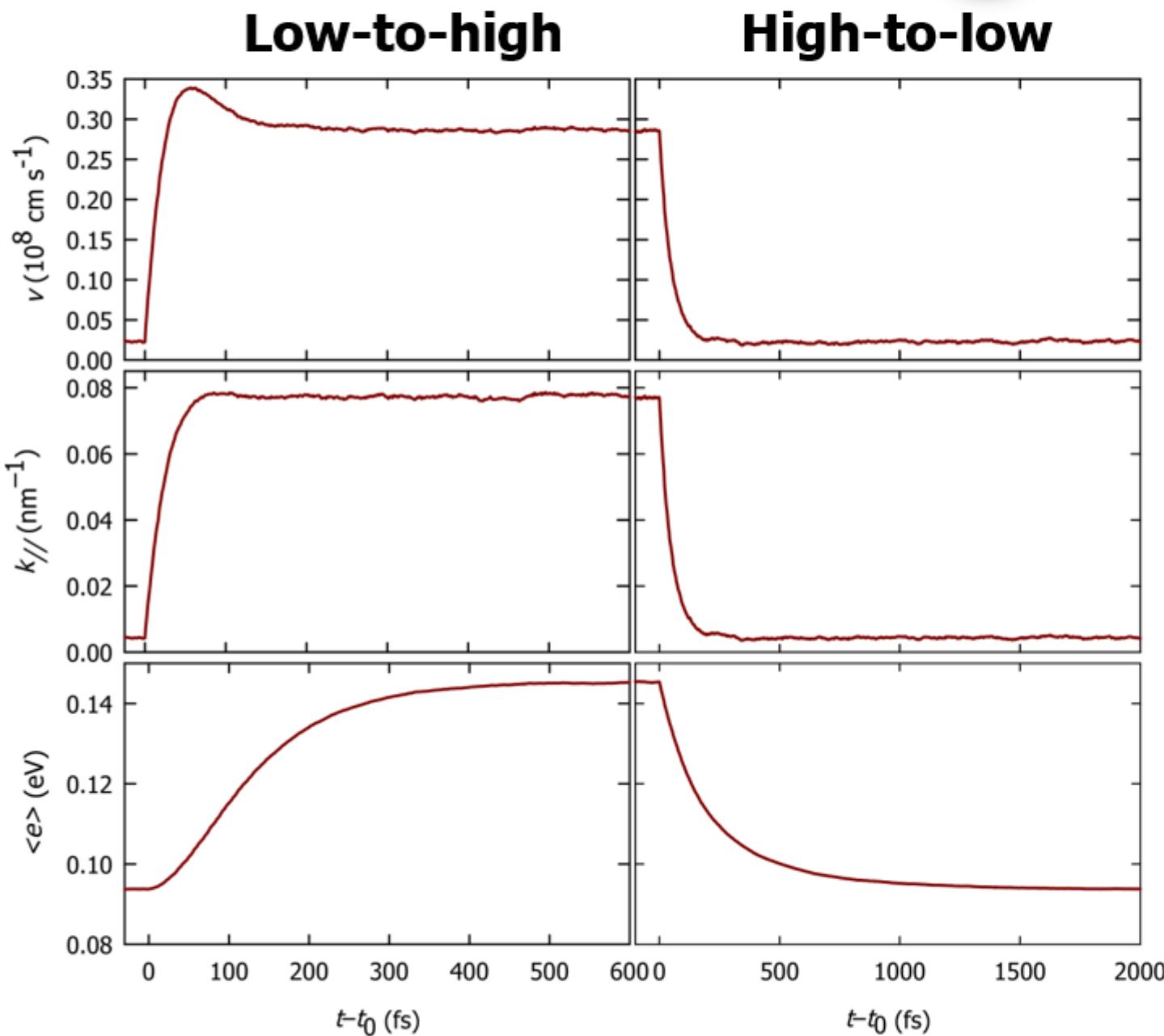
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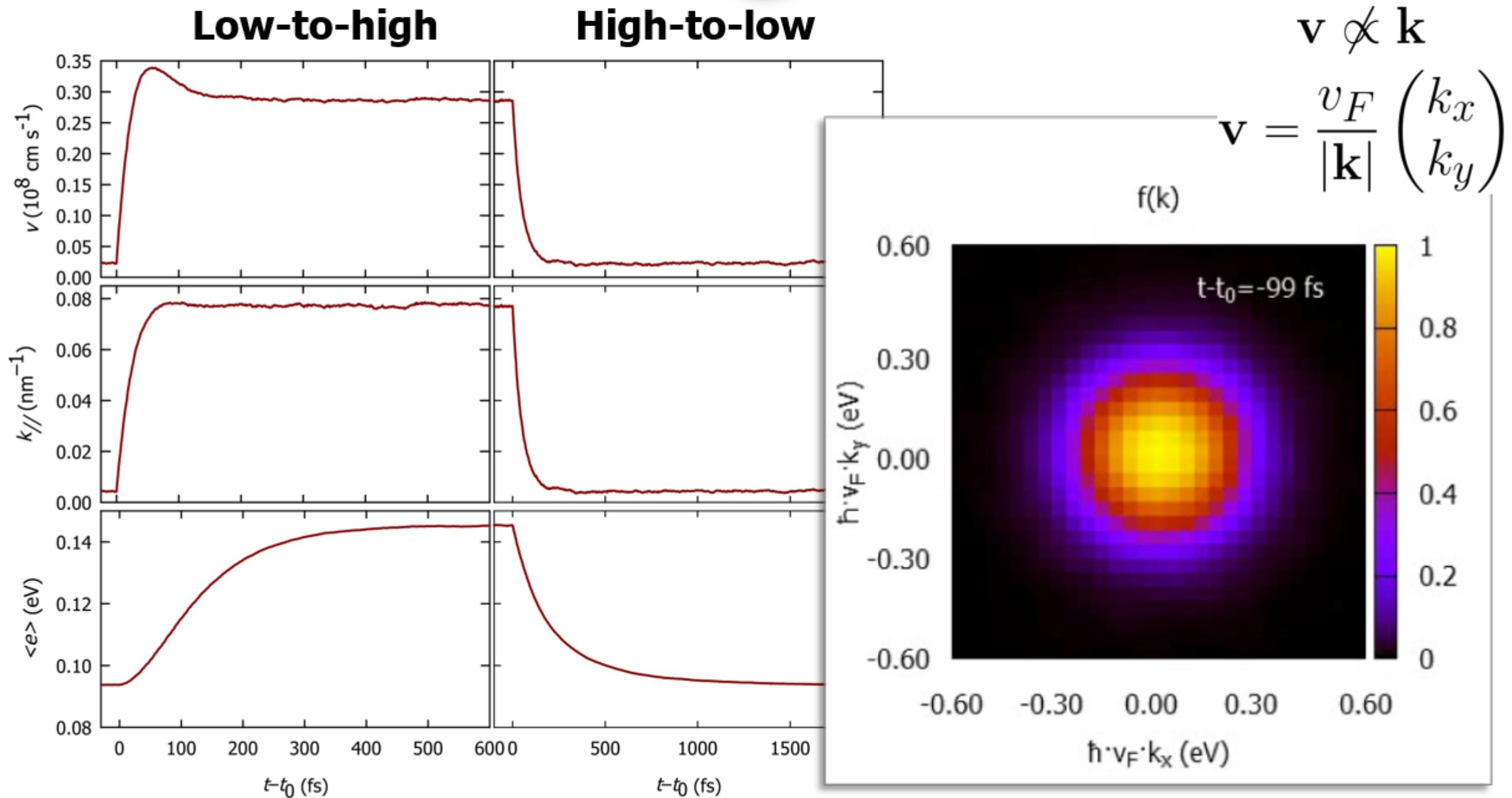


$$v \propto k$$

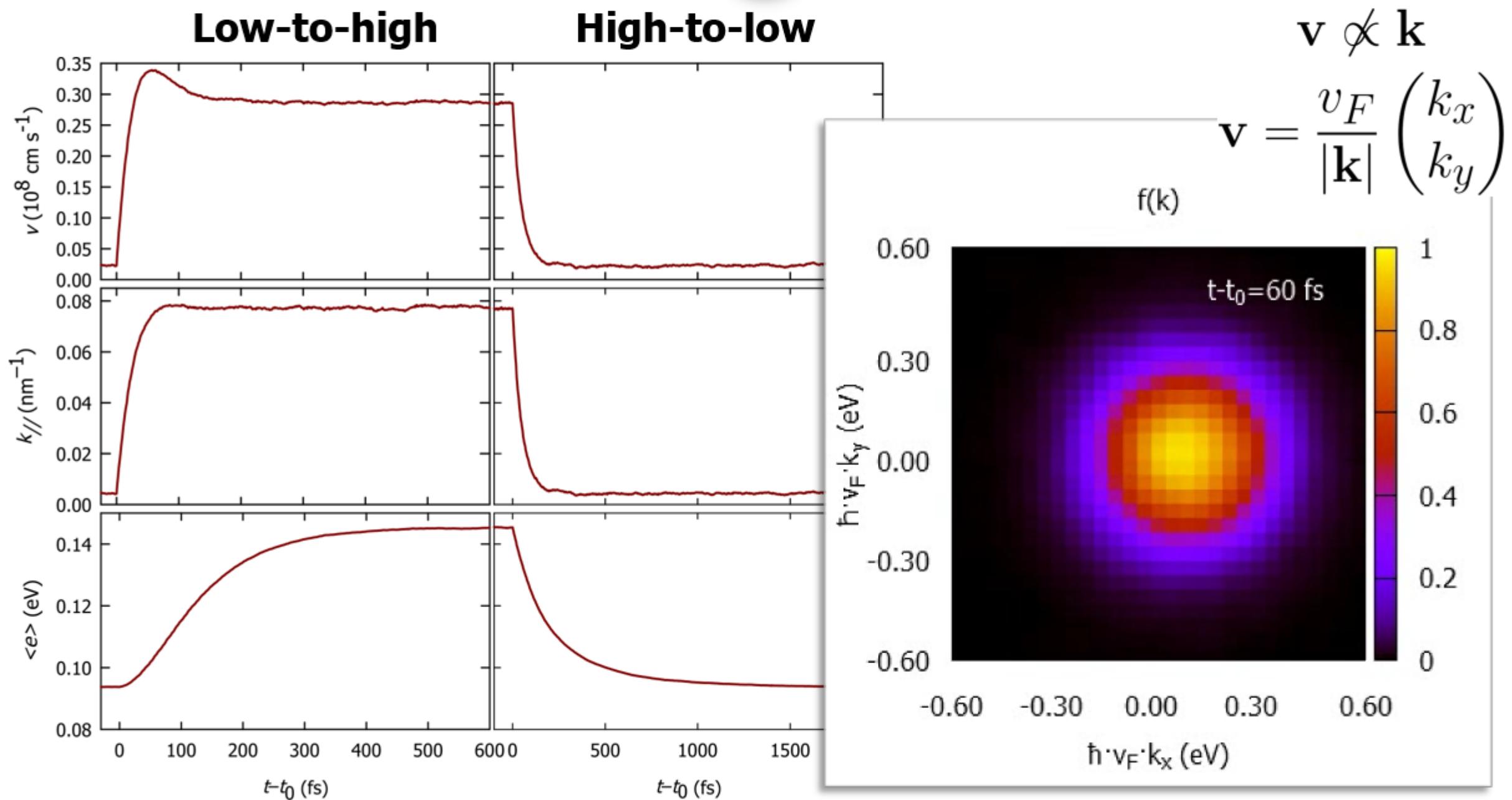
$$\mathbf{v} = \frac{v_F}{|\mathbf{k}|} \begin{pmatrix} k_x \\ k_y \end{pmatrix}$$

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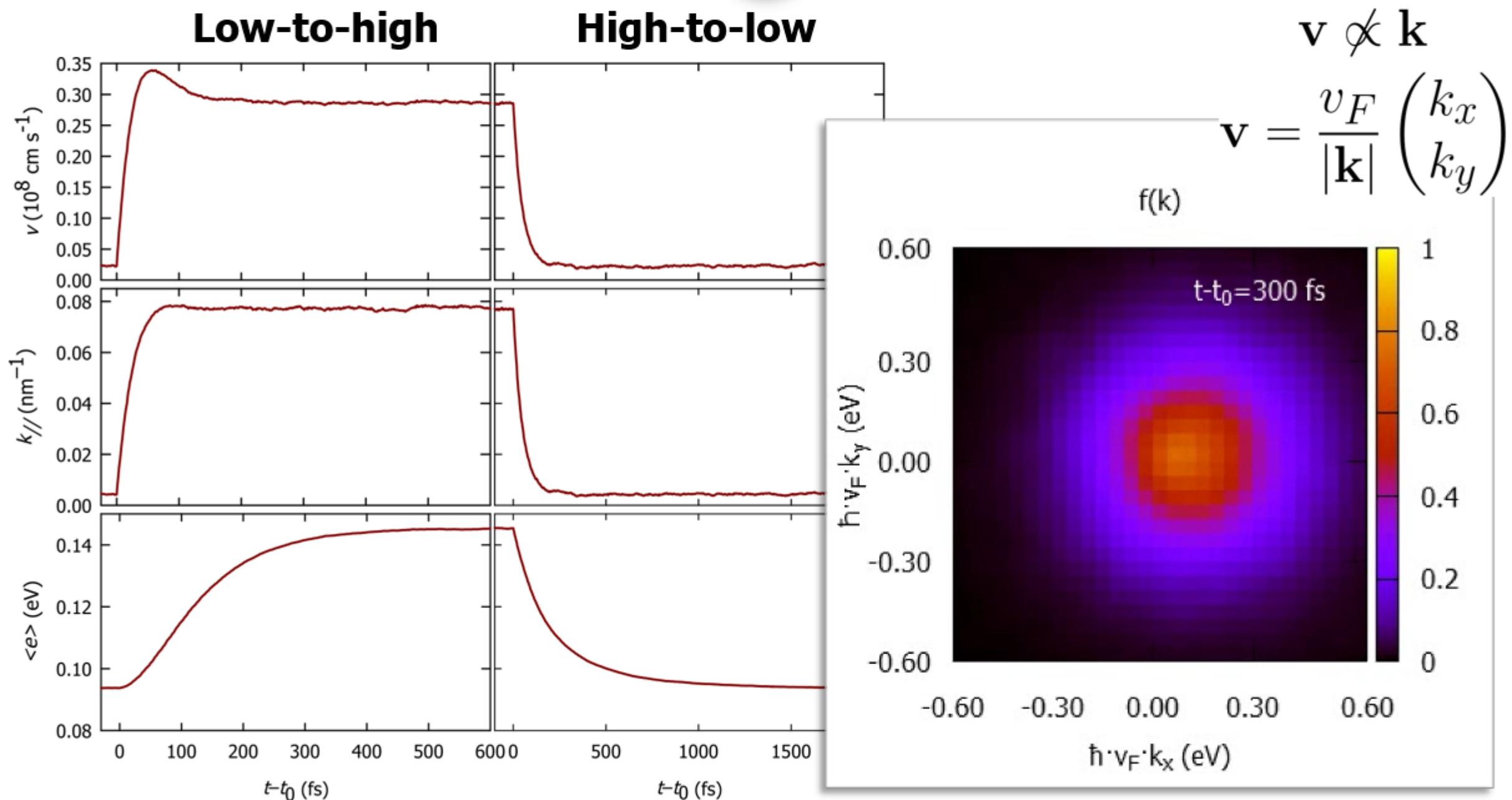
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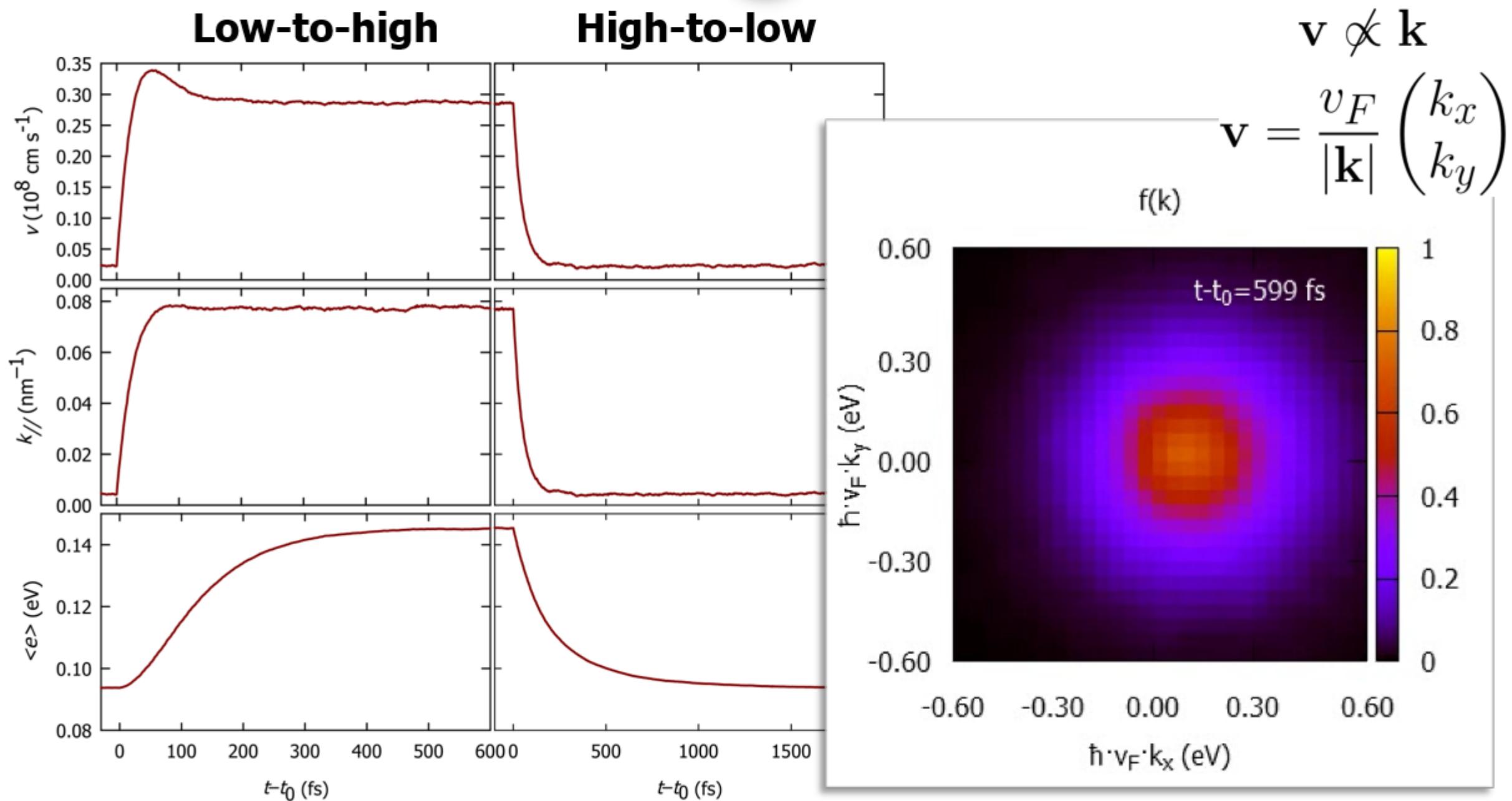
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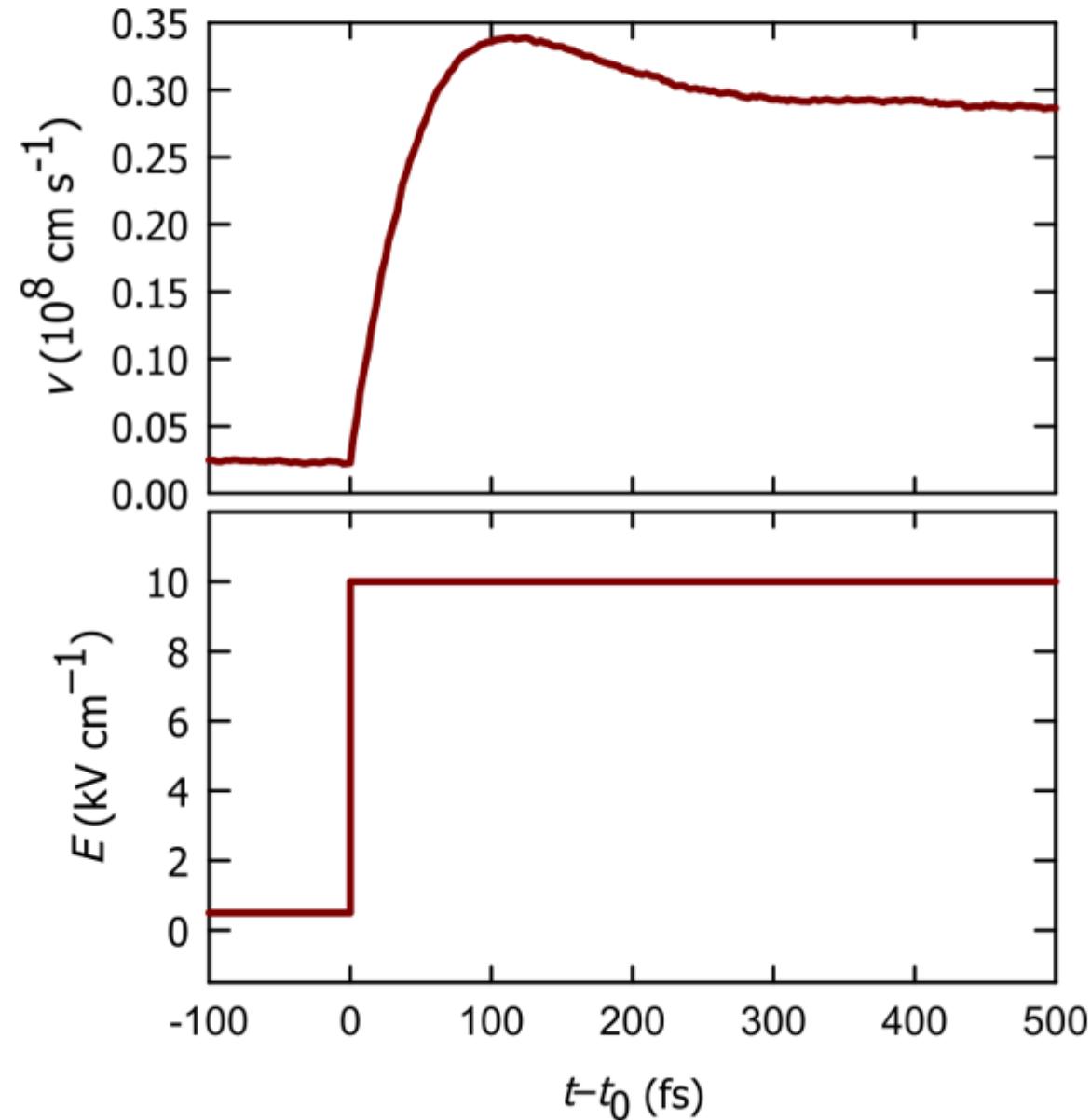
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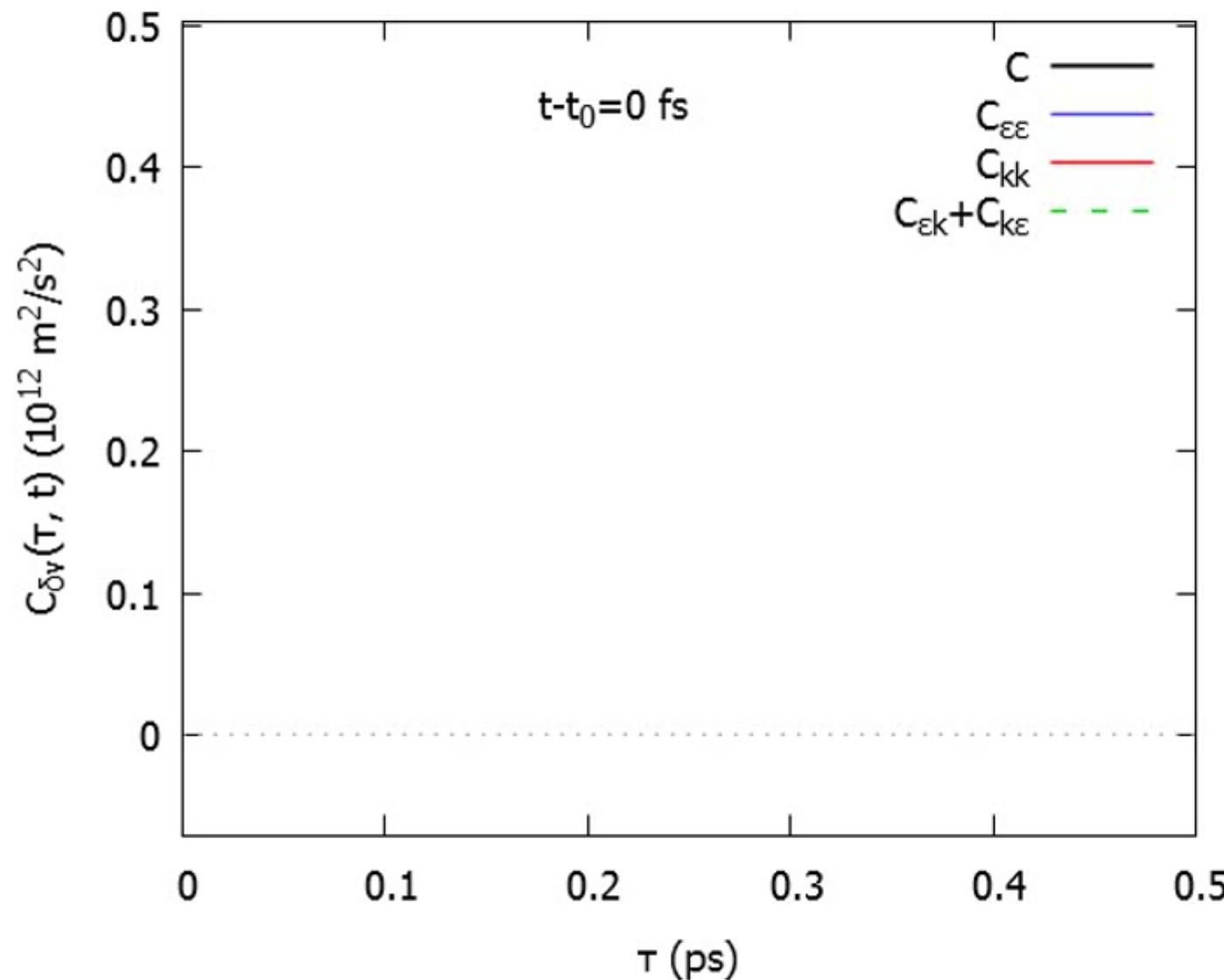
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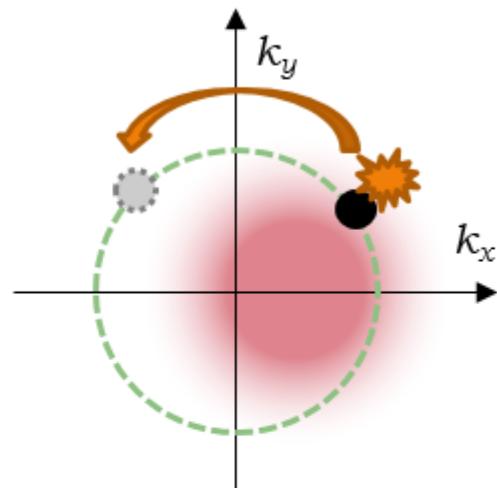


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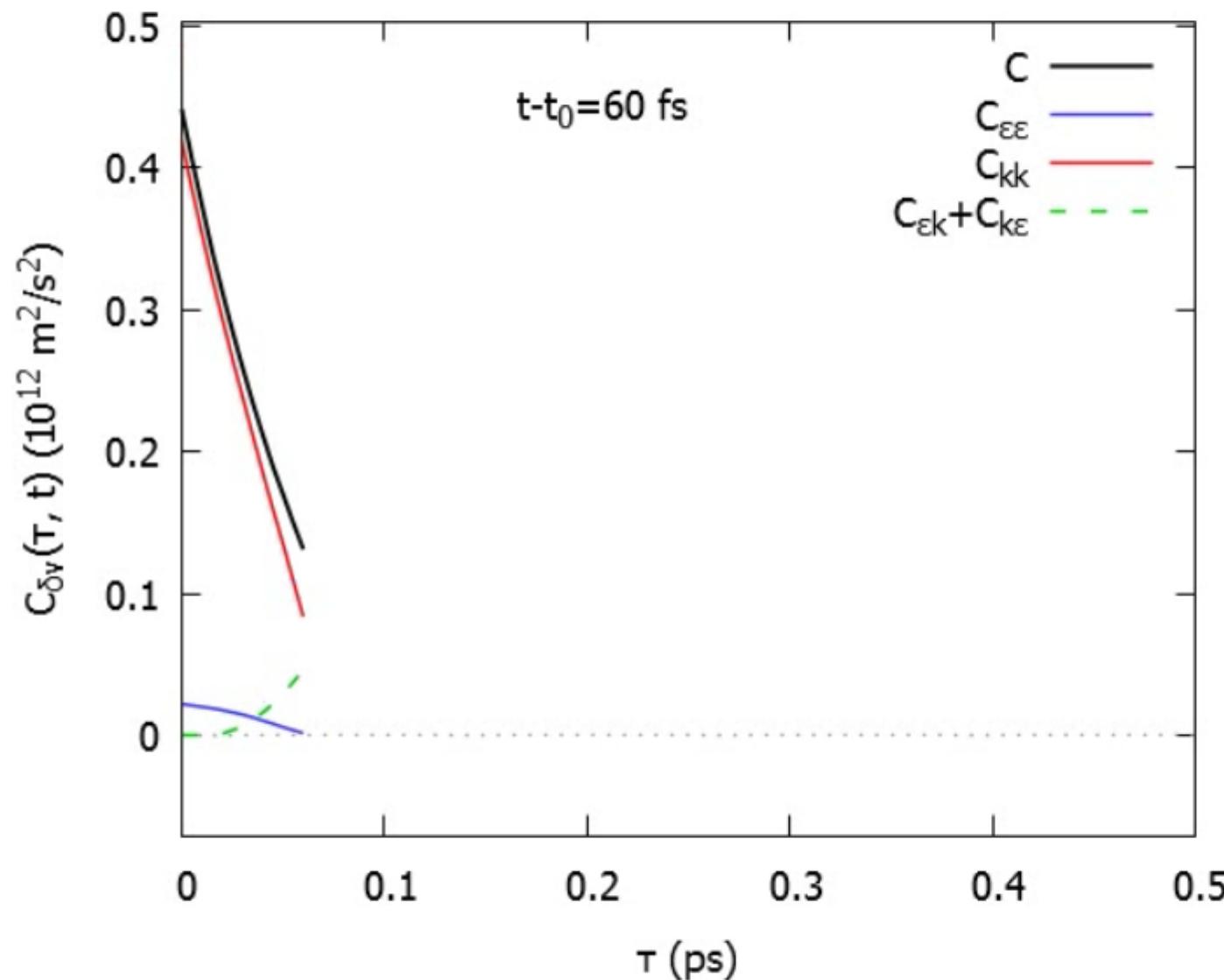


$C_{kk}$   
Fast change in the fluctuation sign  
as a consequence of fast  
momentum (velocity) reorientation:

- Dragging of the electric field
- ↑↑ Energy → ↑↑ Scattering

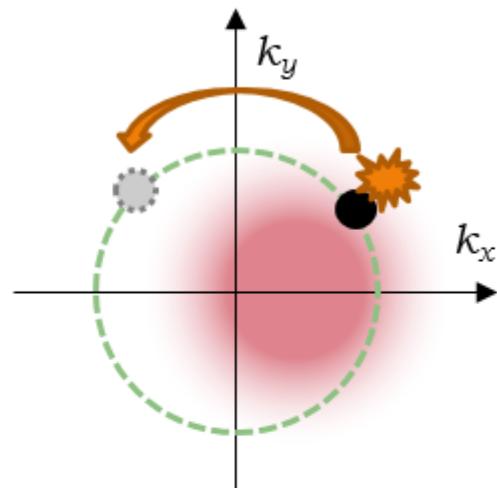


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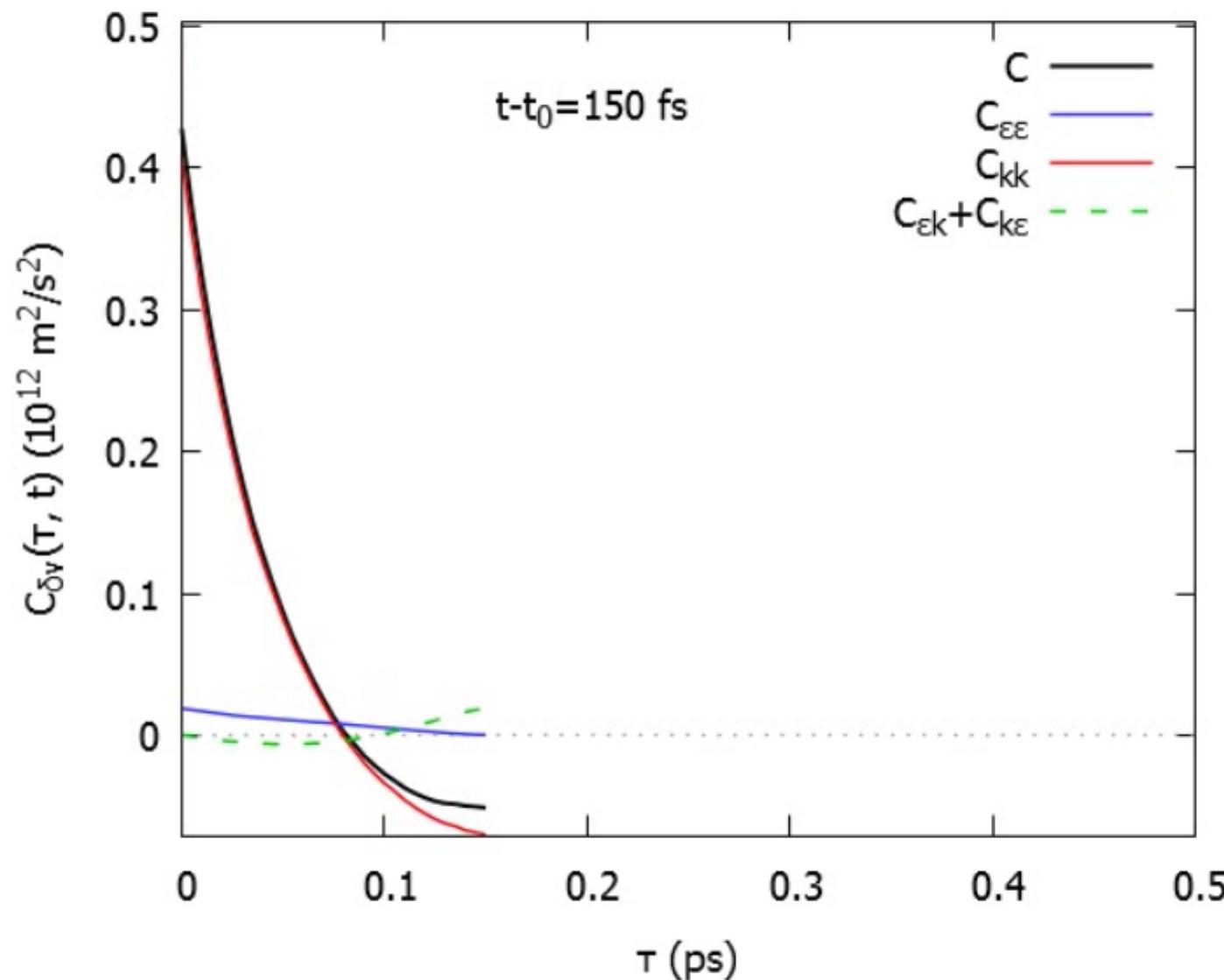


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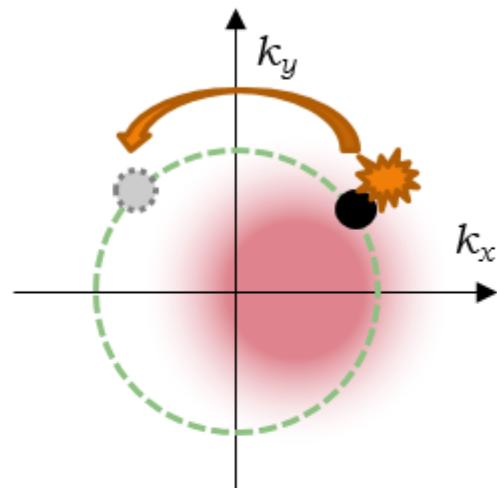


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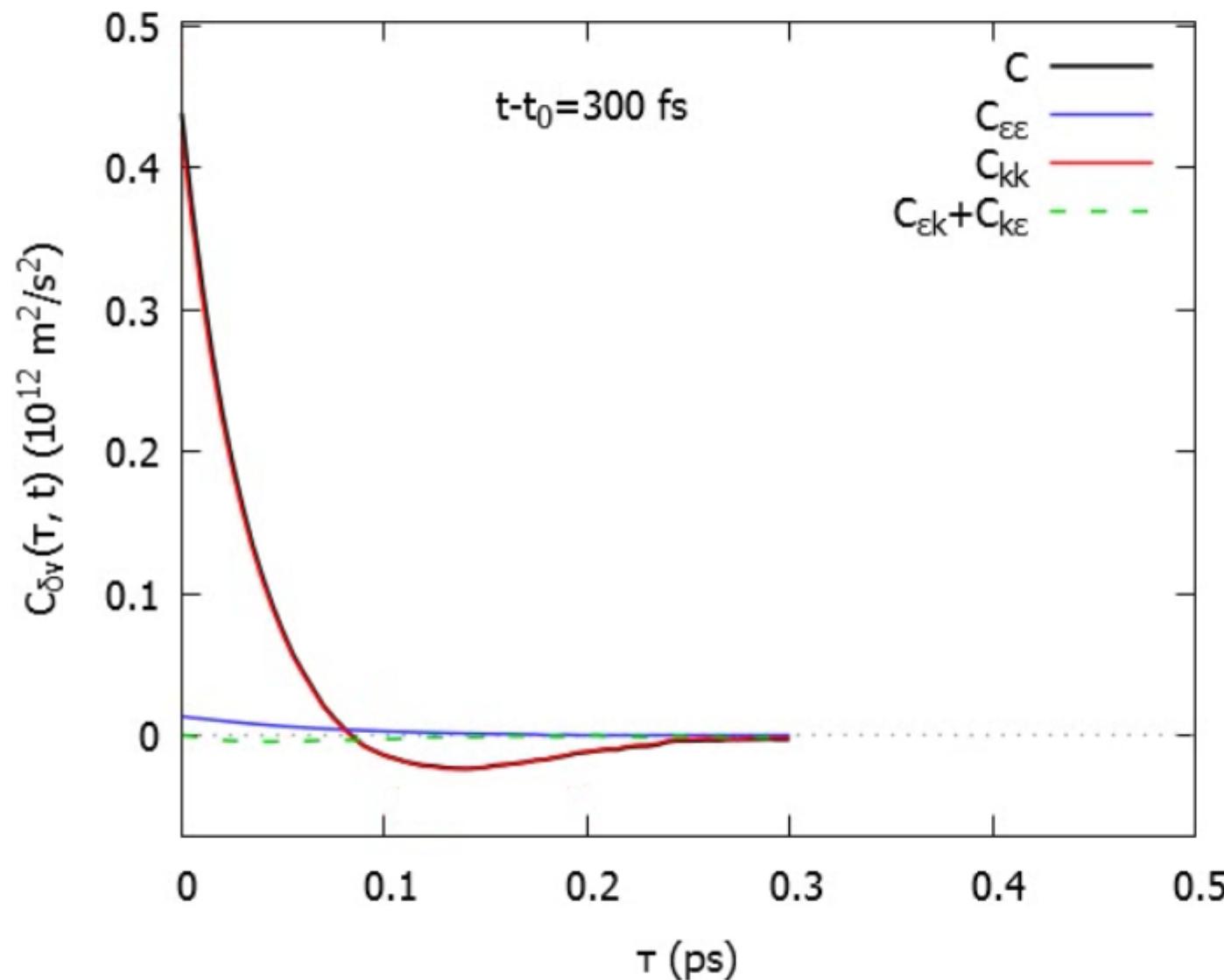


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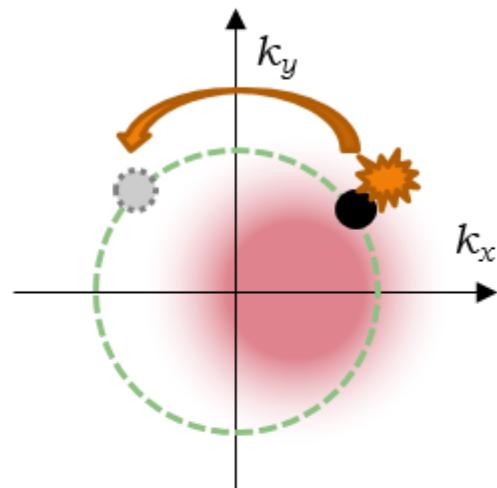


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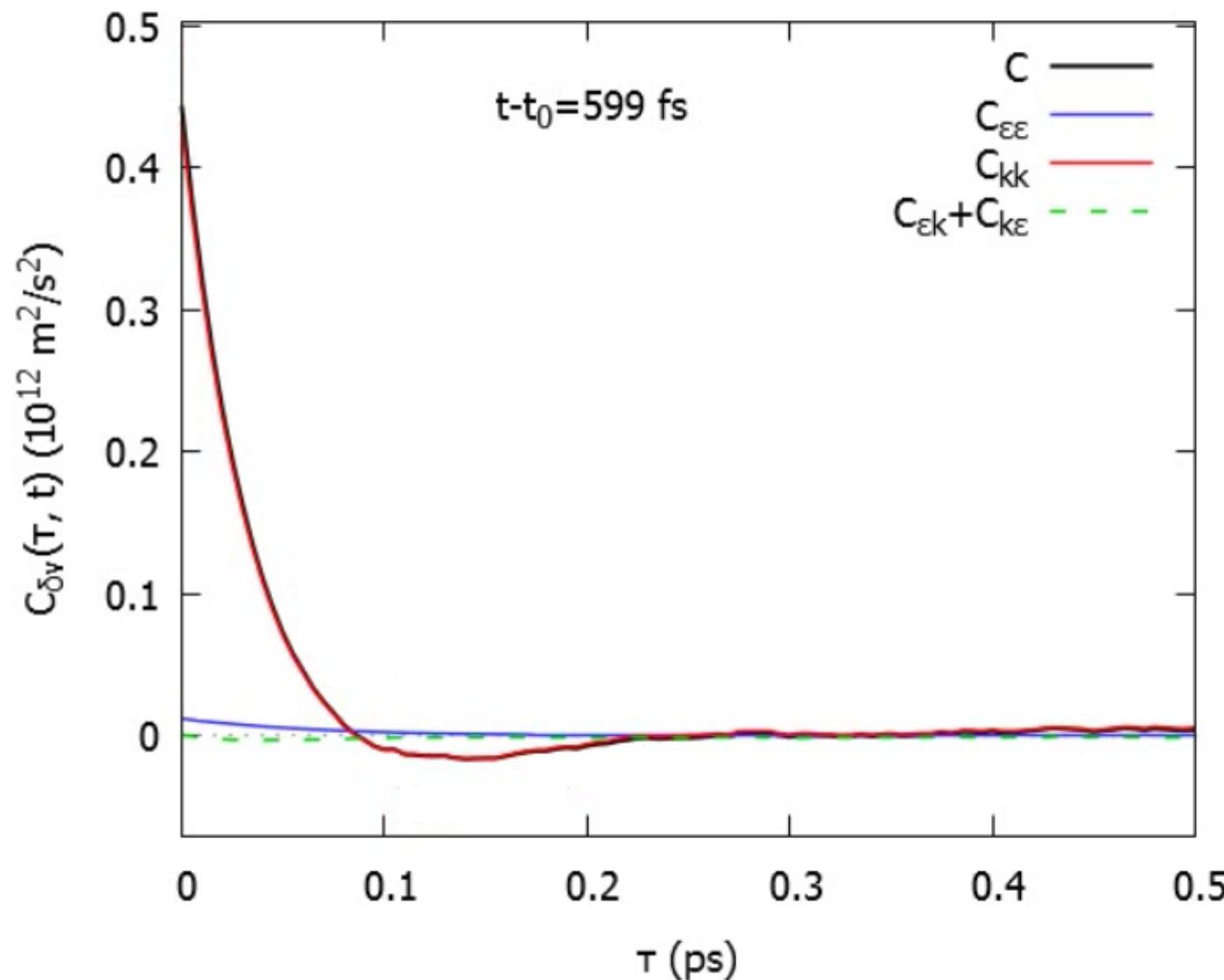


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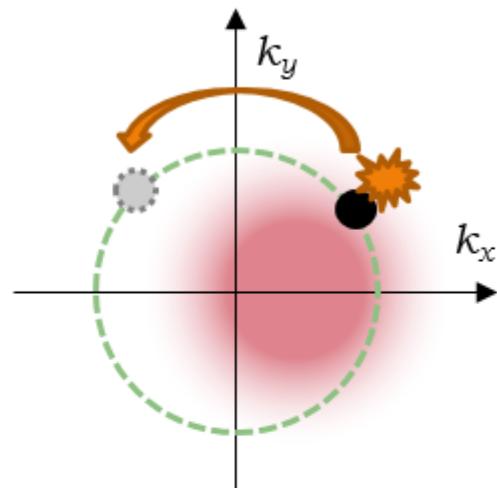


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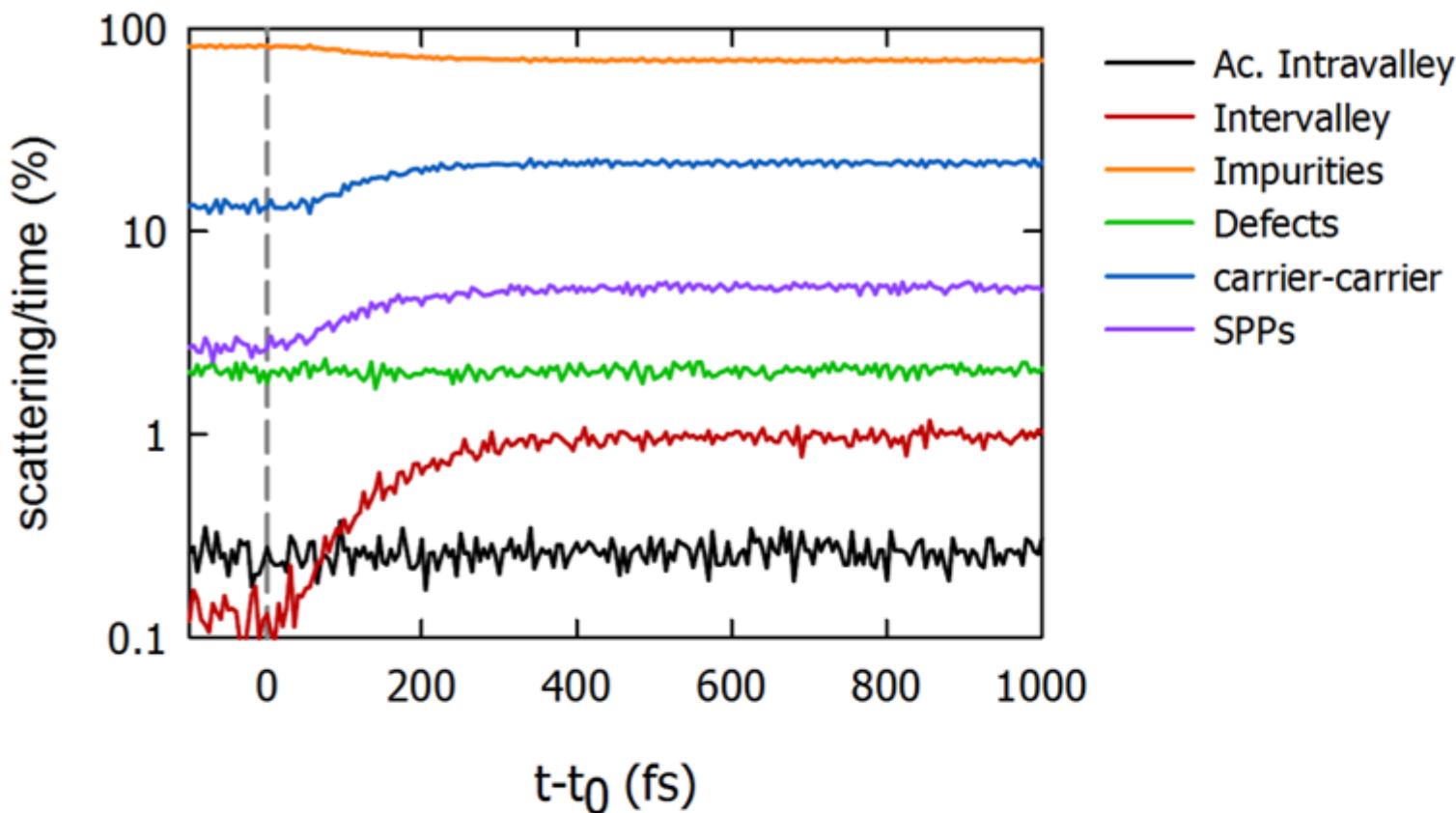


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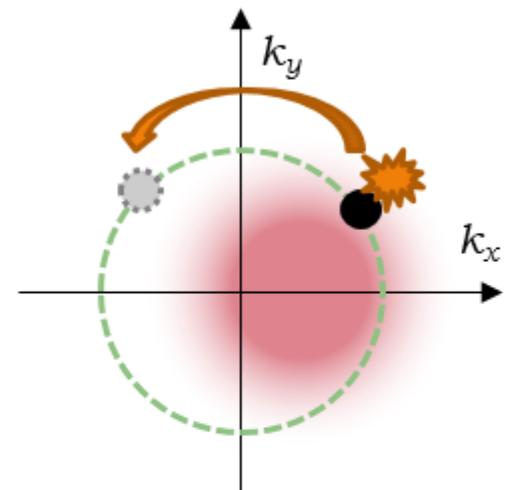


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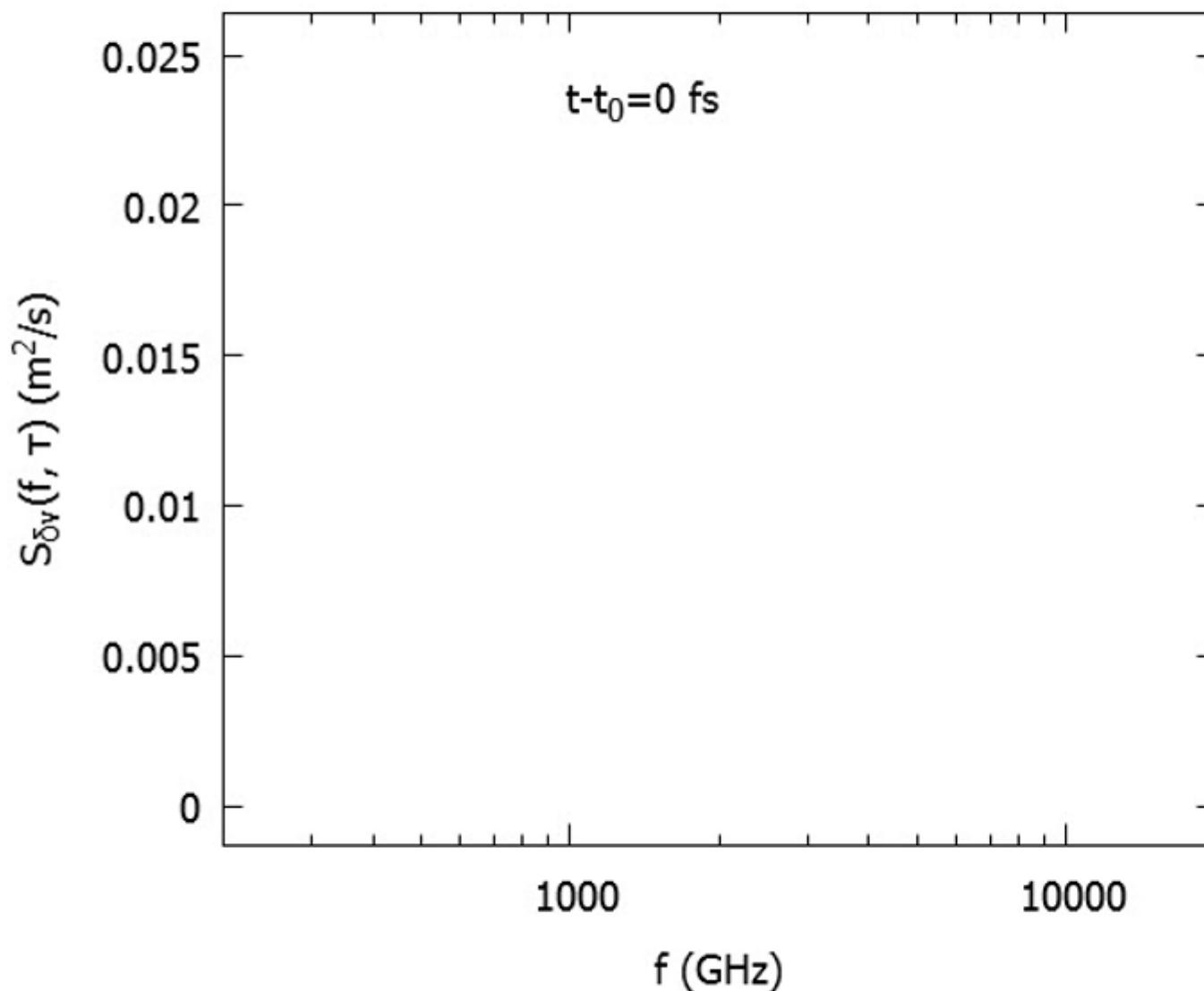


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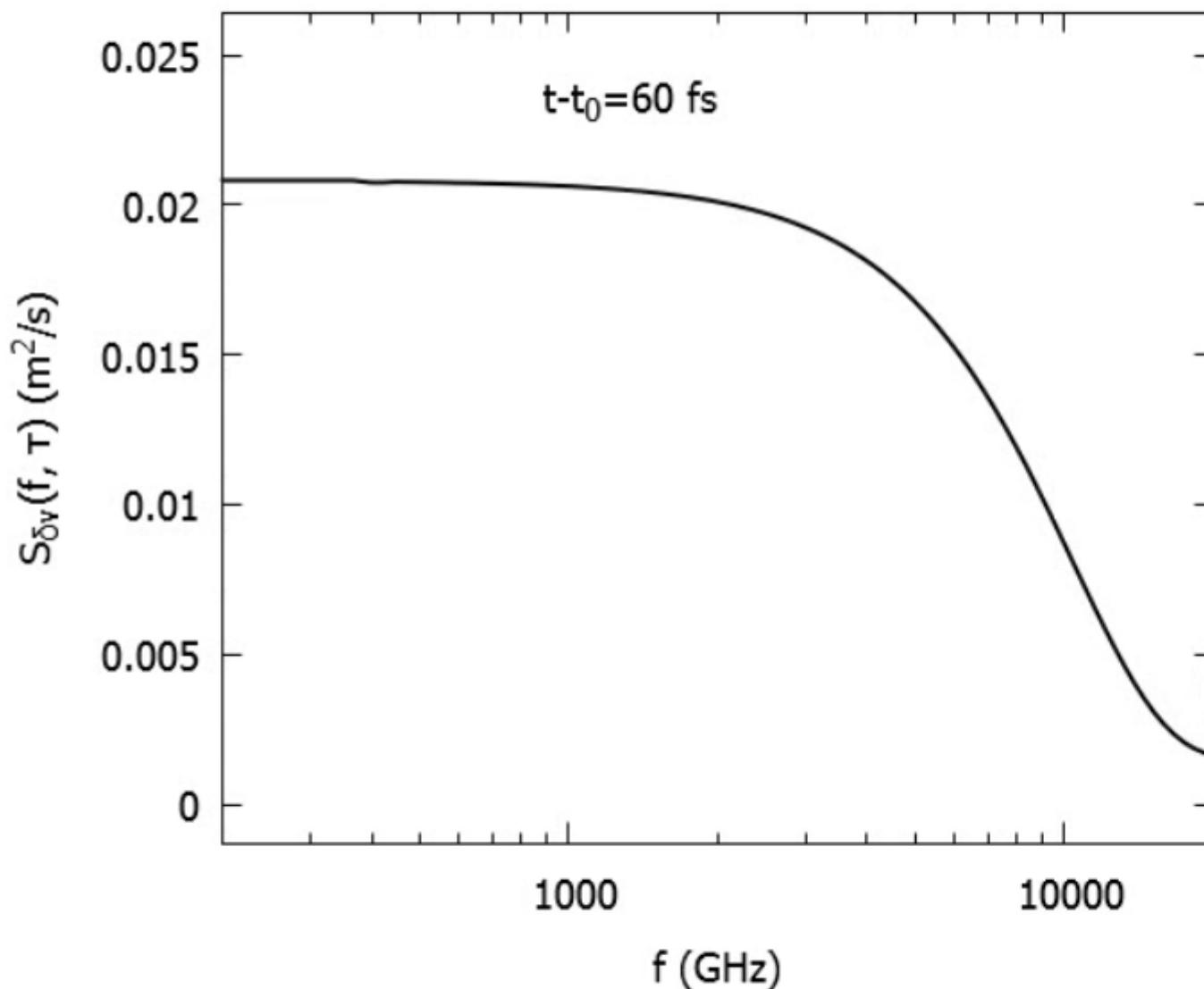


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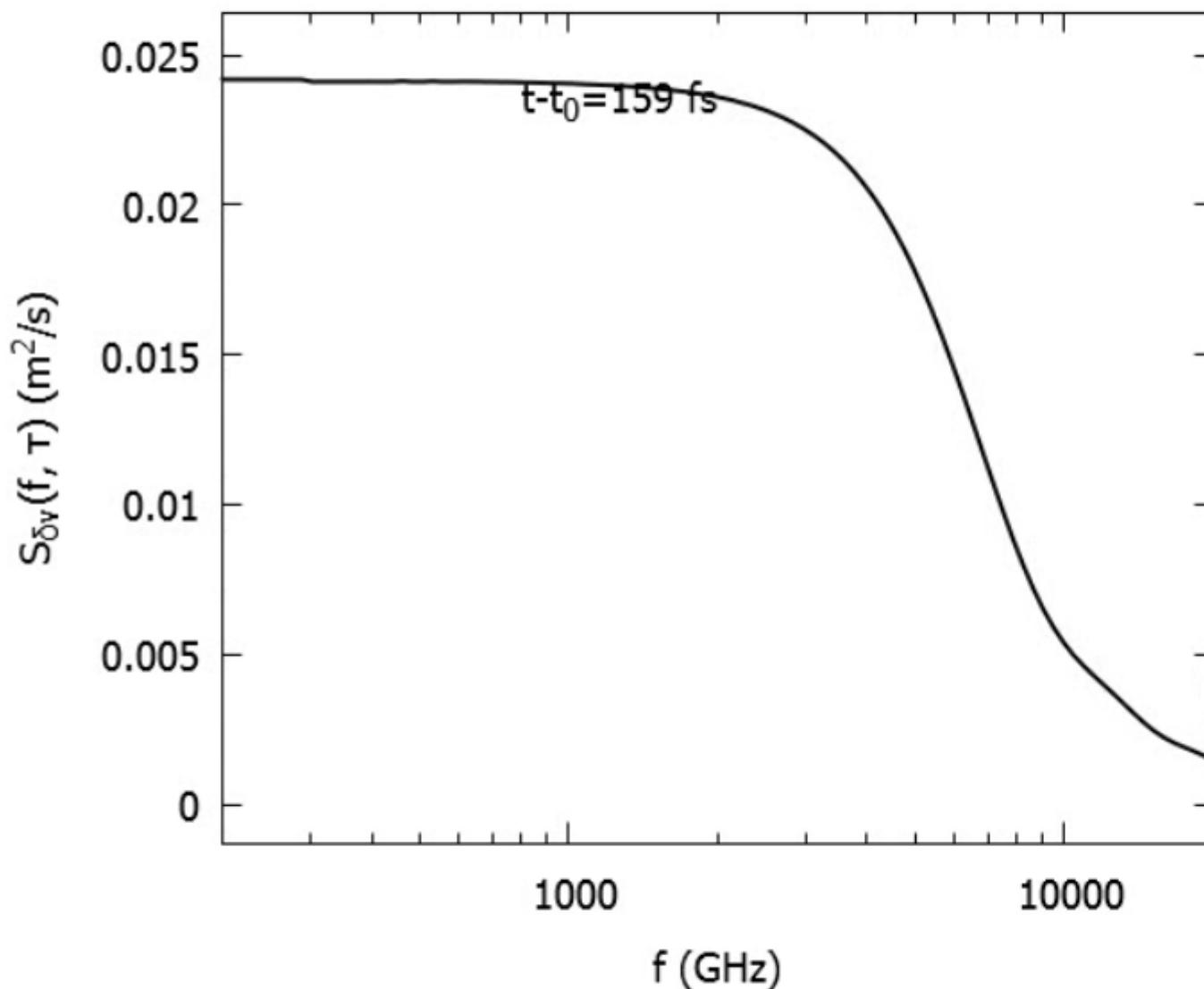
- Lorentzian shape up to 160 fs (Correlation minimum)
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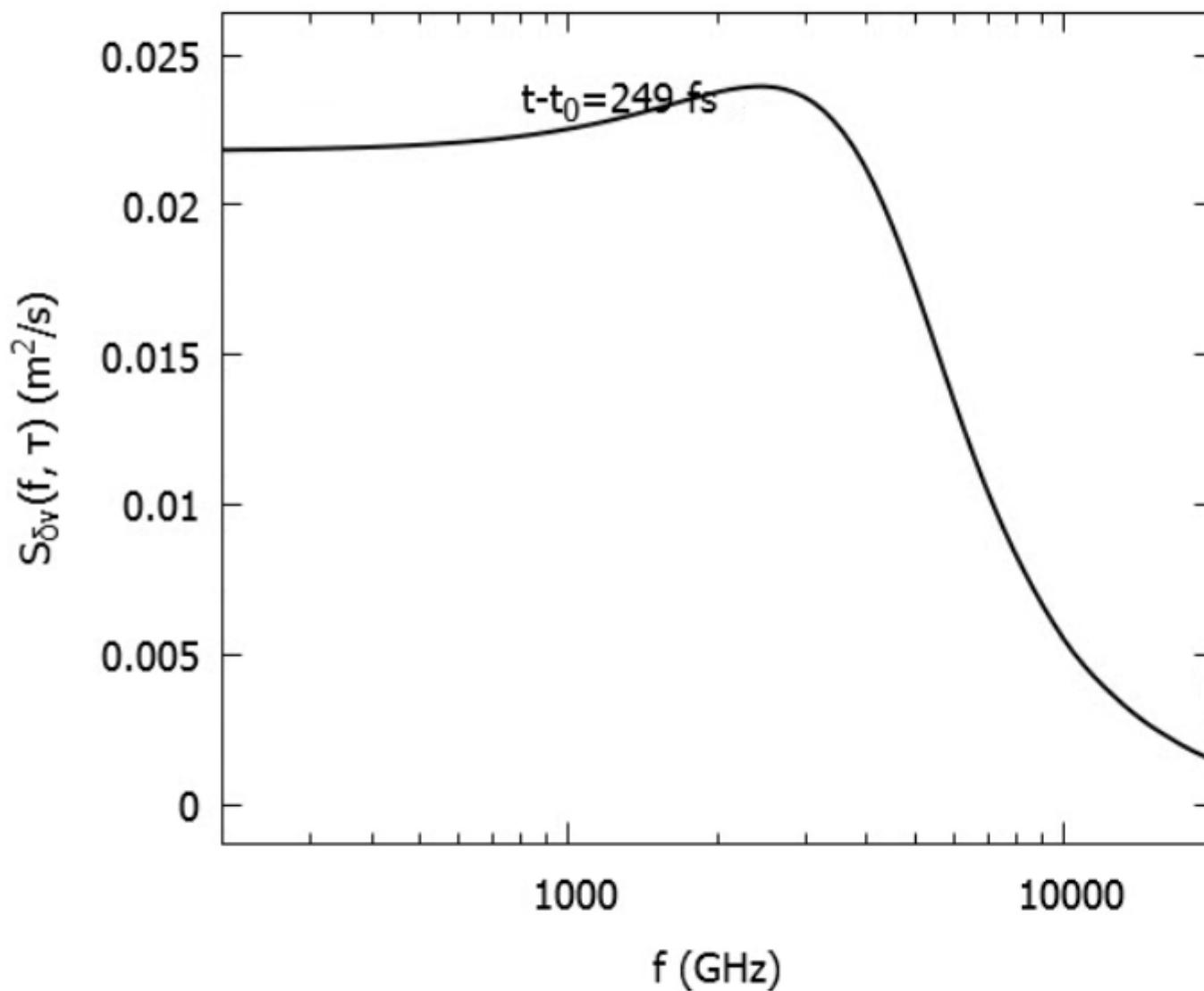
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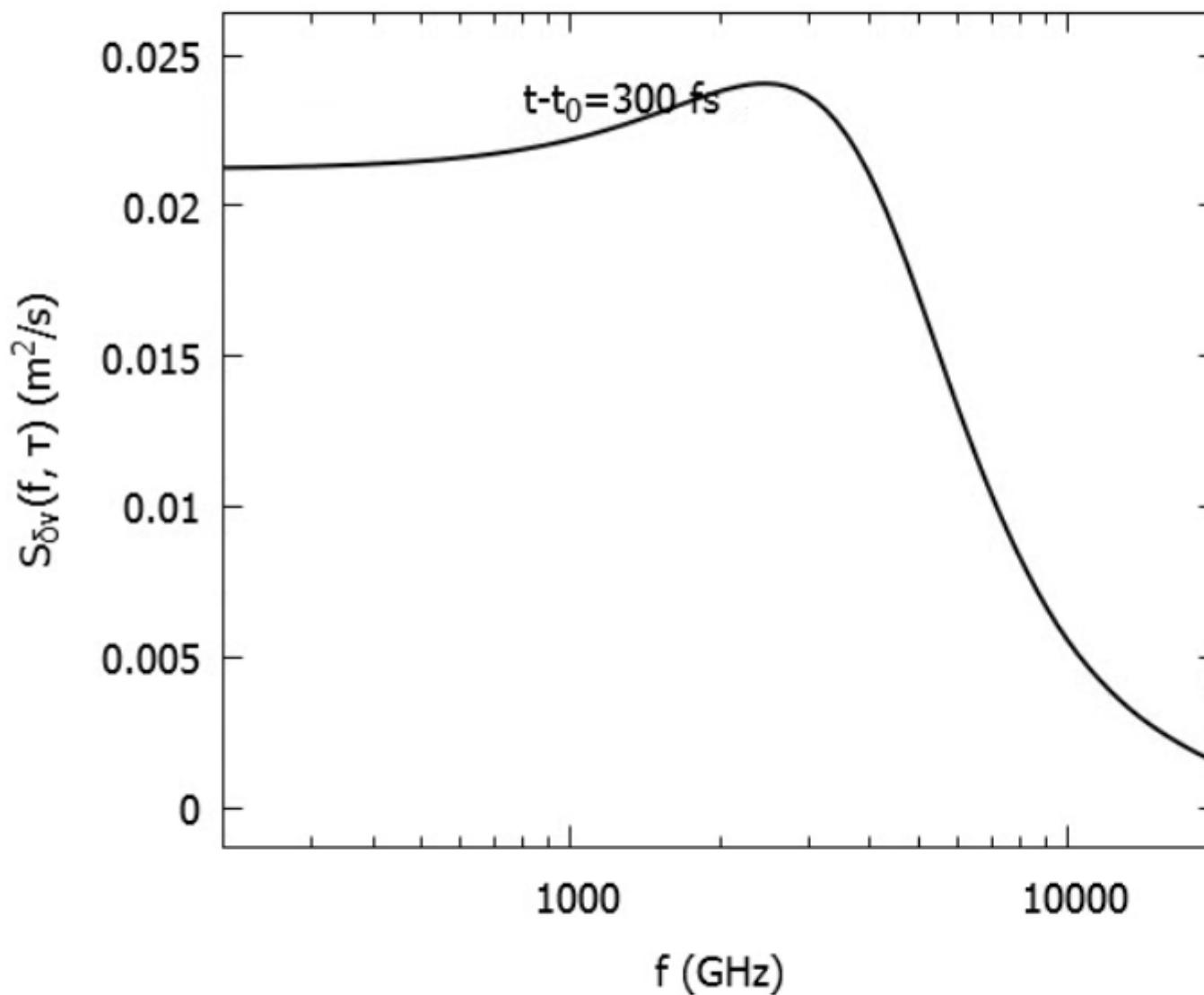
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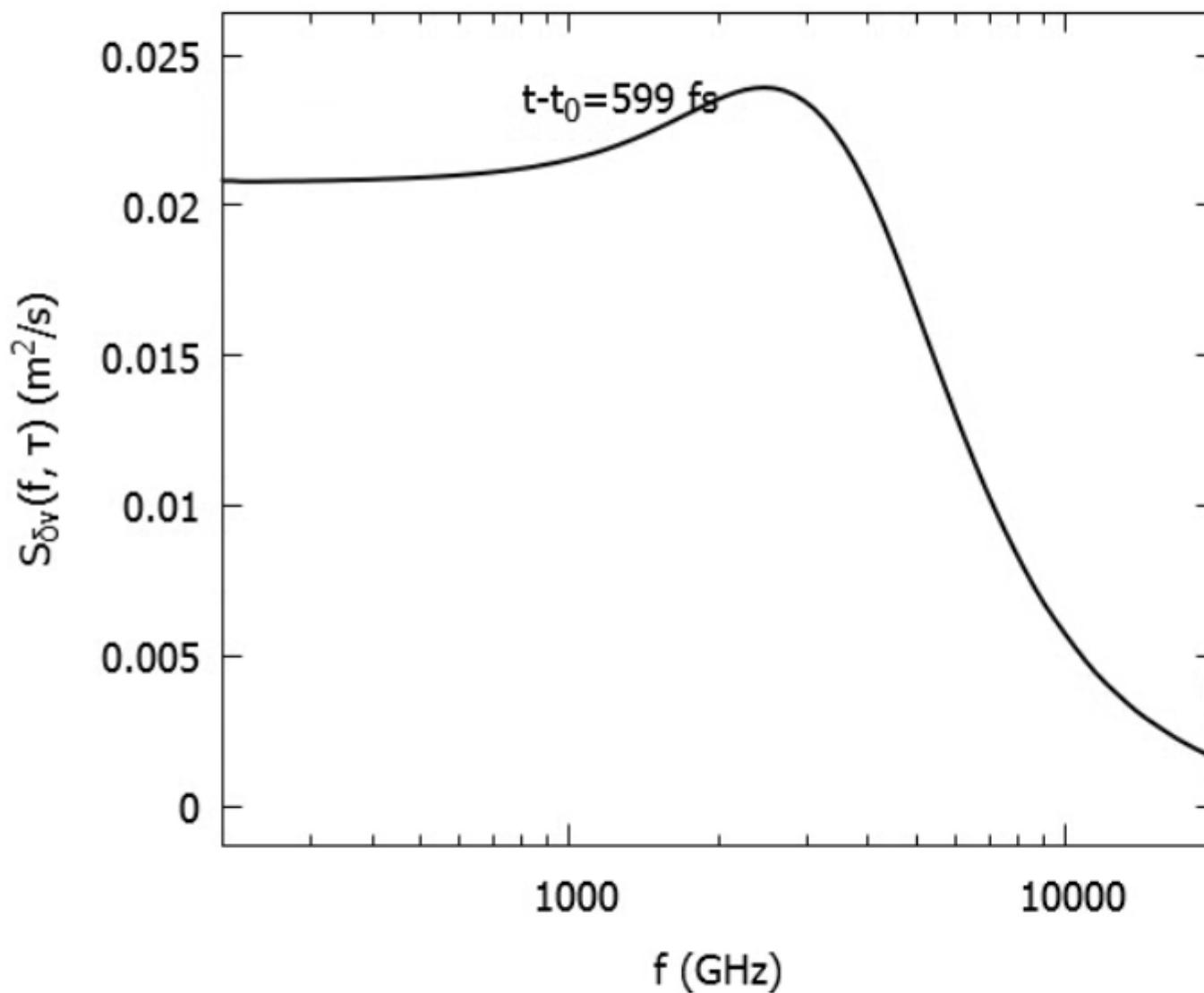
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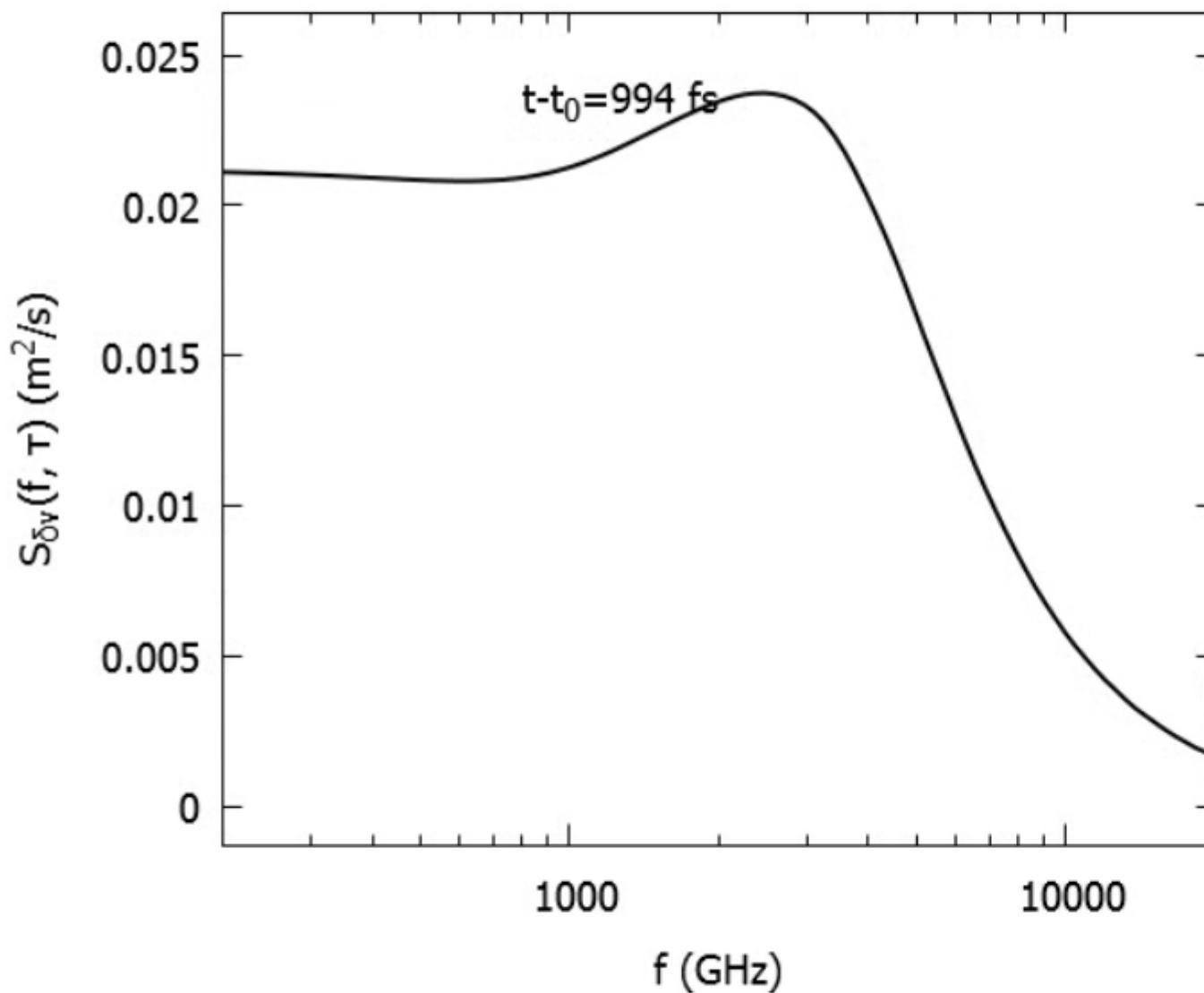
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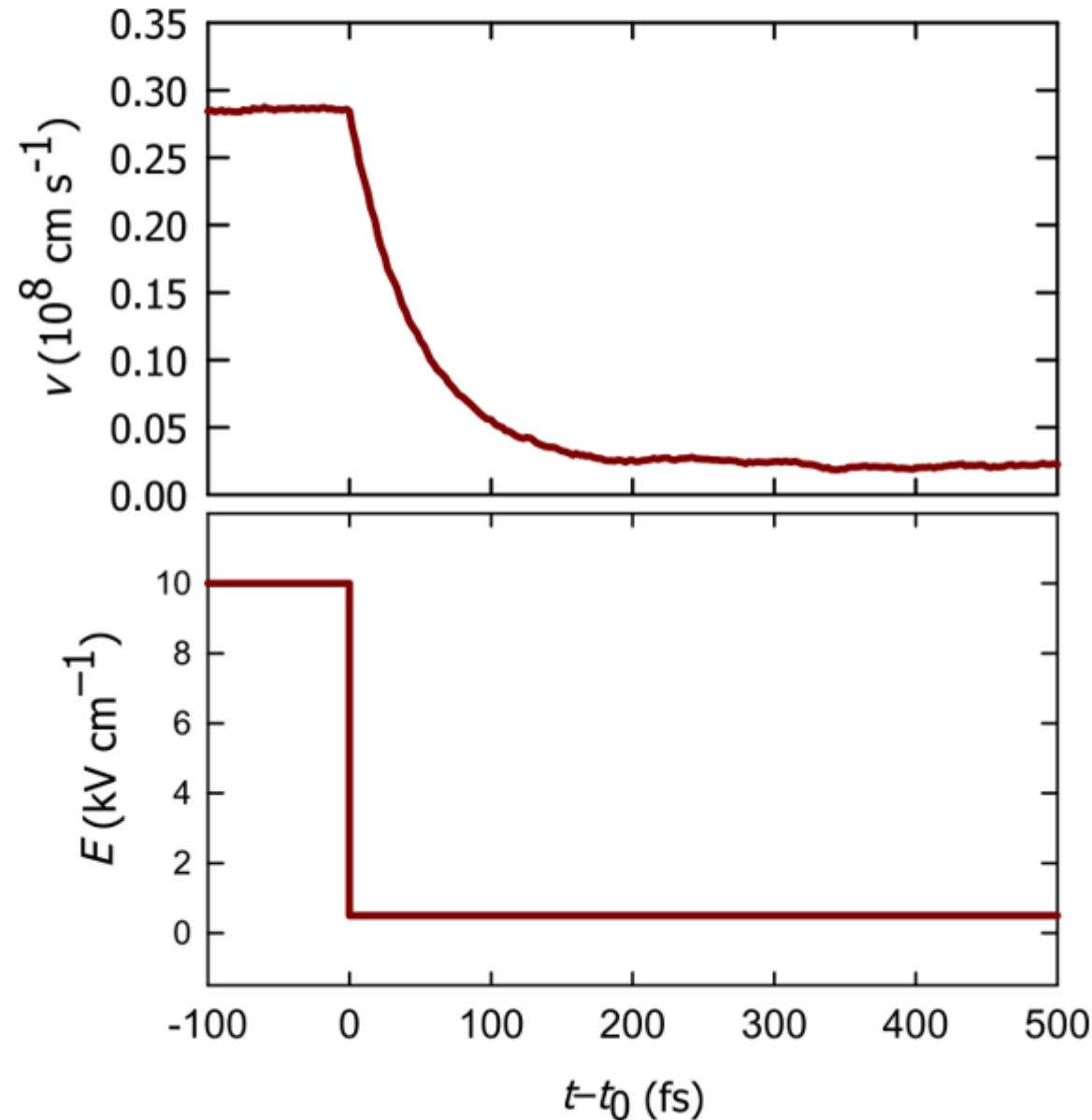
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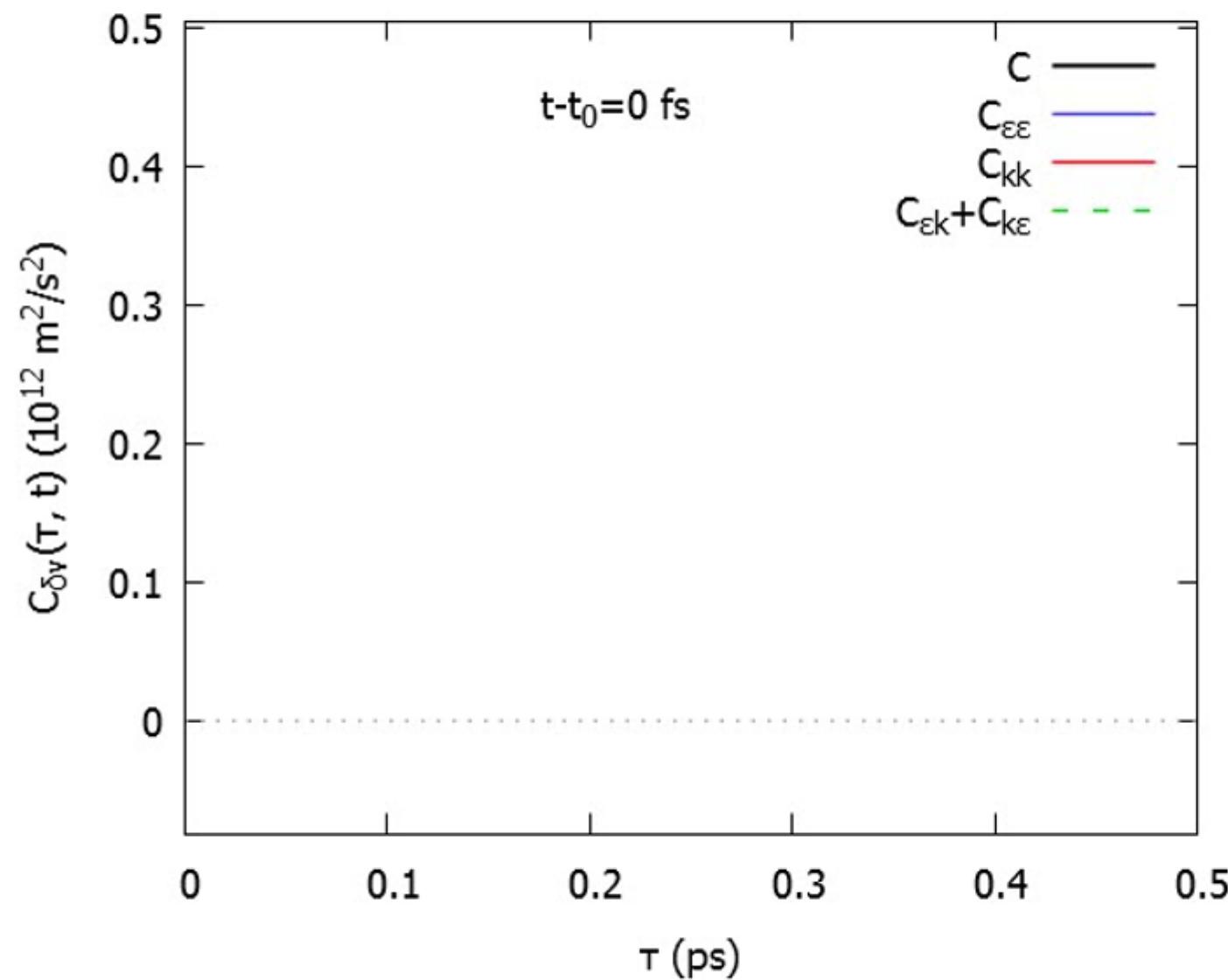


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- Stronger correlation at longer times indicates decreasing scattering activity.

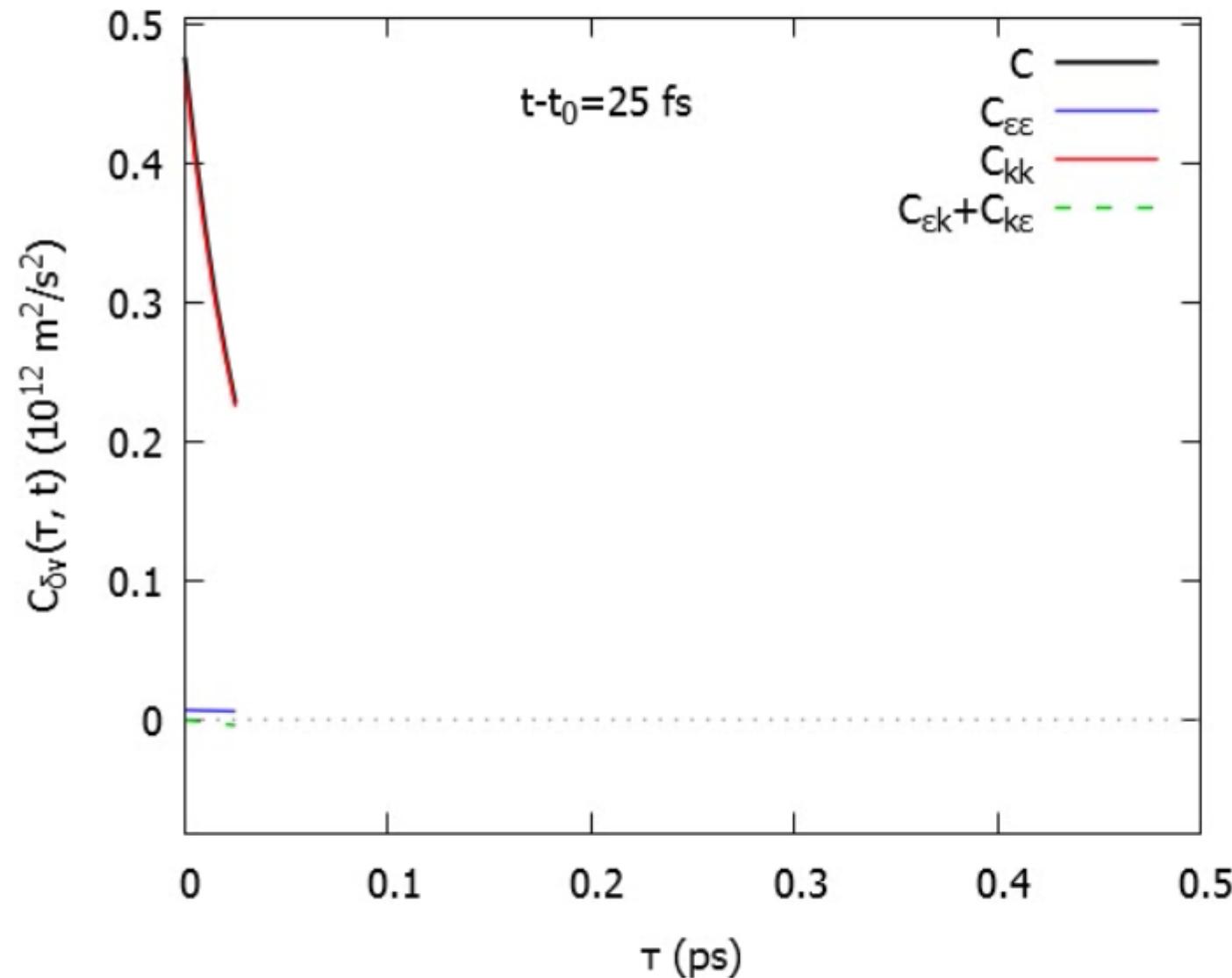
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No redistribution of the averaged velocity for the different energy levels

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A high-to-low field transient is governed by the effect of the scattering mechanisms.

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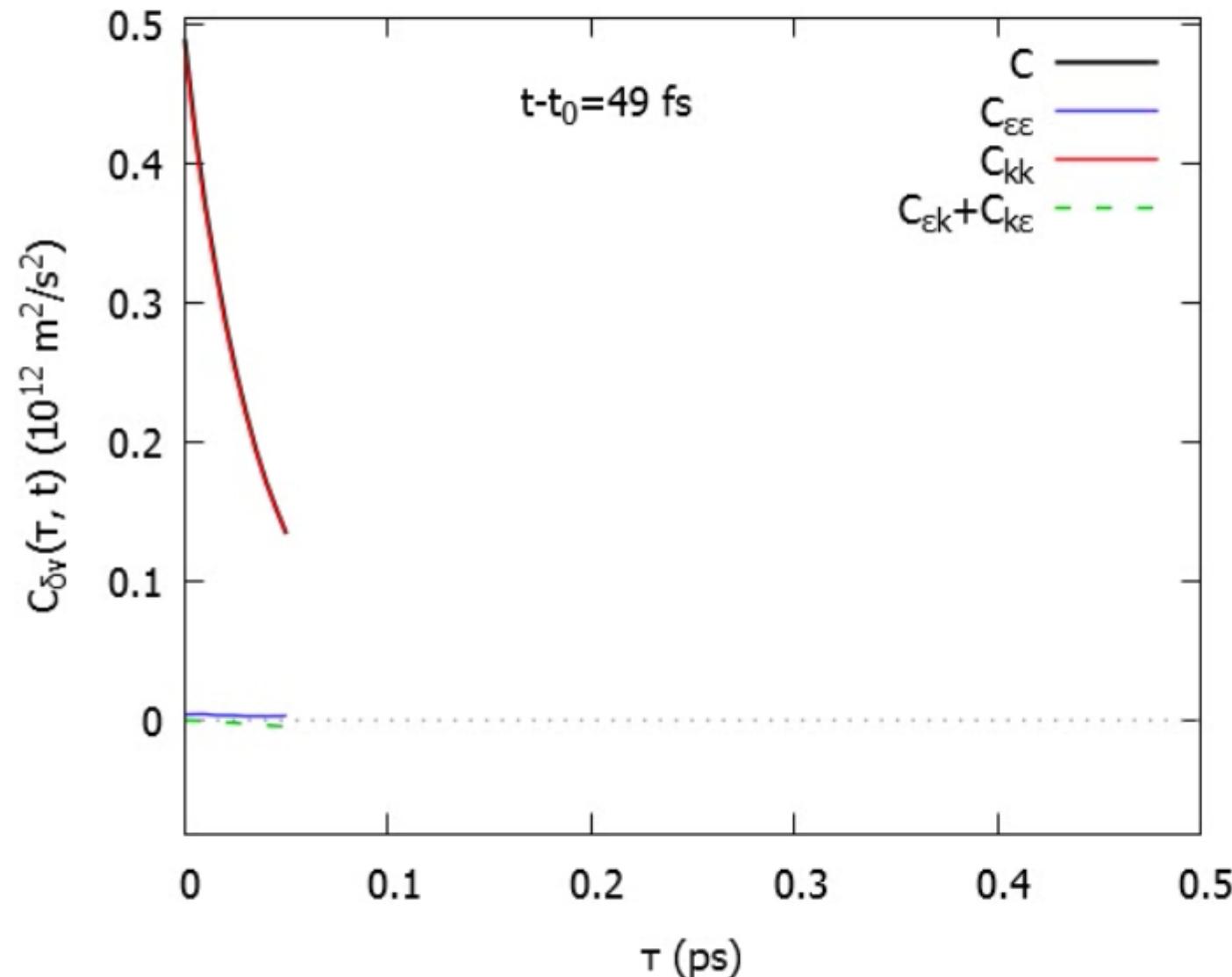
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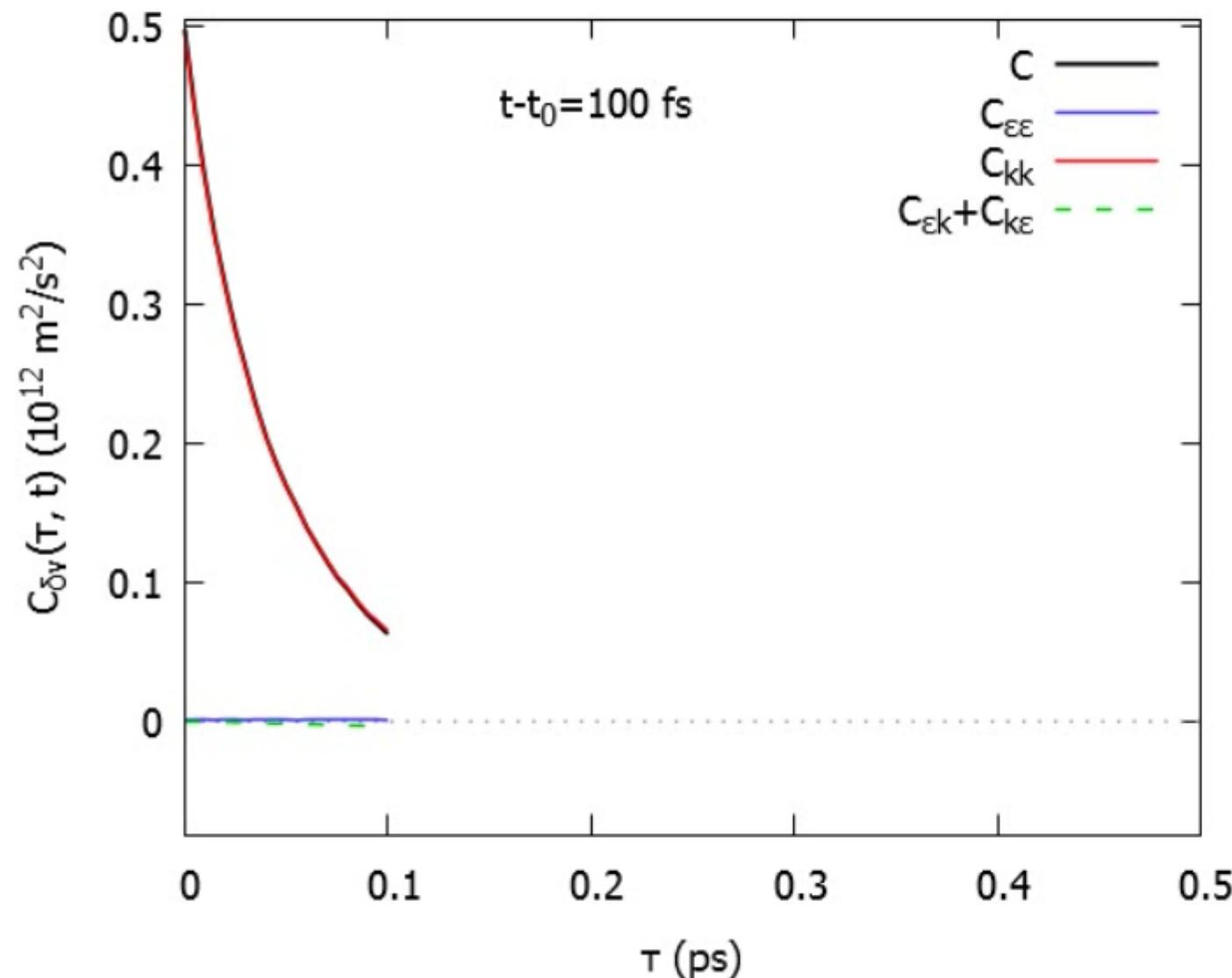
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# Graphene on SiO<sub>2</sub>; **high to low** field: Transient Autocorrelation Function



- Strong **initial decay** of the autocorrelation at first instants due to remnant high-field energetic distribution.
- Stronger correlation at longer times indicates decreasing scattering activity.

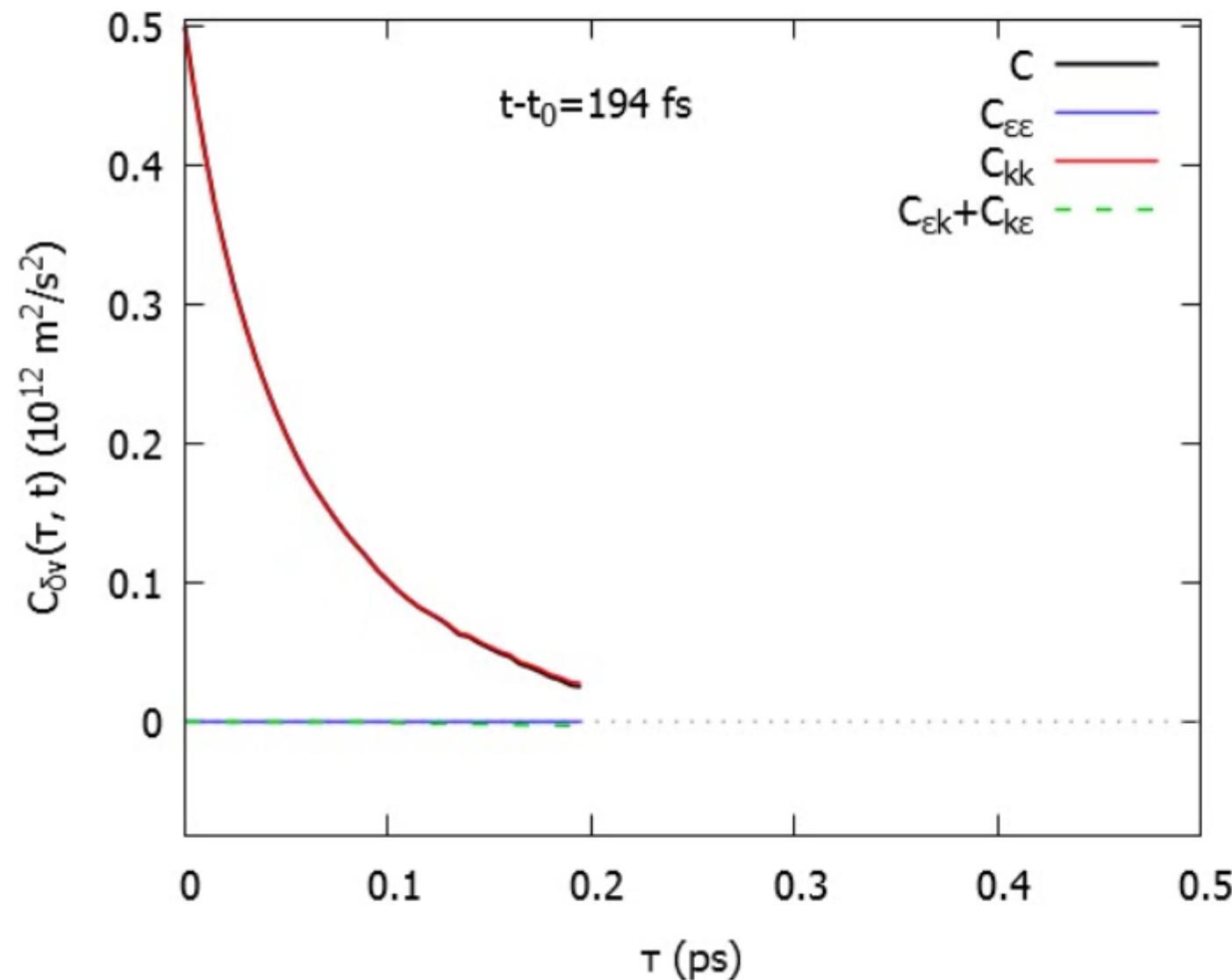
$$C_{\varepsilon\varepsilon} = 0$$

No redistribution of the averaged velocity for the different energy levels

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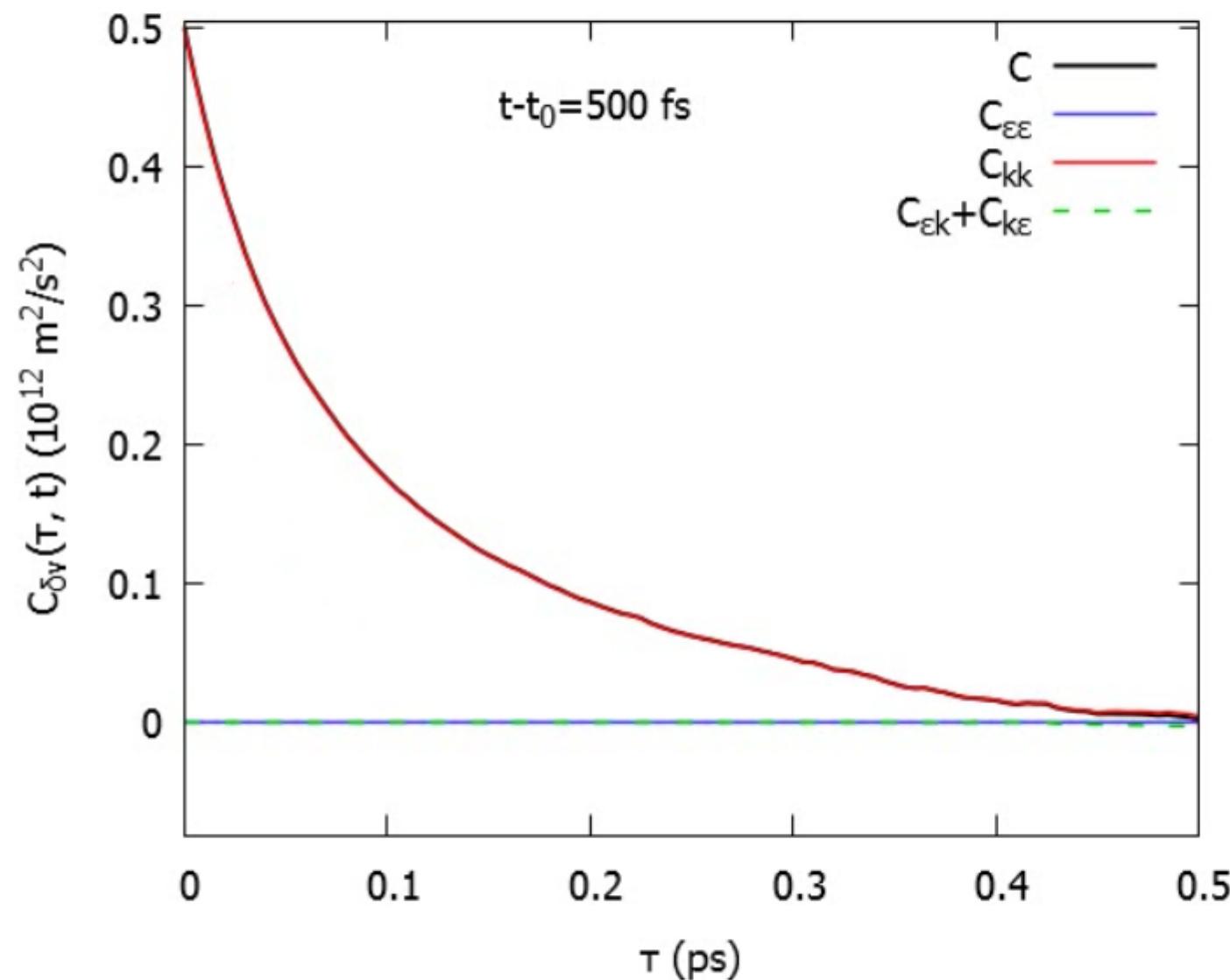
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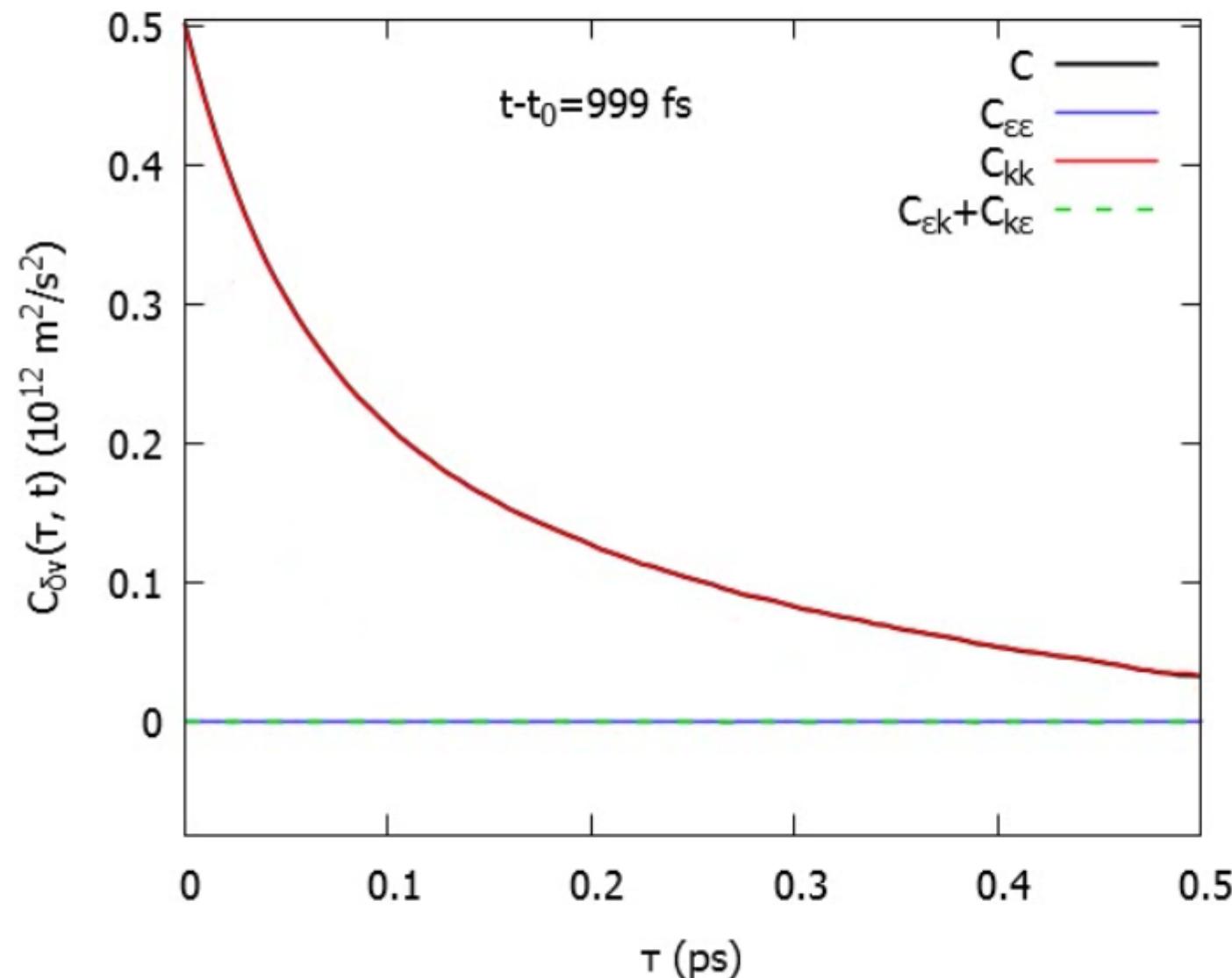
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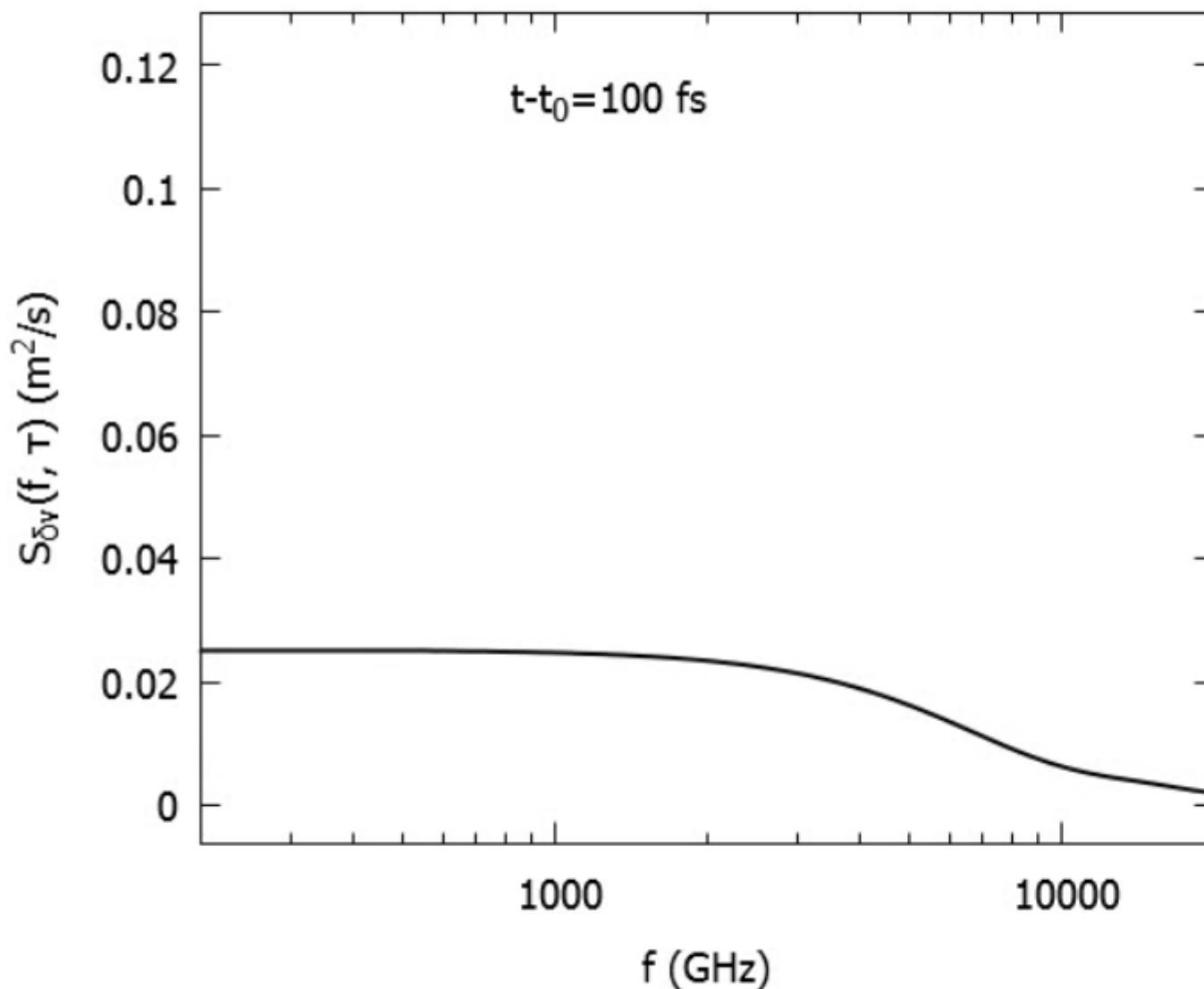
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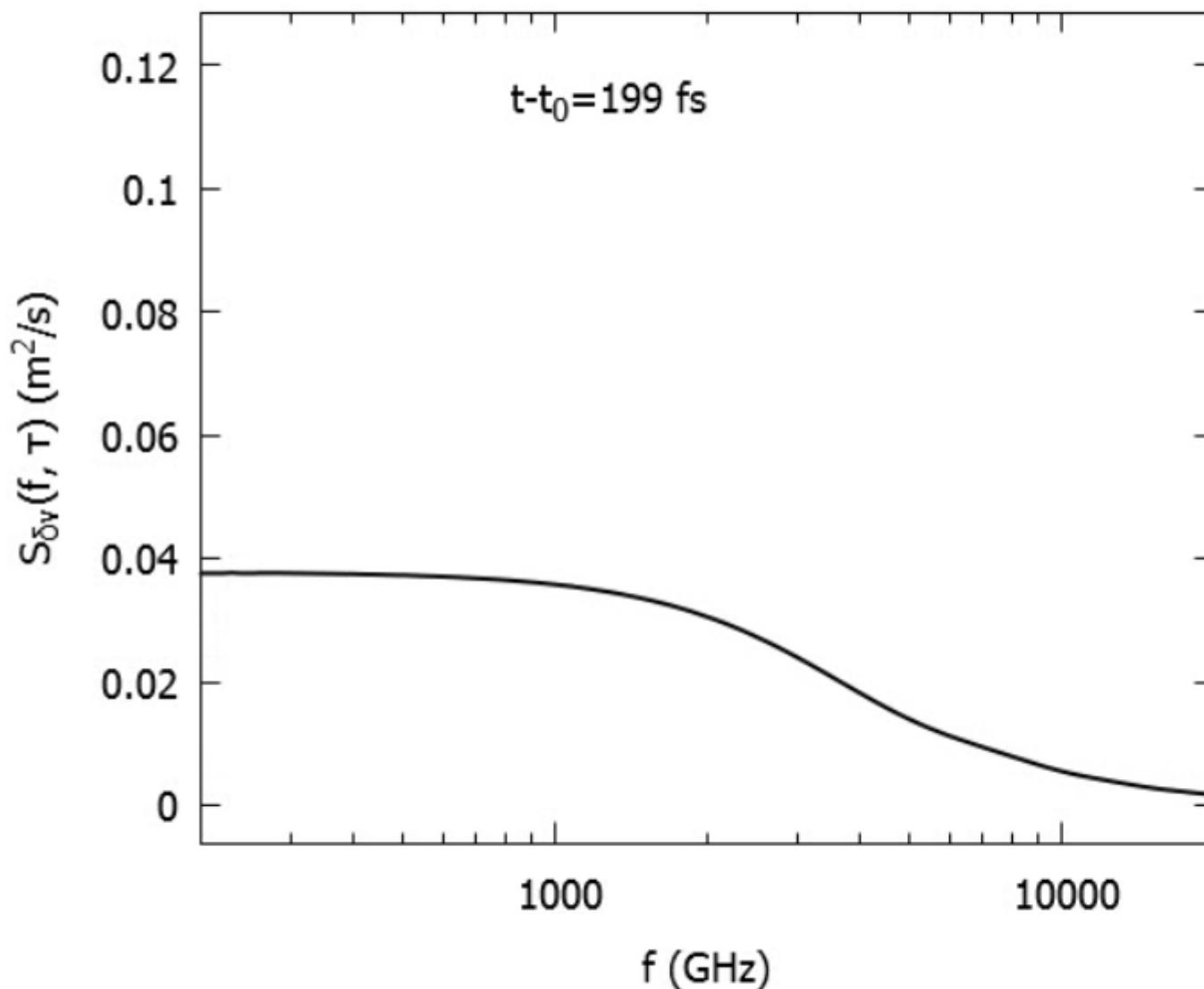
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# Graphene on SiO<sub>2</sub>; **high-to-low** field: Transient Power Spectral Density



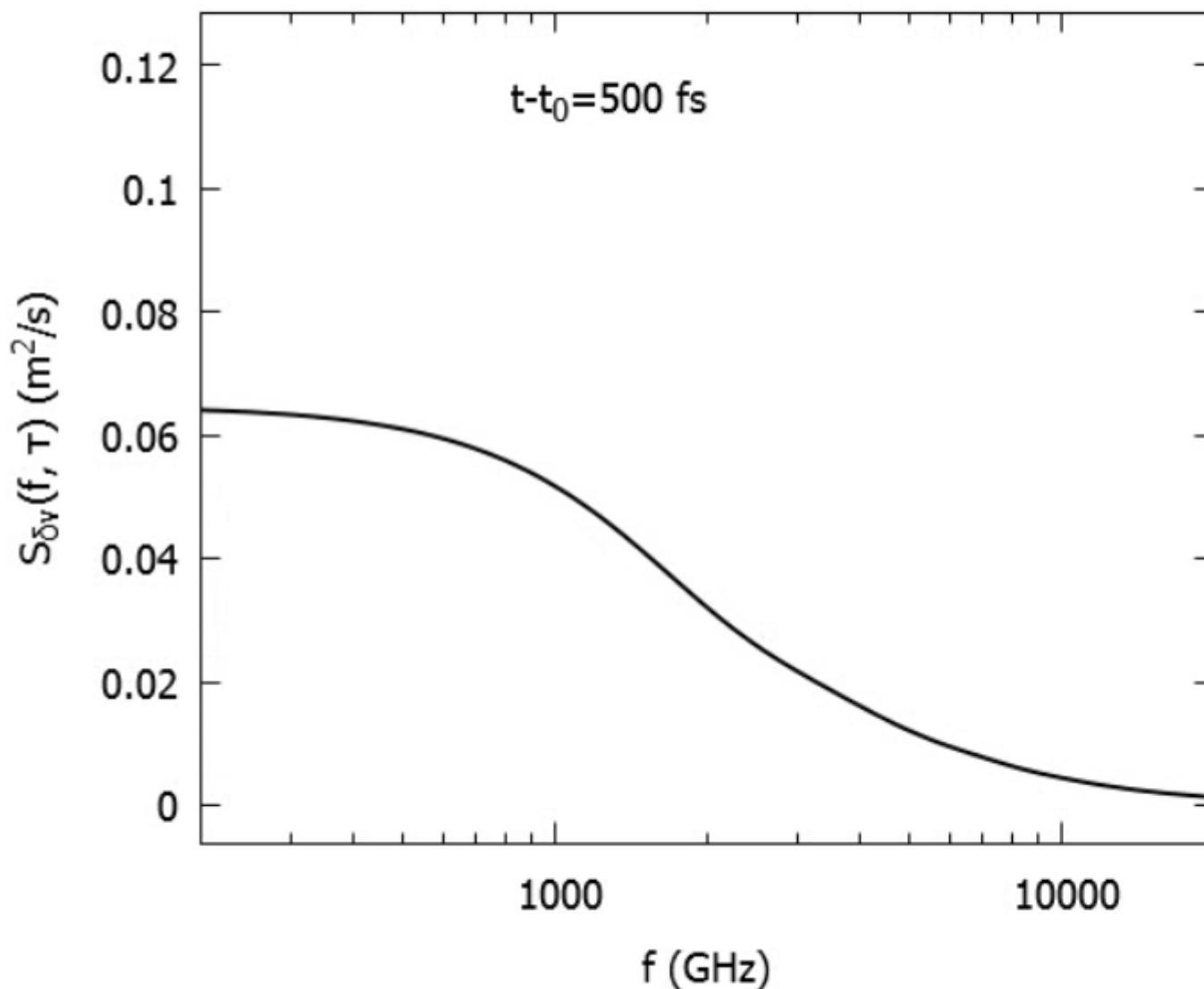
- Higher Power Spectral Density as a result of longer correlation.
- No maximum appears in the sampled frequencies due to a very weak maximum at long times.

# Graphene on SiO<sub>2</sub>; **high-to-low** field: Transient Power Spectral Density



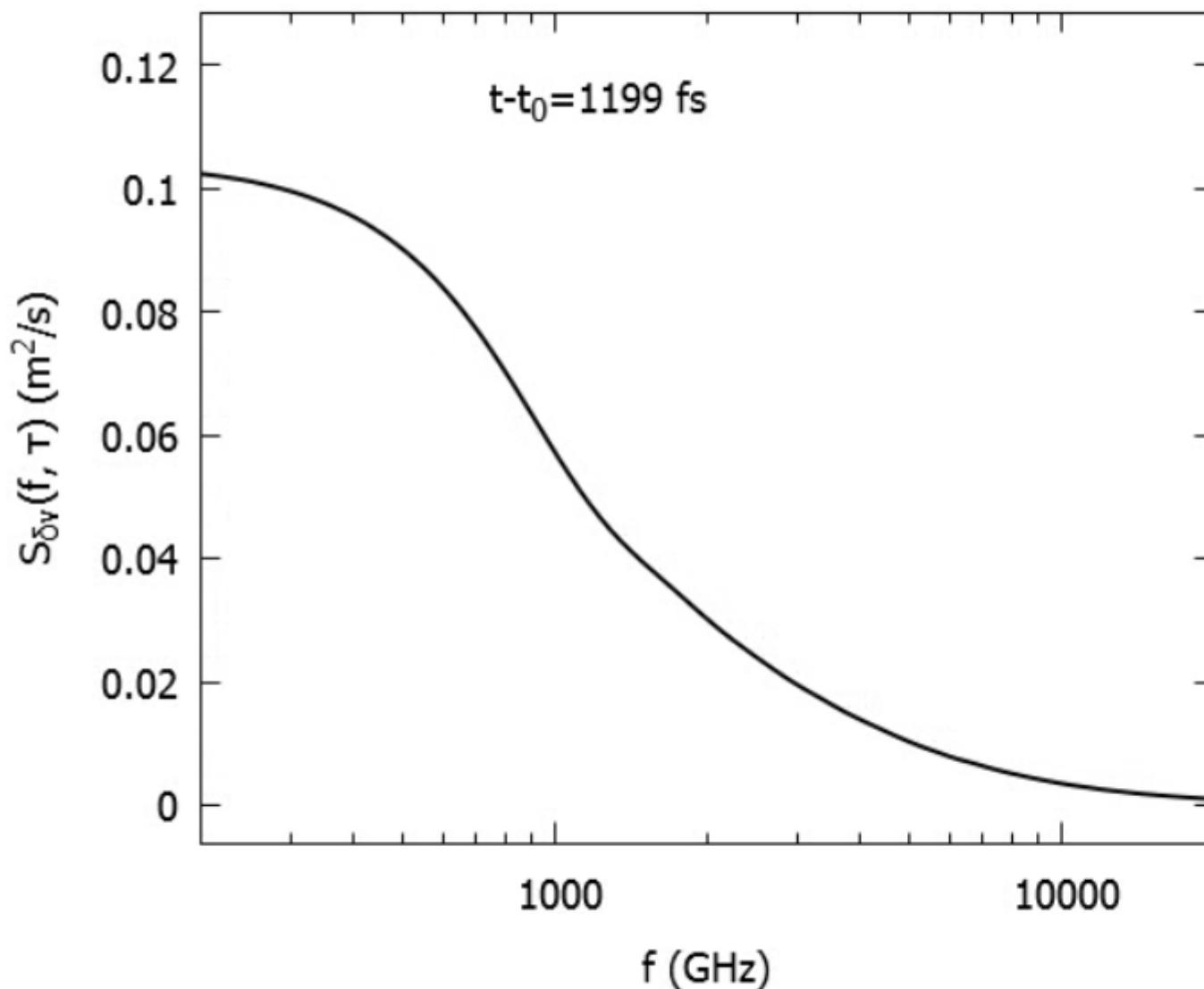
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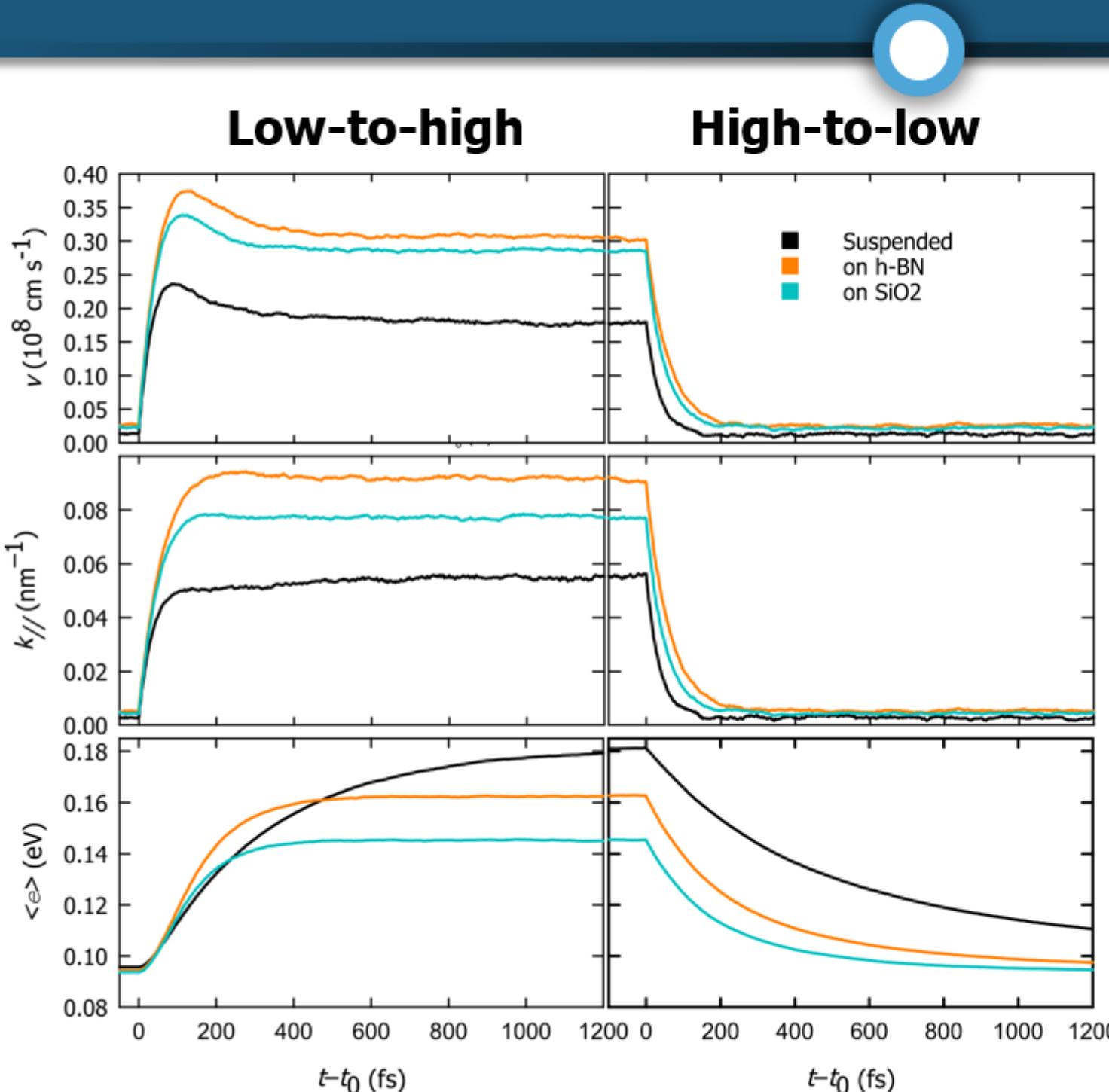
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# Other cases: Graphene on h-BN and Suspended graphene

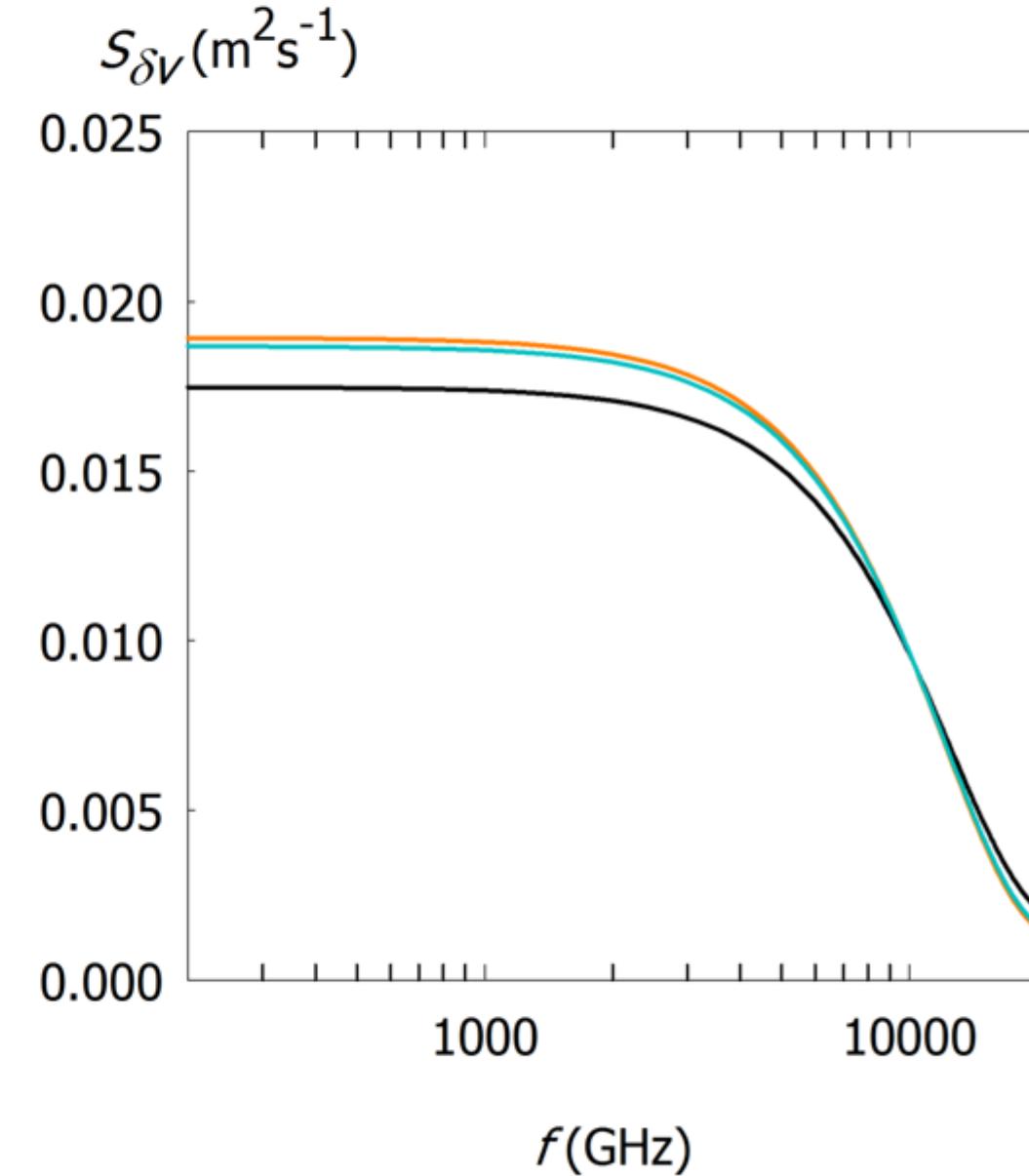
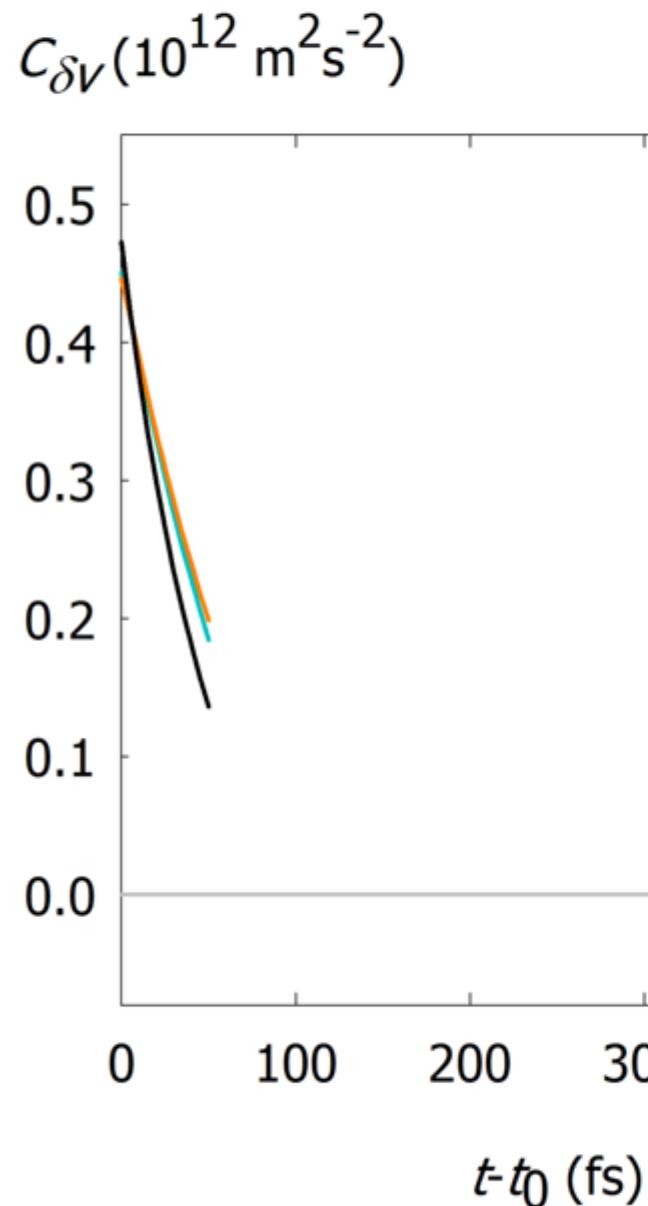


- Suspended graphene shows a faster evolutions for  $v$  and  $k_x$  but slower for the kinetic energy

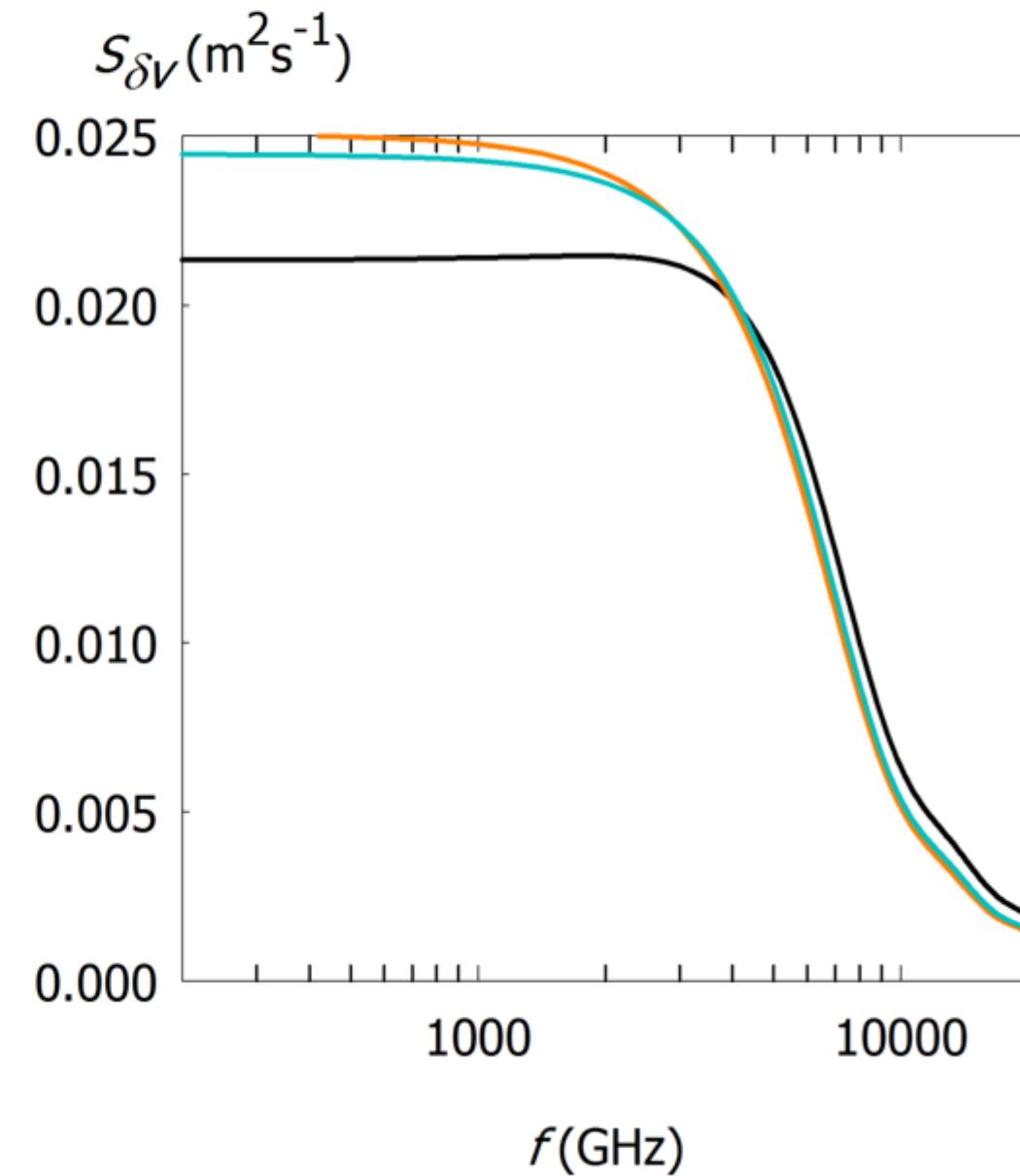
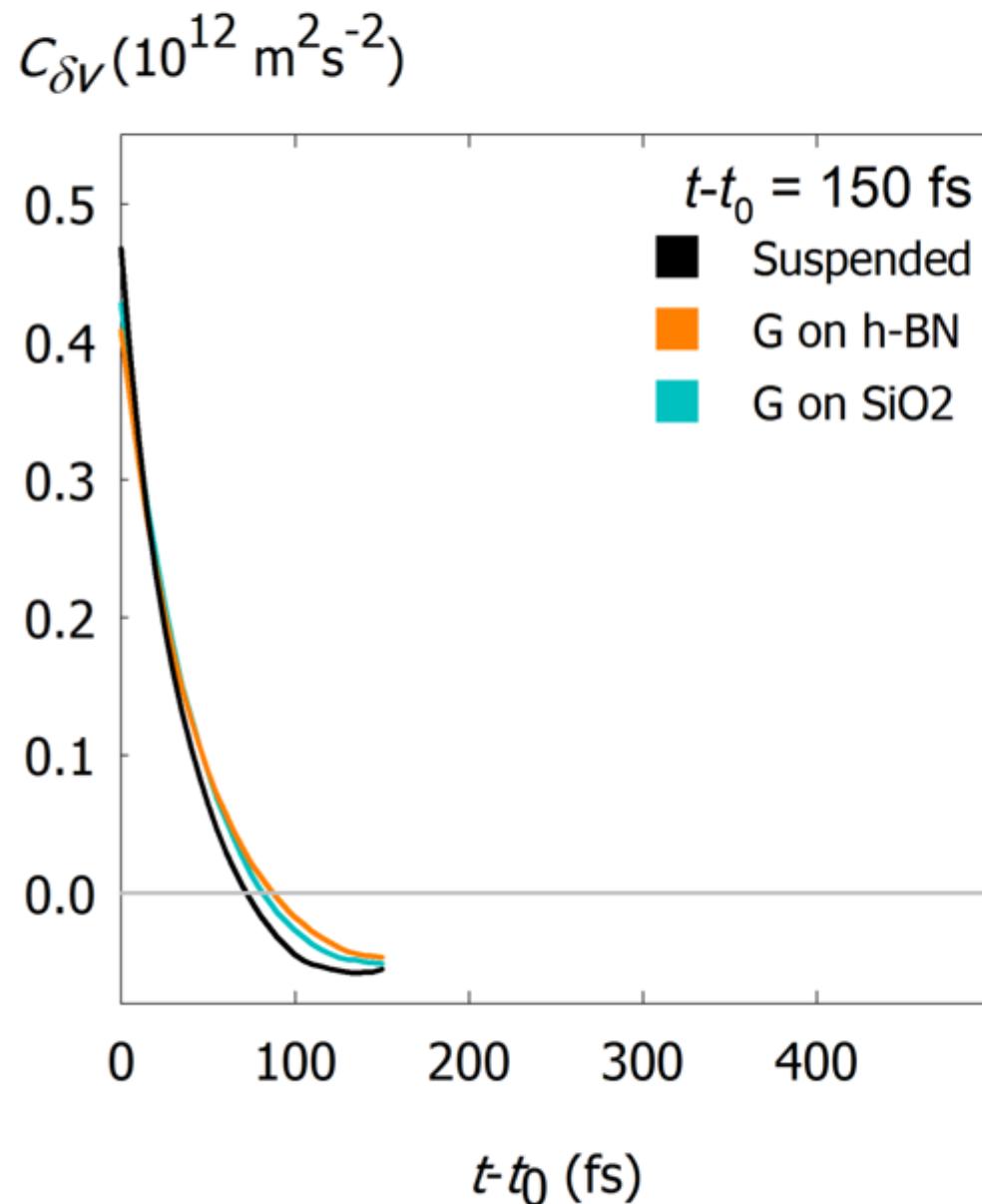


- Wavevector orientation

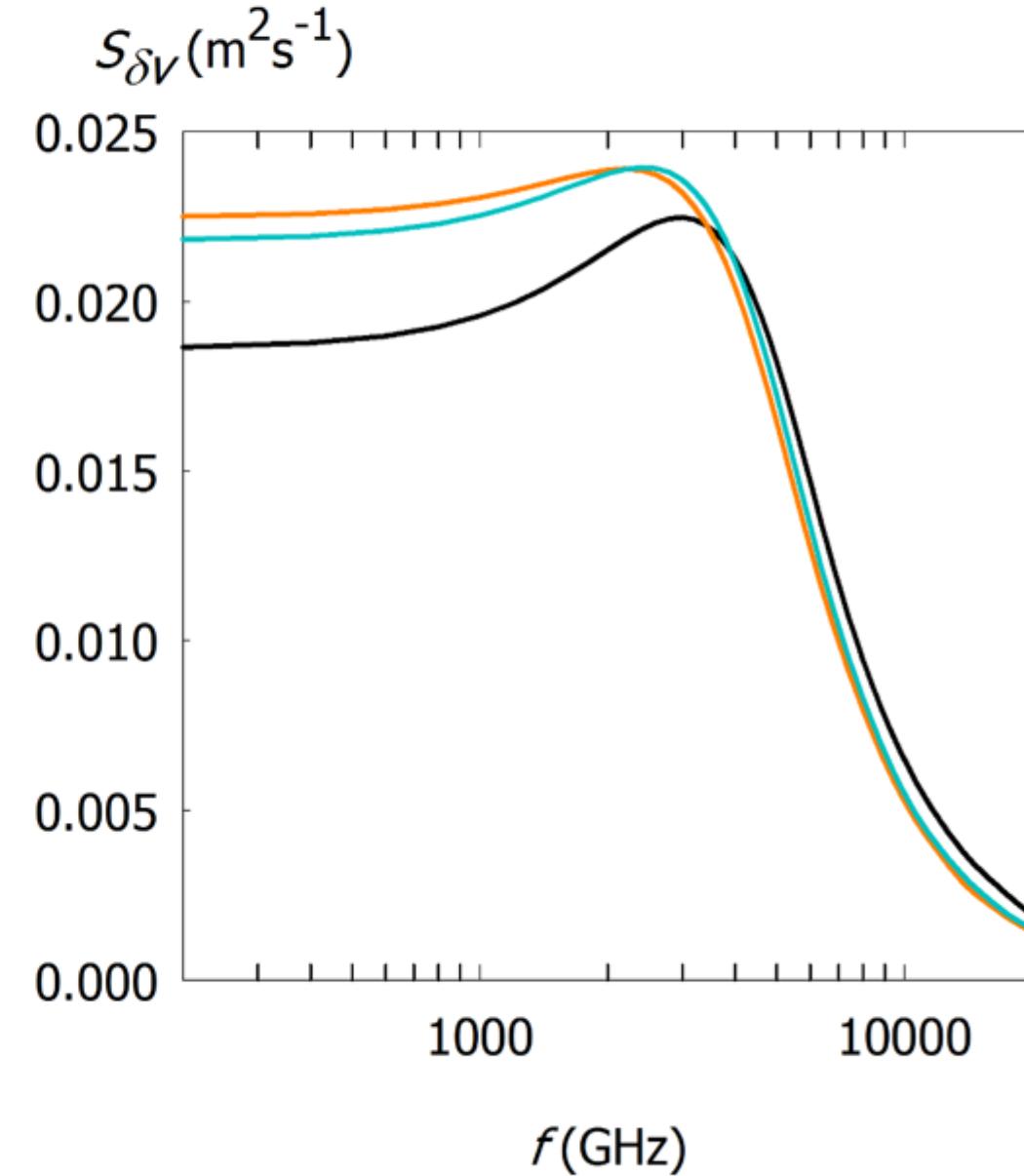
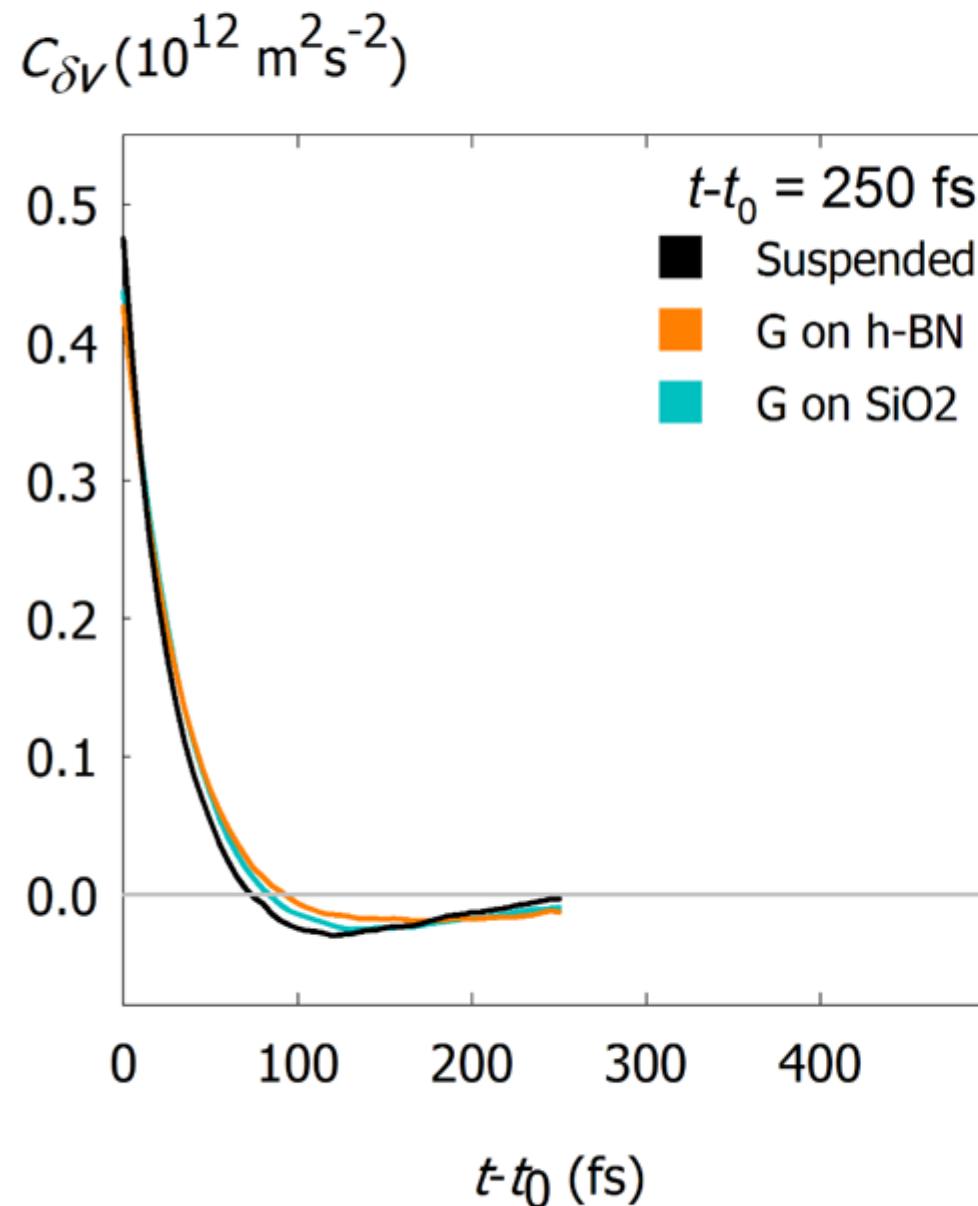
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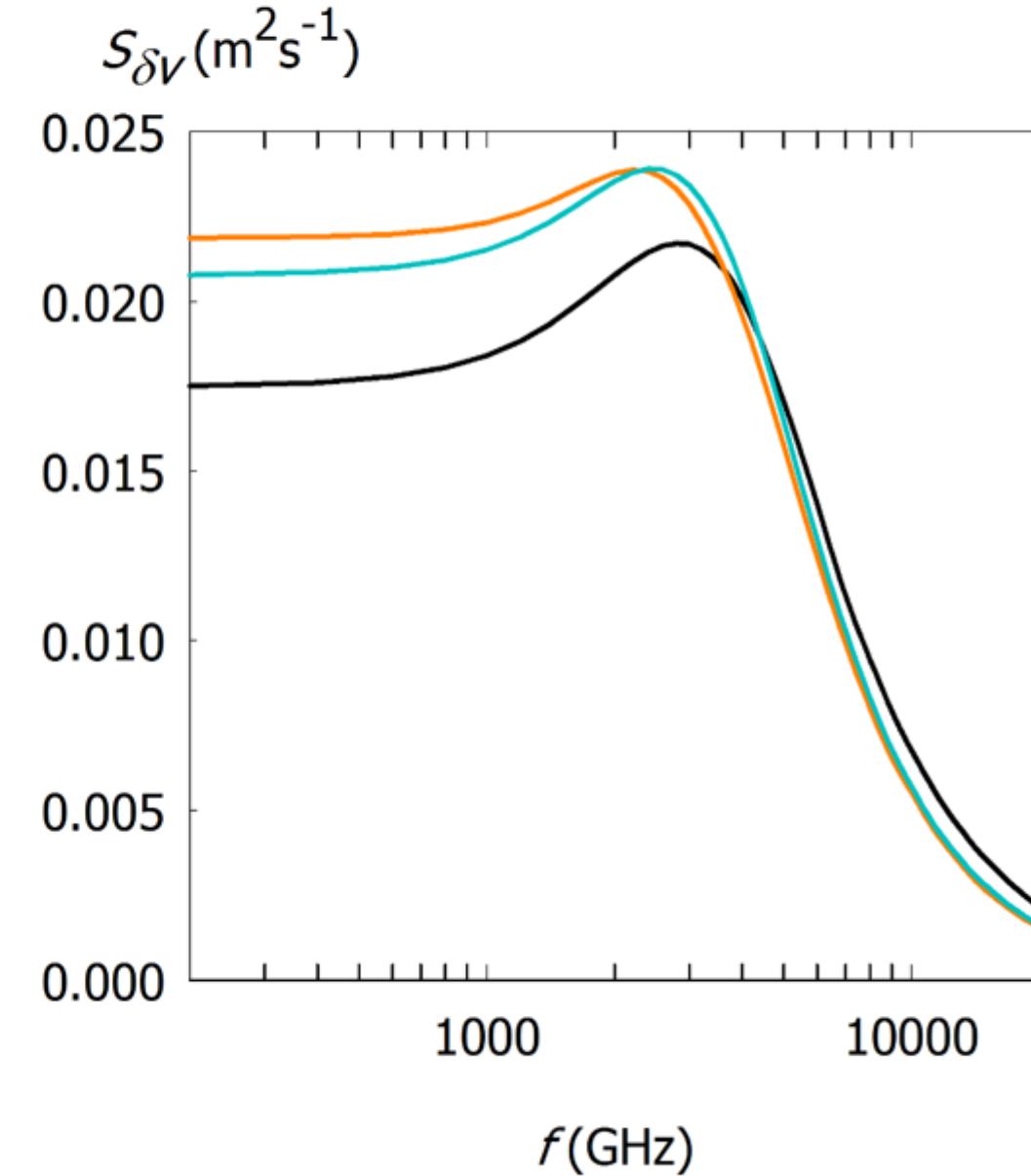
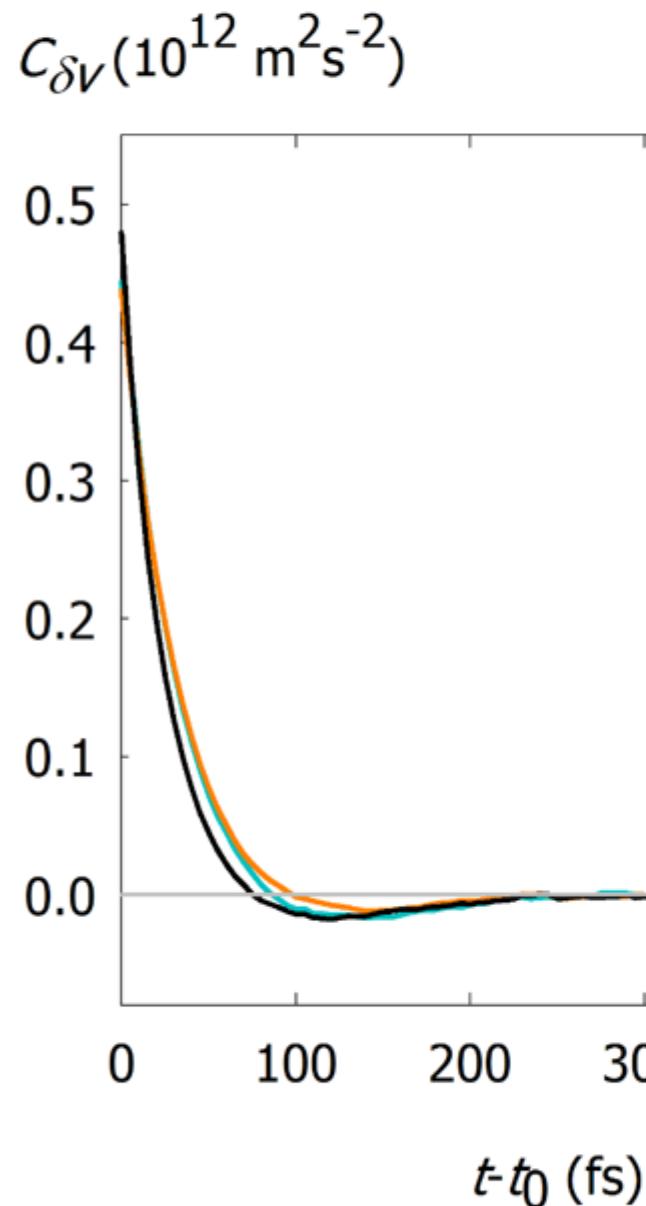
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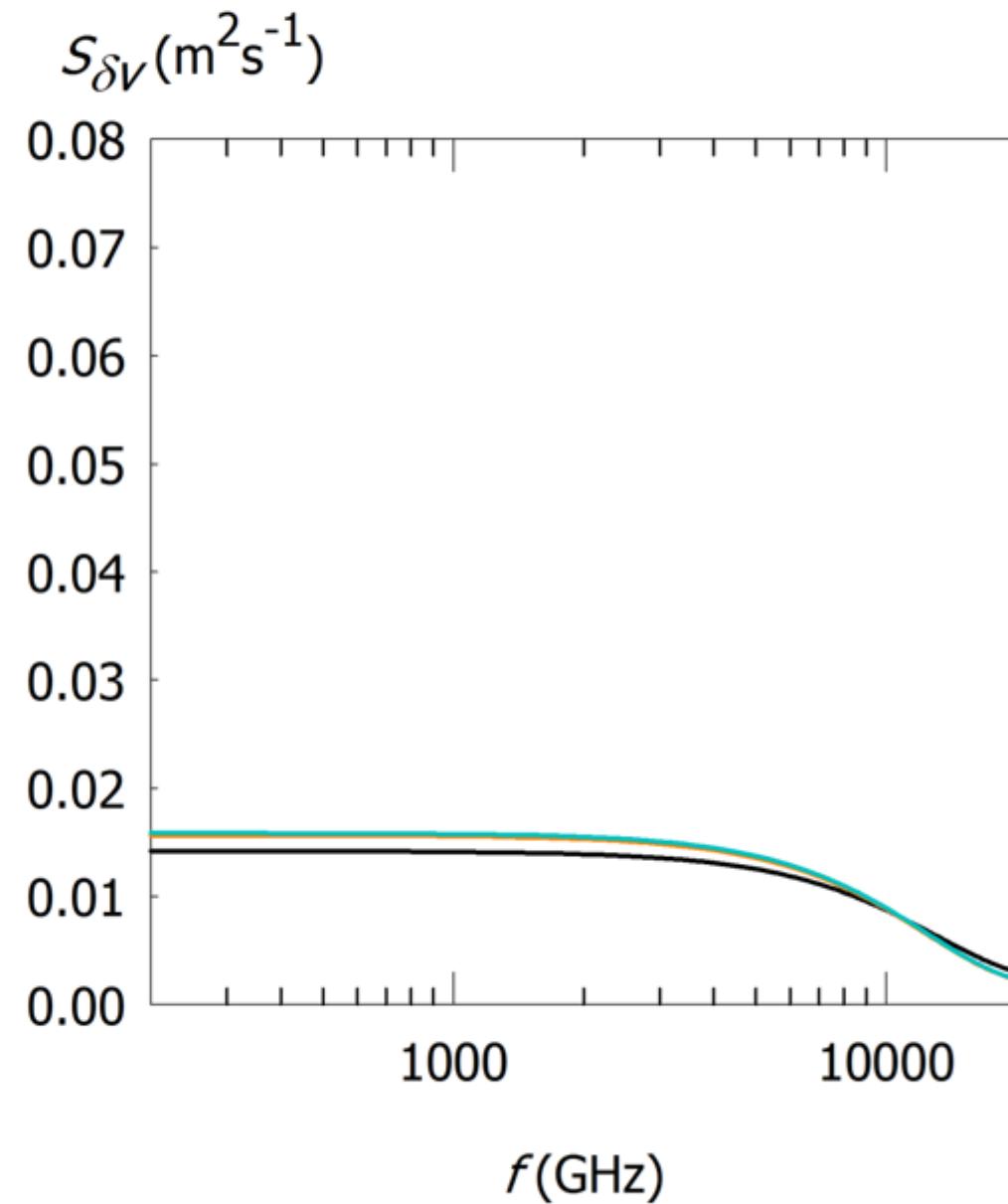
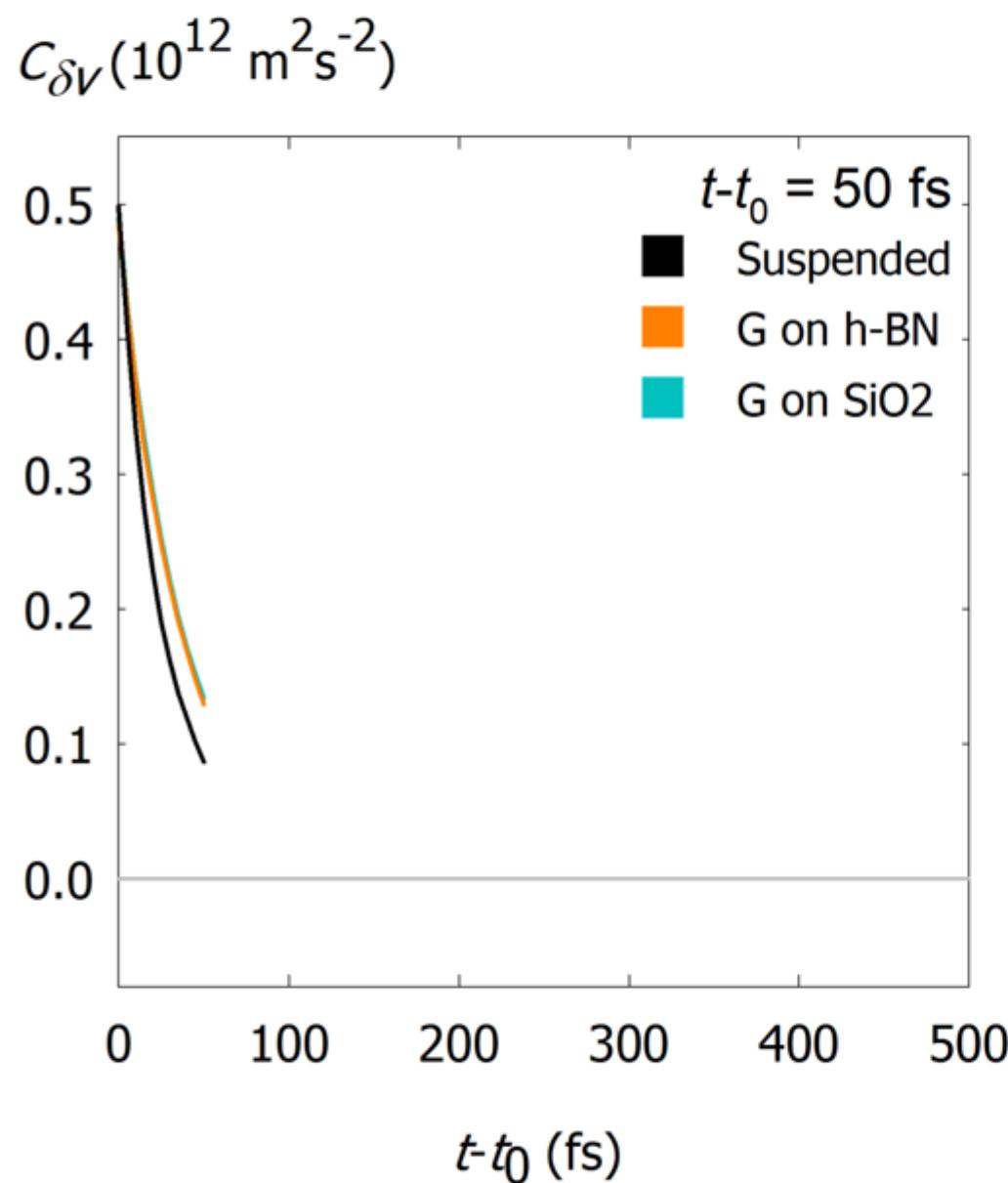
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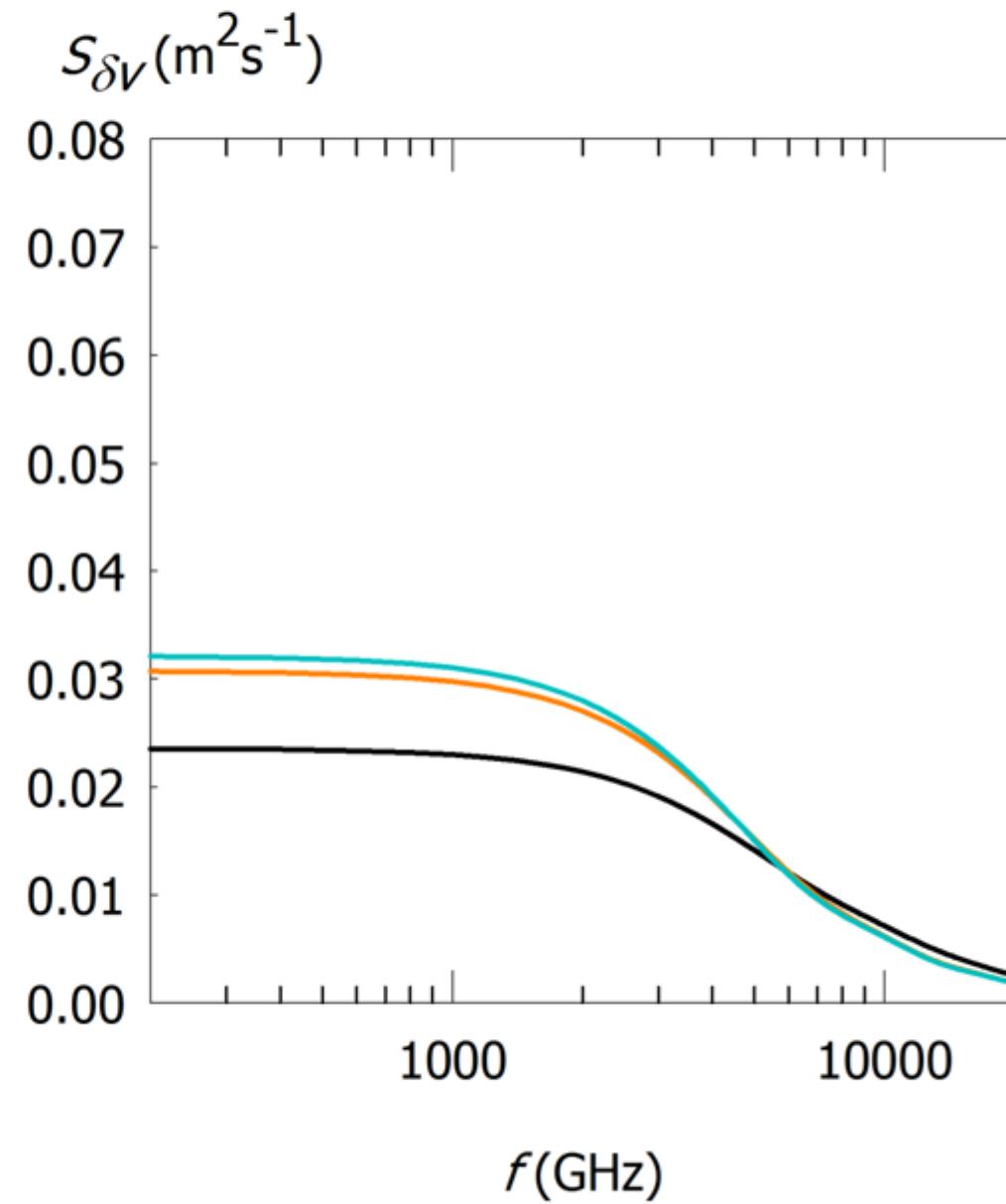
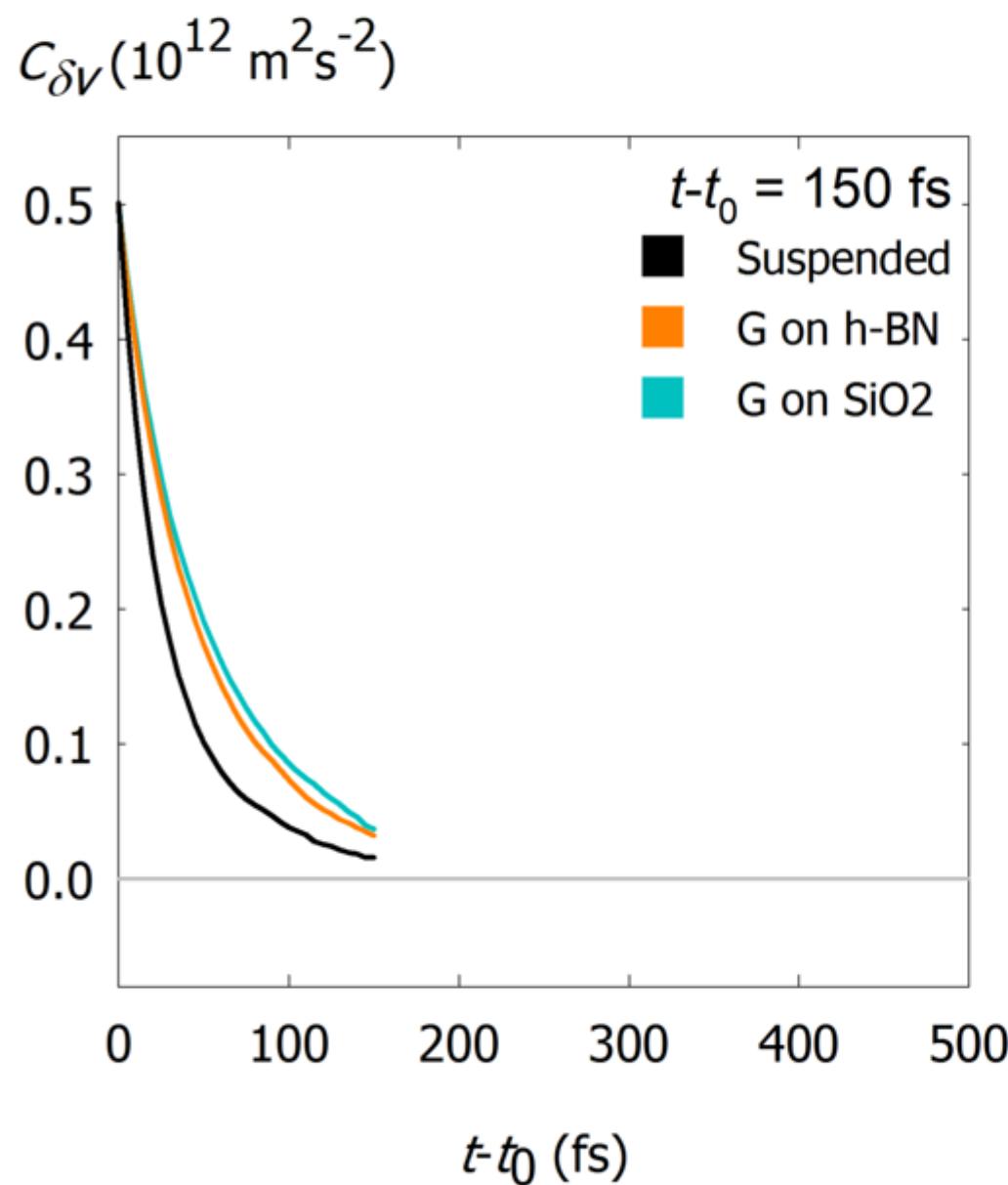
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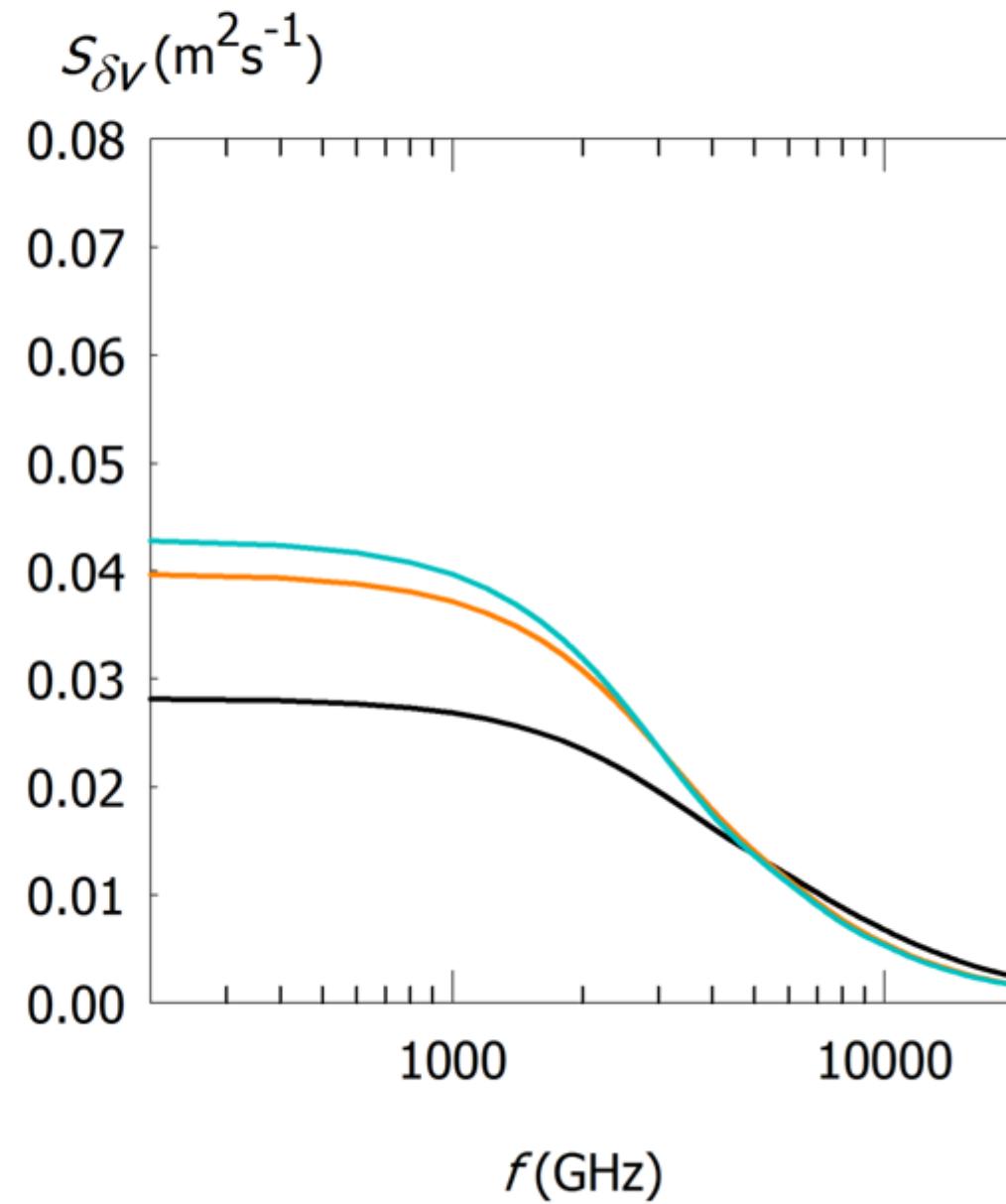
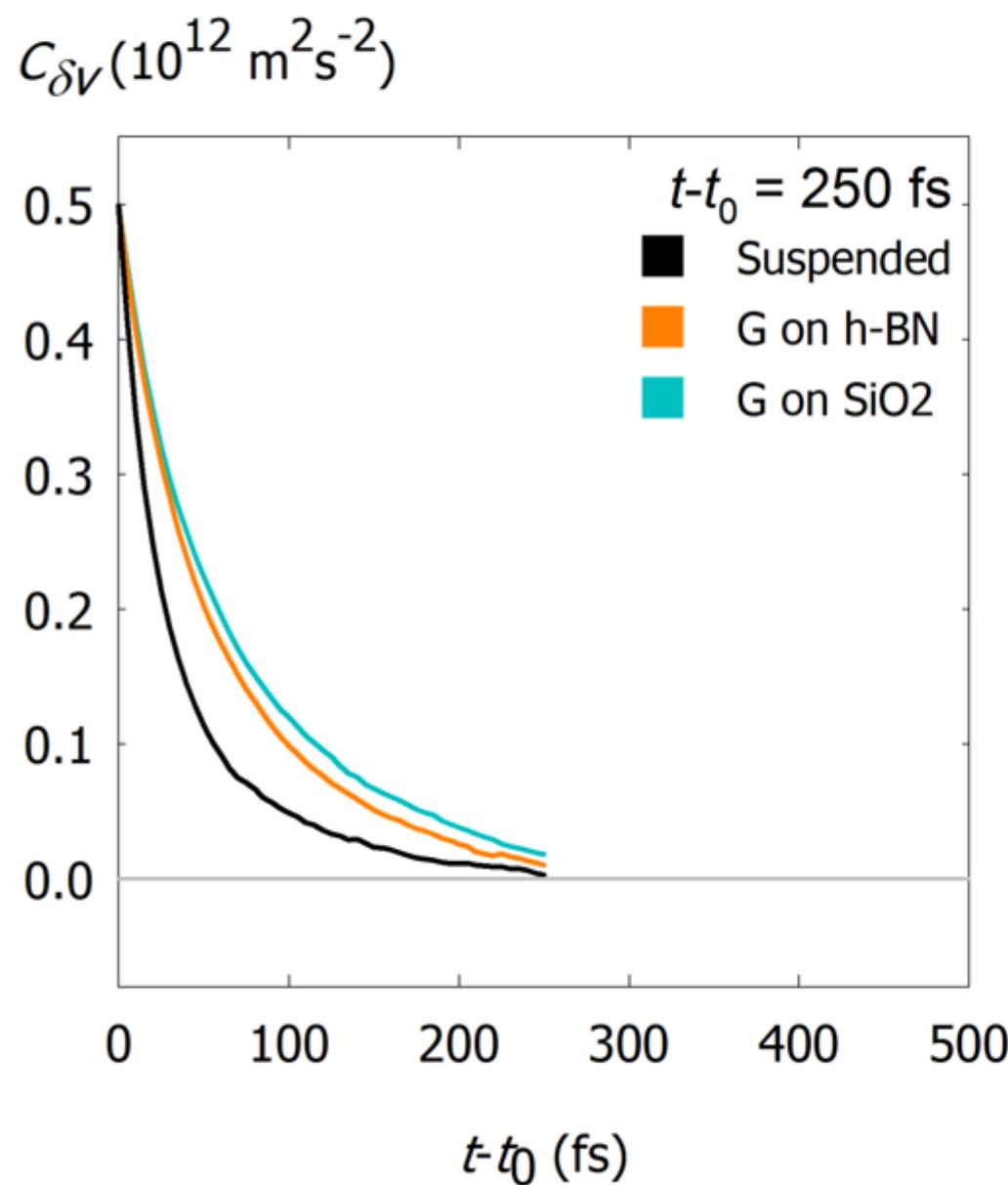
# Other cases: Graphene on h-BN and Suspended graphene; **High-to-low**



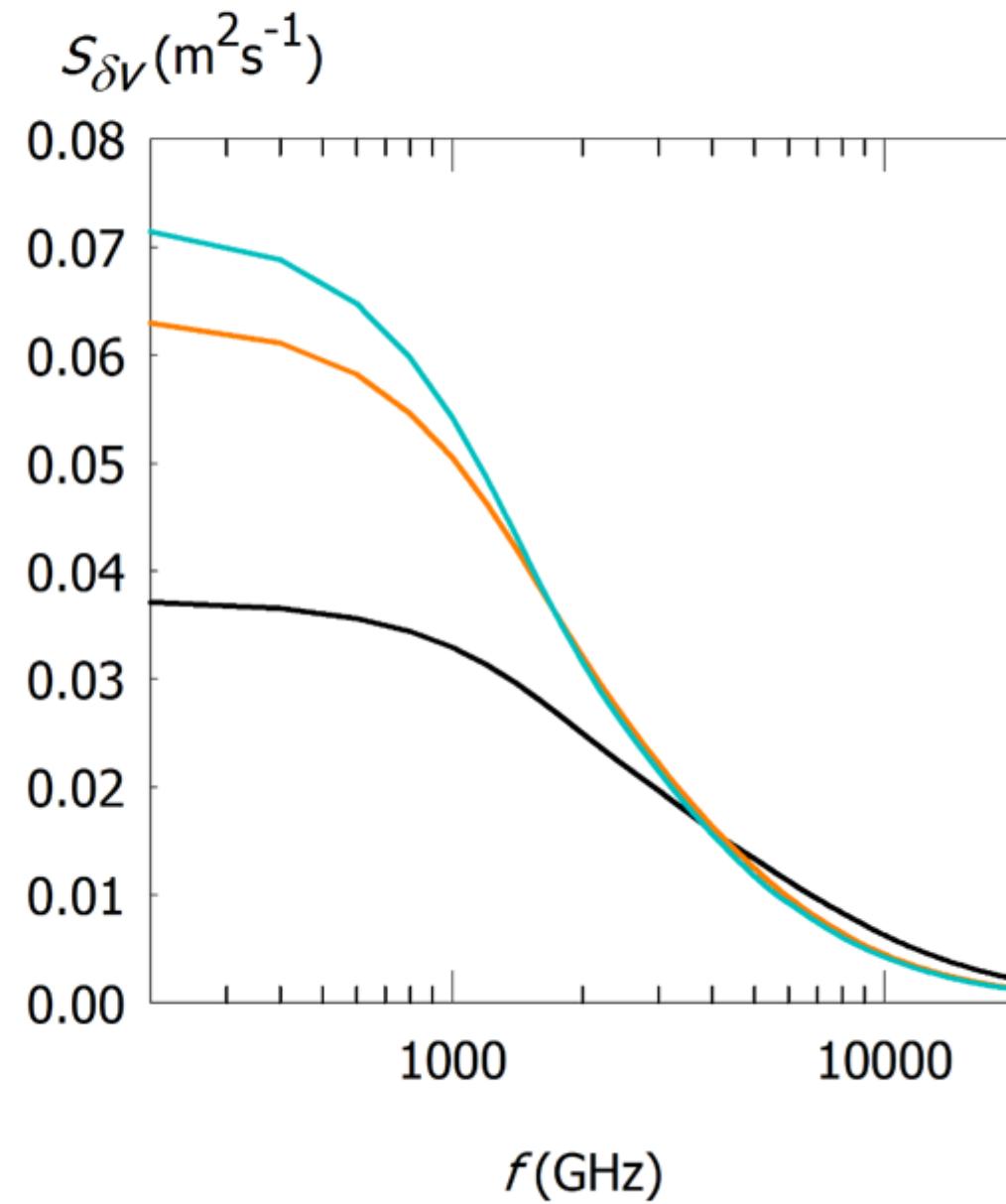
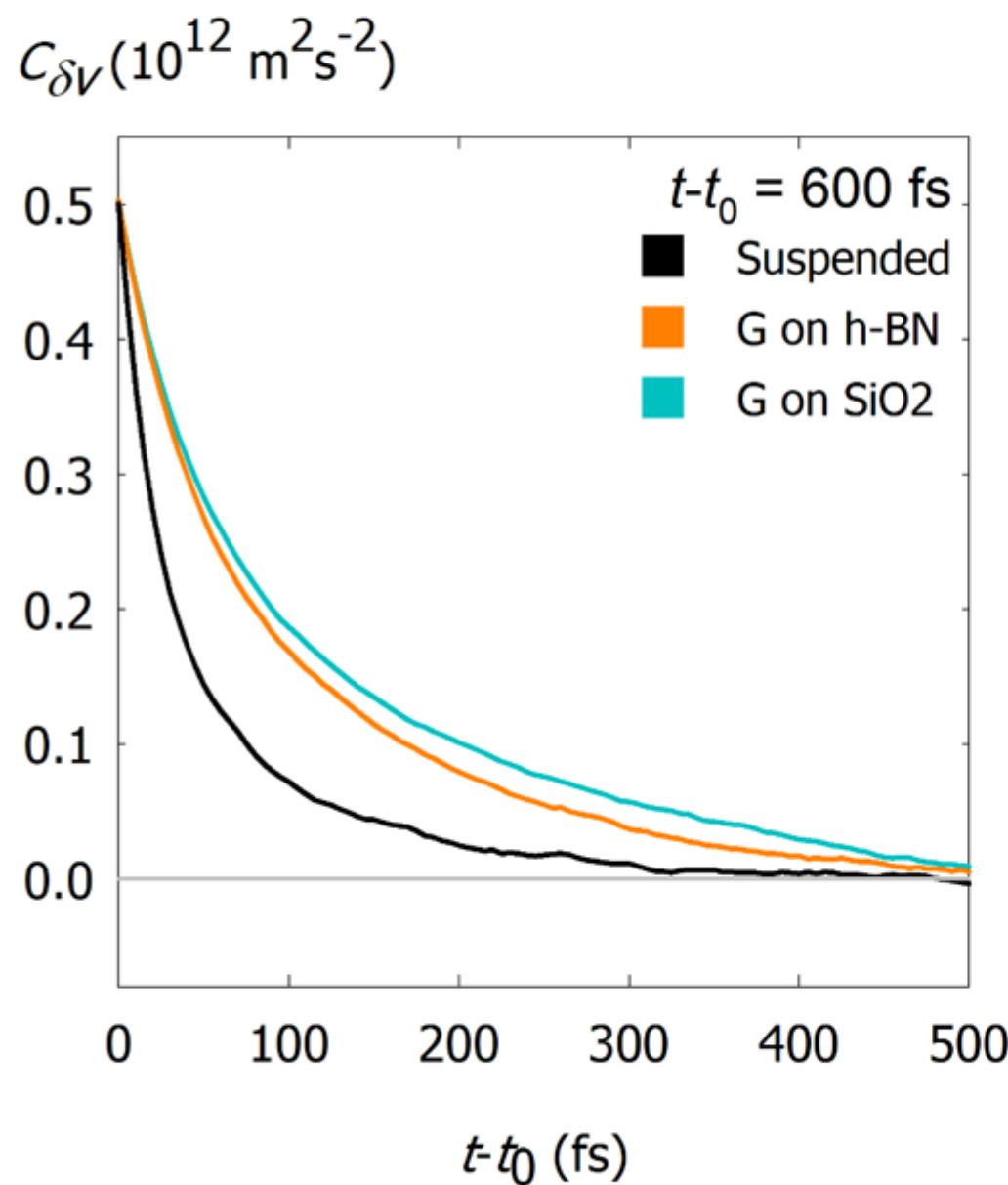
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4

# Conclusions

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- Transient **velocity fluctuations** were studied with a **Monte Carlo model** for electronic transport in monolayer graphene.
- The **velocity-momentum relation in graphene** has important implications
- **Thermal contribution** to the velocity fluctuations is dominant.
- In **low-to-high field** transitions, the **convective term** becomes non negligible as a consequence of velocity overshoot
- The **substrate** presence and type is **very relevant**

# Acknowledgement

This work was supported by research project  
**TEC2013-42622-R** from the  
Ministerio de Economía y Competitividad



# Thanks for your attention